

IGLOO nano Low Power Flash FPGAs with Flash*Freeze Technology

Features and Benefits

Low Power

- nanoPower Consumption—Industry's Lowest Power
- 1.2 V to 1.5 V Core Voltage Support for Low Power

- Supports Single-Voltage System Operation
 Low Power Active FPGA Operation
 Flash*Freeze Technology Enables Ultra-Low Power Consumption while Maintaining FPGA Content Easy Entry to / Exit from Ultra-Low Power Flash*Freeze Mode

Small Footprint Packages

As Small as 3x3 mm in Size

Wide Range of Features

- 10,000 to 250,000 System Gates
- Up to 36 kbits of True Dual-Port SRAM
- Up to 71 User I/Os

Reprogrammable Flash Technology

- 130-nm, 7-Layer Metal, Flash-Based CMOS Process
- Instant On Level 0 Support
- Single-Chip Solution
- Retains Programmed Design When Powered Off 250 MHz (1.5 V systems) and 160 MHz (1.2 V systems) System Performance

In-System Programming (ISP) and Security

- ISP Using On-Chip 128-Bit Advanced Encryption Standard (AES) Decryption via JTAG (IEEE 1532–compliant) FlashLock® Designed to Secure FPGA Contents
- 1.2 V Programming

High-Performance Routing Hierarchy

Segmented, Hierarchical Routing and Clock Structure

Advanced I/Os

- 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V Mixed-Voltage Operation
- Bank-Selectable I/O Voltages—up to 4 Banks per Chip
- Single-Ended I/O Standards: LVTTL, LVCMOS 3.3 V / 2.5 V / 1.8 V / 1.5 V / 1.2 V
- Wide Range Power Supply Voltage Support per JESD8-B, Allowing I/Os to Operate from 2.7 V to 3.6 V Wide Range Power Supply Voltage Support per JESD8-12, Allowing I/Os to Operate from 1.14 V to 1.575 V
- I/O Registers on Input, Output, and Enable Paths
- Selectable Schmitt Trigger Inputs Hot-Swappable and Cold-Sparing I/Os
- Programmable Output Slew Rate and Drive Strength
- Weak Pull-Up/-Down IEEE 1149.1 (JTAG) Boundary Scan Test
- Pin-Compatible Packages across the IGLOO® Family

Clock Conditioning Circuit (CCC) and PLL[†]

- Up to Six CCC Blocks, One with an Integrated PLL
- Configurable Phase Shift, Multiply/Divide, Delay Capabilities, and External Feedback
- Wide Input Frequency Range (1.5 MHz up to 250 MHz)

Embedded Memory

- 1 kbit of FlashROM User Nonvolatile Memory
- SRAMs and FIFOs with Variable-Aspect-Ratio 4,608-Bit RAM Blocks (×1, ×2, ×4, ×9, and ×18 organizations)
- True Dual-Port SRAM (except × 18 organization)[†]

Enhanced Commercial Temperature Range

Tj = -20°C to +85°C

IGLOO nano Devices	AGLN010	AGLN015 ¹	AGLN020		AGLN060	AGLN125	AGLN250
IGLOO nano-Z Devices ¹				AGLN030Z ¹	AGLN060Z ¹	AGLN125Z ¹	AGLN250Z ¹
System Gates	10,000	15,000	20,000	30,000	60,000	125,000	250,000
Typical Equivalent Macrocells	86	128	172	256	512	1,024	2,048
VersaTiles (D-flip-flops)	260	384	520	768	1,536	3,072	6,144
Flash*Freeze Mode (typical, µW)	2	4	4	5	10	16	24
RAM Kbits (1,024 bits) ²	-	-	-	-	18	36	36
4,608-Bit Blocks ²	-	-	-	_	4	8	8
FlashROM Kbits (1,024 bits)	1	1	1	1	1	1	1
Secure (AES) ISP ²	-	-	-	_	Yes	Yes	Yes
Integrated PLL in CCCs 2,3	-	-	-	_	1	1	1
VersaNet Globals	4	4	4	6	18	18	18
I/O Banks	2	3	3	2	2	2	4
Maximum User I/Os (packaged device)	34	49	52	77	71	71	68
Maximum User I/Os (Known Good Die)	34	-	52	83	71	71	68
Package Pins UC/CS QFN VQFP	UC36 QN48	QN68	UC81, CS81 QN68	UC81, CS81 QN48, QN68 VQ100	CS81 VQ100	CS81 VQ100	CS81 VQ100

Notes:

- 1. Not recommended for new designs.
- AGLN030 and smaller devices do not support this feature.
 AGLN060, AGLN125, and AGLN250 in the CS81 package do not support PLLs.
- For higher densities and support of additional features, refer to the IGLOO and IGLOOe datasheets.

[†] AGLN030 and smaller devices do not support this feature.



I/Os Per Package

IGLOO nano Devices	AGLN010	AGLN015 ¹	AGLN020		AGLN060	AGLN125	AGLN250
IGLOO nano-Z Devices ¹				AGLN030Z ¹	AGLN060Z ¹	AGLN125Z ¹	AGLN250Z ¹
Known Good Die	34	-	52	83	71	71	68
UC36	23	-	_	_	-	-	_
QN48	34	-	_	34	-	-	_
QN68	-	49	49	49	-	=	_
UC81	_	-	52	66	-	-	_
CS81	_	-	52	66	60	60	60
VQ100	_	-	_	77	71	71	68

Notes:

- 1. Not recommended for new designs.
- 2. When considering migrating your design to a lower- or higher-density device, refer to the IGLOO datasheet and IGLOO FPGA Fabric User's Guide to ensure compliance with design and board migration requirements.
- 3. When the Flash*Freeze pin is used to directly enable Flash*Freeze mode and not used as a regular I/O, the number of single-ended user I/Os available is reduced by one.
- 4. "G" indicates RoHS-compliant packages. Refer to "IGLOO nano Ordering Information" on page III for the location of the "G" in the part number. For nano devices, the VQ100 package is offered in both leaded and RoHS-compliant versions. All other packages are RoHS-compliant only.

Table 1 • IGLOO nano FPGAs Package Sizes Dimensions

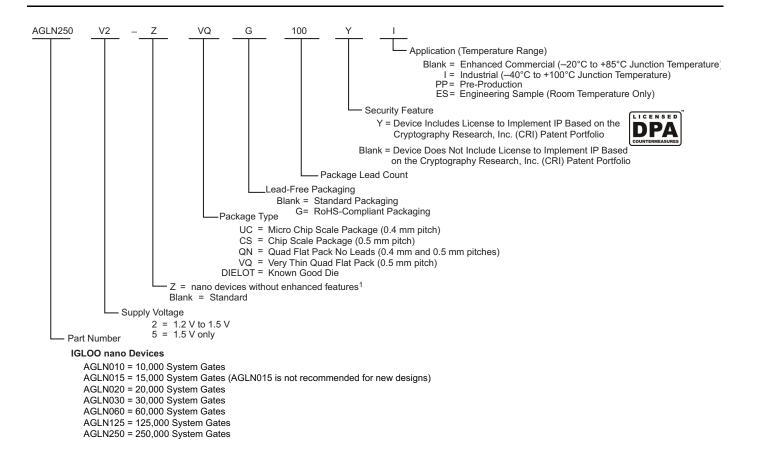
Packages	UC36	UC81	CS81	QN48	QN68	VQ100
Length × Width (mm\mm)	3 x 3	4 x 4	5 x 5	6 x 6	8 x 8	14 x 14
Nominal Area (mm ²)	9	16	36	36	64	196
Pitch (mm)	0.4	0.4	0.5	0.4	0.4	0.5
Height (mm)	0.80	0.80	0.80	0.90	0.90	1.20

IGLOO nano Device Status

IGLOO nano Devices	Status	IGLOO nano-Z Devices	Status
AGLN010	Production		
AGLN015	Not recommended for new designs.		
AGLN020	Production		
		AGLN030Z	Not recommended for new designs.
AGLN060	Production	AGLN060Z	Not recommended for new designs.
AGLN125	Production	AGLN125Z	Not recommended for new designs.
AGLN250	Production	AGLN250Z	Not recommended for new designs.

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IGLOO nano Ordering Information



Notes:

- Z-feature grade devices AGLN060Z, AGLN125Z, and AGLN250Z do not support the enhanced nano features of Schmitt Trigger input, bus hold (hold previous I/O state in Flash*Freeze mode), cold-sparing, hot-swap I/O capability and 1.2 V programming. The AGLN030 Z feature grade does not support Schmitt trigger input, bus hold and 1.2 V programming. For the VQ100, CS81, UC81, QN68, and QN48 packages, the Z feature grade and the N part number are not marked on the device. Z feature grade devices are not recommended for new designs.
- 2. AGLN030 is available in the Z feature grade only.
- 3. Marking Information: IGLOO nano V2 devices do not have a V2 marking, but IGLOO nano V5 devices are marked with a V5 designator.

Devices Not Recommended For New Designs

AGLN015, AGLN030Z, AGLN060Z, AGLN125Z, and AGLN250Z are not recommended for new designs.

Device Marking

Microsemi normally topside marks the full ordering part number on each device. There are some exceptions to this, such as some of the Z feature grade nano devices, the V2 designator for IGLOO devices, and packages where space is physically limited. Packages that have limited characters available are UC36, UC81, CS81, QN48, QN68, and QFN132. On these specific packages, a subset of the device marking will be used that includes the required legal information and as much of the part number as allowed by character limitation of the device. In this case, devices will have a truncated device marking and may exclude the applications markings, such as the I designator for Industrial Devices or the ES designator for Engineering Samples.

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Figure 1 shows an example of device marking based on the AGL030V5-UCG81. The actual mark will vary by the device/package combination ordered.

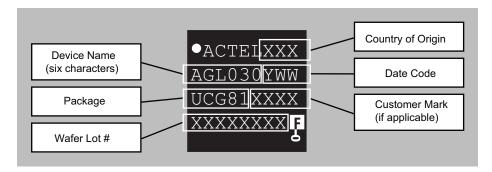


Figure 1 • Example of Device Marking for Small Form Factor Packages

IGLOO nano Products Available in the Z Feature Grade

IGLOO nano-Z Devices	AGLN030Z*	AGLN060Z*	AGLN125Z*	AGLN250Z*
	QN48	-	_	-
	QN68	-	_	-
	UC81	-	_	-
	CS81	CS81	CS81	CS81
Packages	VQ100	VQ100	VQ100	VQ100

Note: *Not recommended for new designs.

Temperature Grade Offerings

	AGLN010	AGLN015 [*]	AGLN020		AGLN060	AGLN125	AGLN250
Package				AGLN030Z*	AGLN060Z*	AGLN125Z [*]	AGLN250Z [*]
UC36	C, I	-	-	_	_	_	_
QN48	C, I	-	-	C, I	_	_	_
QN68	_	C, I	C, I	C, I	_	_	_
UC81	_	-	C, I	C, I	-	_	_
CS81	_	-	C, I	C, I	C, I	C, I	C, I
VQ100	_	-	-	C, I	C, I	C, I	C, I

Note: * Not recommended for new designs.

C = Enhanced Commercial temperature range: -20°C to +85°C junction temperature

I = Industrial temperature range: -40°C to +100°C junction temperature

Contact your local Microsemi representative for device availability: http://www.microsemi.com/soc/contact/default.aspx.

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1 – IGLOO nano Device Overview

General Description

The IGLOO family of flash FPGAs, based on a 130-nm flash process, offers the lowest power FPGA, a single-chip solution, small footprint packages, reprogrammability, and an abundance of advanced features.

The Flash*Freeze technology used in IGLOO nano devices enables entering and exiting an ultra-low power mode that consumes nanoPower while retaining SRAM and register data. Flash*Freeze technology simplifies power management through I/O and clock management with rapid recovery to operation mode.

The Low Power Active capability (static idle) allows for ultra-low power consumption while the IGLOO nano device is completely functional in the system. This allows the IGLOO nano device to control system power management based on external inputs (e.g., scanning for keyboard stimulus) while consuming minimal power.

Nonvolatile flash technology gives IGLOO nano devices the advantage of being a secure, low power, single-chip solution that is Instant On. The IGLOO nano device is reprogrammable and offers time-to-market benefits at an ASIC-level unit cost.

These features enable designers to create high-density systems using existing ASIC or FPGA design flows and tools.

IGLOO nano devices offer 1 kbit of on-chip, reprogrammable, nonvolatile FlashROM storage as well as clock conditioning circuitry based on an integrated phase-locked loop (PLL). The AGLN030 and smaller devices have no PLL or RAM support. IGLOO nano devices have up to 250 k system gates, supported with up to 36 kbits of true dual-port SRAM and up to 71 user I/Os.

IGLOO nano devices increase the breadth of the IGLOO product line by adding new features and packages for greater customer value in high volume consumer, portable, and battery-backed markets. Features such as smaller footprint packages designed with two-layer PCBs in mind, power consumption measured in nanoPower, Schmitt trigger, and bus hold (hold previous I/O state in Flash*Freeze mode) functionality make these devices ideal for deployment in applications that require high levels of flexibility and low cost.

Flash*Freeze Technology

The IGLOO nano device offers unique Flash*Freeze technology, allowing the device to enter and exit ultra-low power Flash*Freeze mode. IGLOO nano devices do not need additional components to turn off I/Os or clocks while retaining the design information, SRAM content, and registers. Flash*Freeze technology is combined with in-system programmability, which enables users to quickly and easily upgrade and update their designs in the final stages of manufacturing or in the field. The ability of IGLOO nano V2 devices to support a wide range of core voltage (1.2 V to 1.5 V) allows further reduction in power consumption, thus achieving the lowest total system power.

During Flash*Freeze mode, each I/O can be set to the following configurations: hold previous state, tristate, HIGH, or LOW.

The availability of low power modes, combined with reprogrammability, a single-chip and single-voltage solution, and small-footprint packages make IGLOO nano devices the best fit for portable electronics.



Flash Advantages

Low Power

Flash-based IGLOO nano devices exhibit power characteristics similar to those of an ASIC, making them an ideal choice for power-sensitive applications. IGLOO nano devices have only a very limited power-on current surge and no high-current transition period, both of which occur on many FPGAs.

IGLOO nano devices also have low dynamic power consumption to further maximize power savings; power is reduced even further by the use of a 1.2 V core voltage.

Low dynamic power consumption, combined with low static power consumption and Flash*Freeze technology, gives the IGLOO nano device the lowest total system power offered by any FPGA.

Security

Nonvolatile, flash-based IGLOO nano devices do not require a boot PROM, so there is no vulnerable external bitstream that can be easily copied. IGLOO nano devices incorporate FlashLock, which provides a unique combination of reprogrammability and design security without external overhead, advantages that only an FPGA with nonvolatile flash programming can offer.

IGLOO nano devices utilize a 128-bit flash-based lock and a separate AES key to provide the highest level of security in the FPGA industry for programmed intellectual property and configuration data. In addition, all FlashROM data in IGLOO nano devices can be encrypted prior to loading, using the industry-leading AES-128 (FIPS192) bit block cipher encryption standard. AES was adopted by the National Institute of Standards and Technology (NIST) in 2000 and replaces the 1977 DES standard. IGLOO nano devices have a built-in AES decryption engine and a flash-based AES key that make them the most comprehensive programmable logic device security solution available today. IGLOO nano devices with AES-based security provide a high level of protection for remote field updates over public networks such as the Internet, and are designed to ensure that valuable IP remains out of the hands of system overbuilders, system cloners, and IP thieves.

Security, built into the FPGA fabric, is an inherent component of IGLOO nano devices. The flash cells are located beneath seven metal layers, and many device design and layout techniques have been used to make invasive attacks extremely difficult. IGLOO nano devices, with FlashLock and AES security, are unique in being highly resistant to both invasive and noninvasive attacks. Your valuable IP is protected with industry-standard security, making remote ISP possible. An IGLOO nano device provides the best available security for programmable logic designs.

Single Chip

Flash-based FPGAs store their configuration information in on-chip flash cells. Once programmed, the configuration data is an inherent part of the FPGA structure, and no external configuration data needs to be loaded at system power-up (unlike SRAM-based FPGAs). Therefore, flash-based IGLOO nano FPGAs do not require system configuration components such as EEPROMs or microcontrollers to load device configuration data. This reduces bill-of-materials costs and PCB area, and increases security and system reliability.

Instant On

Microsemi flash-based IGLOO nano devices support Level 0 of the Instant On classification standard. This feature helps in system component initialization, execution of critical tasks before the processor wakes up, setup and configuration of memory blocks, clock generation, and bus activity management. The Instant On feature of flash-based IGLOO nano devices greatly simplifies total system design and reduces total system cost, often eliminating the need for CPLDs and clock generation PLLs. In addition, glitches and brownouts in system power will not corrupt the IGLOO nano device's flash configuration, and unlike SRAM-based FPGAs, the device will not have to be reloaded when system power is restored. This enables the reduction or complete removal of the configuration PROM, expensive voltage monitor, brownout detection, and clock generator devices from the PCB design. Flash-based IGLOO nano devices simplify total system design and reduce cost and design risk while increasing system reliability and improving system initialization time.

IGLOO nano flash FPGAs enable the user to quickly enter and exit Flash*Freeze mode. This is done almost instantly (within 1 µs) and the device retains configuration and data in registers and RAM. Unlike SRAM-based FPGAs, the device does not need to reload configuration and design state from external memory components; instead it retains all necessary information to resume operation immediately.

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Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, performance, and ease of use. Unlike SRAM-based FPGAs, flash-based IGLOO nano devices allow all functionality to be Instant On; no external boot PROM is required. On-board security mechanisms prevent access to all the programming information and enable secure remote updates of the FPGA logic.

Designers can perform secure remote in-system reprogramming to support future design iterations and field upgrades with confidence that valuable intellectual property cannot be compromised or copied. Secure ISP can be performed using the industry-standard AES algorithm. The IGLOO nano device architecture mitigates the need for ASIC migration at higher user volumes. This makes IGLOO nano devices cost-effective ASIC replacement solutions, especially for applications in the consumer, networking/communications, computing, and avionics markets.

With a variety of devices under \$1, IGLOO nano FPGAs enable cost-effective implementation of programmable logic and quick time to market.

Firm-Error Immunity

Firm errors occur most commonly when high-energy neutrons, generated in the upper atmosphere, strike a configuration cell of an SRAM FPGA. The energy of the collision can change the state of the configuration cell and thus change the logic, routing, or I/O behavior in an unpredictable way. These errors are impossible to prevent in SRAM FPGAs. The consequence of this type of error can be a complete system failure. Firm errors do not exist in the configuration memory of IGLOO nano flash-based FPGAs. Once it is programmed, the flash cell configuration element of IGLOO nano FPGAs cannot be altered by high-energy neutrons and is therefore immune to them. Recoverable (or soft) errors occur in the user data SRAM of all FPGA devices. These can easily be mitigated by using error detection and correction (EDAC) circuitry built into the FPGA fabric.

Advanced Flash Technology

The IGLOO nano device offers many benefits, including nonvolatility and reprogrammability, through an advanced flash-based, 130-nm LVCMOS process with seven layers of metal. Standard CMOS design techniques are used to implement logic and control functions. The combination of fine granularity, enhanced flexible routing resources, and abundant flash switches allows for very high logic utilization without compromising device routability or performance. Logic functions within the device are interconnected through a four-level routing hierarchy.

IGLOO nano FPGAs utilize design and process techniques to minimize power consumption in all modes of operation.

Advanced Architecture

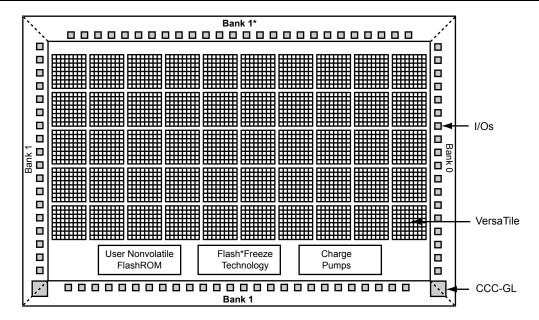
The proprietary IGLOO nano architecture provides granularity comparable to standard-cell ASICs. The IGLOO nano device consists of five distinct and programmable architectural features (Figure 1-3 on page 1-5 to Figure 1-4 on page 1-5):

- Flash*Freeze technology
- FPGA VersaTiles
- Dedicated FlashROM
- Dedicated SRAM/FIFO memory[†]
- Extensive CCCs and PLLs[†]
- Advanced I/O structure

The FPGA core consists of a sea of VersaTiles. Each VersaTile can be configured as a three-input logic function, a D-flip-flop (with or without enable), or a latch by programming the appropriate flash switch interconnections. The versatility of the IGLOO nano core tile as either a three-input lookup table (LUT) equivalent or a D-flip-flop/latch with enable allows for efficient use of the FPGA fabric. The VersaTile capability is unique to the ProASIC[®] family of third-generation-architecture flash FPGAs. VersaTiles are connected with any of the four levels of routing hierarchy. Flash switches are distributed throughout the device to provide nonvolatile, reconfigurable interconnect programming. Maximum core utilization is possible for virtually any design.

[†] The AGLN030 and smaller devices do not support PLL or SRAM.





Note: *Bank 0 for the AGLN030 device

Figure 1-1 • IGLOO Device Architecture Overview with Two I/O Banks and No RAM (AGLN010 and AGLN030)

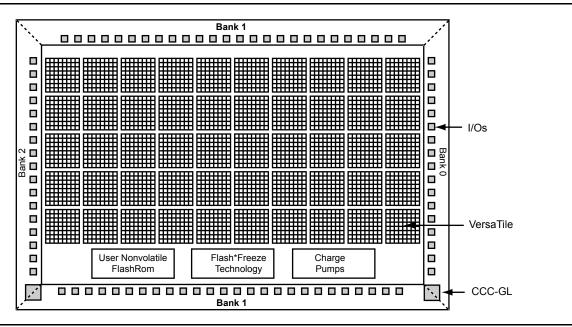


Figure 1-2 • IGLOO Device Architecture Overview with Three I/O Banks and No RAM (AGLN015 and **AGLN020)**

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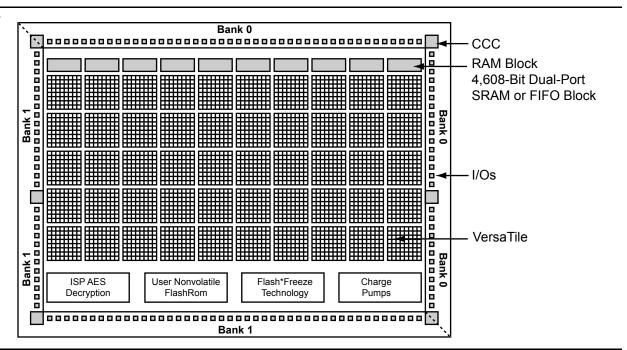


Figure 1-3 • IGLOO Device Architecture Overview with Two I/O Banks (AGLN060, AGLN125)

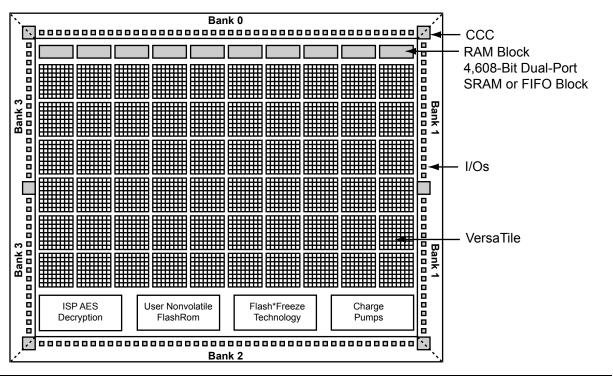


Figure 1-4 • IGLOO Device Architecture Overview with Four I/O Banks (AGLN250)



Flash*Freeze Technology

The IGLOO nano device has an ultra-low power static mode, called Flash*Freeze mode, which retains all SRAM and register information and can still quickly return to normal operation. Flash*Freeze technology enables the user to quickly (within 1 µs) enter and exit Flash*Freeze mode by activating the Flash*Freeze pin while all power supplies are kept at their original values. I/Os, global I/Os, and clocks can still be driven and can be toggling without impact on power consumption, and the device retains all core registers, SRAM information, and I/O states. I/Os can be individually configured to either hold their previous state or be tristated during Flash*Freeze mode.

Alternatively, I/Os can be set to a specific state using weak pull-up or pull-down I/O attribute configuration. No power is consumed by the I/O banks, clocks, JTAG pins, or PLL, and the device consumes as little as $2~\mu W$ in this mode.

Flash*Freeze technology allows the user to switch to Active mode on demand, thus simplifying the power management of the device.

The Flash*Freeze pin (active low) can be routed internally to the core to allow the user's logic to decide when it is safe to transition to this mode. Refer to Figure 1-5 for an illustration of entering/exiting Flash*Freeze mode. It is also possible to use the Flash*Freeze pin as a regular I/O if Flash*Freeze mode usage is not planned.

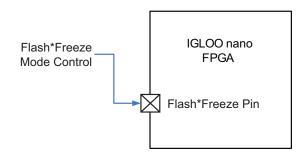


Figure 1-5 • IGLOO nano Flash*Freeze Mode

VersaTiles

The IGLOO nano core consists of VersaTiles, which have been enhanced beyond the ProASIC entry to the IGLOO nano VersaTile supports the following:

- · All 3-input logic functions—LUT-3 equivalent
- · Latch with clear or set
- · D-flip-flop with clear or set
- · Enable D-flip-flop with clear or set

Refer to Figure 1-6 for VersaTile configurations.

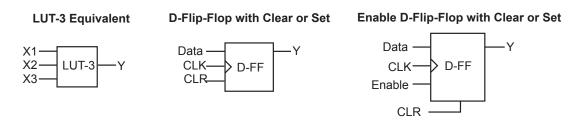


Figure 1-6 • VersaTile Configurations

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User Nonvolatile FlashROM

IGLOO nano devices have 1 kbit of on-chip, user-accessible, nonvolatile FlashROM. The FlashROM can be used in diverse system applications:

- · Internet protocol addressing (wireless or fixed)
- System calibration settings
- · Device serialization and/or inventory control
- · Subscription-based business models (for example, set-top boxes)
- Secure key storage for secure communications algorithms
- Asset management/tracking
- Date stamping
- Version management

The FlashROM is written using the standard IGLOO nano IEEE 1532 JTAG programming interface. The core can be individually programmed (erased and written), and on-chip AES decryption can be used selectively to securely load data over public networks (except in the AGLN030 and smaller devices), as in security keys stored in the FlashROM for a user design.

The FlashROM can be programmed via the JTAG programming interface, and its contents can be read back either through the JTAG programming interface or via direct FPGA core addressing. Note that the FlashROM can only be programmed from the JTAG interface and cannot be programmed from the internal logic array.

The FlashROM is programmed as 8 banks of 128 bits; however, reading is performed on a byte-by-byte basis using a synchronous interface. A 7-bit address from the FPGA core defines which of the 8 banks and which of the 16 bytes within that bank are being read. The three most significant bits (MSBs) of the FlashROM address determine the bank, and the four least significant bits (LSBs) of the FlashROM address define the byte.

The IGLOO nano development software solutions, Libero[®] System-on-Chip (SoC) and Designer, have extensive support for the FlashROM. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature enables the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using Microsemi Libero SoC and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.

SRAM and FIFO

IGLOO nano devices (except the AGLN030 and smaller devices) have embedded SRAM blocks along their north and south sides. Each variable-aspect-ratio SRAM block is 4,608 bits in size. Available memory configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1 bits. The individual blocks have independent read and write ports that can be configured with different bit widths on each port. For example, data can be sent through a 4-bit port and read as a single bitstream. The embedded SRAM blocks can be initialized via the device JTAG port (ROM emulation mode) using the UJTAG macro (except in the AGLN030 and smaller devices).

In addition, every SRAM block has an embedded FIFO control unit. The control unit allows the SRAM block to be configured as a synchronous FIFO without using additional core VersaTiles. The FIFO width and depth are programmable. The FIFO also features programmable Almost Empty (AEMPTY) and Almost Full (AFULL) flags in addition to the normal Empty and Full flags. The embedded FIFO control unit contains the counters necessary for generation of the read and write address pointers. The embedded SRAM/FIFO blocks can be cascaded to create larger configurations.

PLL and CCC

Higher density IGLOO nano devices using either the two I/O bank or four I/O bank architectures provide designers with very flexible clock conditioning capabilities. AGLN060, AGLN125, and AGLN250 contain six CCCs. One CCC (center west side) has a PLL. The AGLN030 and smaller devices use different CCCs in their architecture (CCC-GL). These CCC-GLs contain a global MUX but do not have any PLLs or programmable delays.

For devices using the six CCC block architecture, these are located at the four corners and the centers of the east and west sides. All six CCC blocks are usable; the four corner CCCs and the east CCC allow simple clock delay operations as well as clock spine access.



The inputs of the six CCC blocks are accessible from the FPGA core or from dedicated connections to the CCC block, which are located near the CCC.

The CCC block has these key features:

- Wide input frequency range (f_{IN CCC}) = 1.5 MHz up to 250 MHz
- Output frequency range (f_{OUT CCC}) = 0.75 MHz up to 250 MHz
- · 2 programmable delay types for clock skew minimization
- Clock frequency synthesis (for PLL only)

Additional CCC specifications:

- Internal phase shift = 0°, 90°, 180°, and 270°. Output phase shift depends on the output divider configuration (for PLL only).
- Output duty cycle = 50% ± 1.5% or better (for PLL only)
- Low output jitter: worst case < 2.5% × clock period peak-to-peak period jitter when single global network used (for PLL only)
- Maximum acquisition time is 300 µs (for PLL only)
- Exceptional tolerance to input period jitter—allowable input jitter is up to 1.5 ns (for PLL only)
- Four precise phases; maximum misalignment between adjacent phases of 40 ps × 250 MHz / f_{OUT_CCC} (for PLL only)

Global Clocking

IGLOO nano devices have extensive support for multiple clocking domains. In addition to the CCC and PLL support described above, there is a comprehensive global clock distribution network.

Each VersaTile input and output port has access to nine VersaNets: six chip (main) and three quadrant global networks. The VersaNets can be driven by the CCC or directly accessed from the core via multiplexers (MUXes). The VersaNets can be used to distribute low-skew clock signals or for rapid distribution of high-fanout nets.

I/Os with Advanced I/O Standards

IGLOO nano FPGAs feature a flexible I/O structure, supporting a range of voltages (1.2 V, 1.2 V wide range, 1.5 V, 1.8 V, 2.5 V, 3.0 V wide range, and 3.3 V).

The I/Os are organized into banks with two, three, or four banks per device. The configuration of these banks determines the I/O standards supported.

Each I/O module contains several input, output, and enable registers. These registers allow the implementation of various single-data-rate applications for all versions of nano devices and double-data-rate applications for the AGLN060, AGLN125, and AGLN250 devices.

IGLOO nano devices support LVTTL and LVCMOS I/O standards, are hot-swappable, and support cold-sparing and Schmitt trigger.

Hot-swap (also called hot-plug, or hot-insertion) is the operation of hot-insertion or hot-removal of a card in a powered-up system.

Cold-sparing (also called cold-swap) refers to the ability of a device to leave system data undisturbed when the system is powered up, while the component itself is powered down, or when power supplies are floating.

Wide Range I/O Support

IGLOO nano devices support JEDEC-defined wide range I/O operation. IGLOO nano devices support both the JESD8-B specification, covering both 3 V and 3.3 V supplies, for an effective operating range of 2.7 V to 3.6 V, and JESD8-12 with its 1.2 V nominal, supporting an effective operating range of 1.14 V to 1.575 V.

Wider I/O range means designers can eliminate power supplies or power conditioning components from the board or move to less costly components with greater tolerances. Wide range eases I/O bank management and provides enhanced protection from system voltage spikes, while providing the flexibility to easily run custom voltage applications.

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Specifying I/O States During Programming

You can modify the I/O states during programming in FlashPro. In FlashPro, this feature is supported for PDB files generated from Designer v8.5 or greater. See the *FlashPro User's Guide* for more information.

Note: PDB files generated from Designer v8.1 to Designer v8.4 (including all service packs) have limited display of Pin Numbers only.

- Load a PDB from the FlashPro GUI. You must have a PDB loaded to modify the I/O states during programming.
- 2. From the FlashPro GUI, click PDB Configuration. A FlashPoint Programming File Generator window appears.
- 3. Click the Specify I/O States During Programming button to display the Specify I/O States During Programming dialog box.
- 4. Sort the pins as desired by clicking any of the column headers to sort the entries by that header. Select the I/Os you wish to modify (Figure 1-7 on page 1-9).
- 5. Set the I/O Output State. You can set Basic I/O settings if you want to use the default I/O settings for your pins, or use Custom I/O settings to customize the settings for each pin. Basic I/O state settings:
 - 1 I/O is set to drive out logic High
 - 0 I/O is set to drive out logic Low

Last Known State – I/O is set to the last value that was driven out prior to entering the programming mode, and then held at that value during programming

Z -Tri-State: I/O is tristated

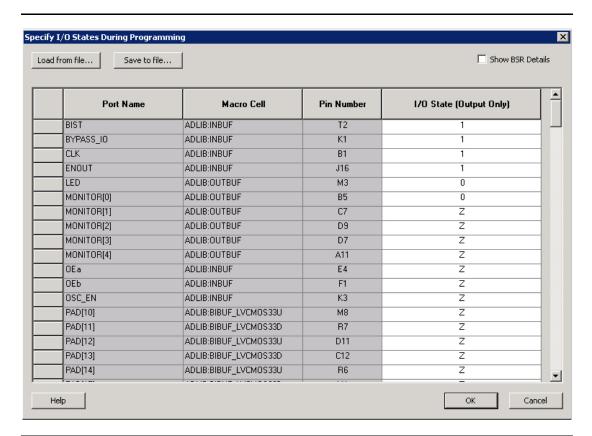


Figure 1-7 • I/O States During Programming Window



IGLOO nano Device Overview

6. Click **OK** to return to the FlashPoint – Programming File Generator window.

Note: I/O States During programming are saved to the ADB and resulting programming files after completing programming file generation.

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2 - IGLOO nano DC and Switching Characteristics

General Specifications

The Z feature grade does not support the enhanced nano features of Schmitt trigger input, Flash*Freeze bus hold (hold previous I/O state in Flash*Freeze mode), cold-sparing, and hot-swap I/O capability. Refer to "IGLOO nano Ordering Information" on page III for more information.

Operating Conditions

Stresses beyond those listed in Table 2-1 may cause permanent damage to the device.

Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Absolute Maximum Ratings are stress ratings only; functional operation of the device at these or any other conditions beyond those listed under the Recommended Operating Conditions specified in Table 2-2 on page 2-2 is not implied.

Table 2-1 • Absolute Maximum Ratings

Symbol	Parameter	Limits	Units
VCC	DC core supply voltage	-0.3 to 1.65	V
VJTAG	JTAG DC voltage	-0.3 to 3.75	V
VPUMP	Programming voltage	-0.3 to 3.75	V
VCCPLL	Analog power supply (PLL)	-0.3 to 1.65	V
VCCI	DC I/O buffer supply voltage	-0.3 to 3.75	V
VI ¹	I/O input voltage	−0.3 V to 3.6 V	V
T _{STG} ²	Storage temperature	-65 to +150	°C
T_J^2	Junction temperature	+125	°C

Notes:

^{1.} The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 2-4 on page 2-3.

^{2.} For flash programming and retention maximum limits, refer to Table 2-3 on page 2-2, and for recommended operating limits, refer to Table 2-2 on page 2-2.

Table 2-2 • Recommended Operating Conditions 1

Symbol	Parameter		Extended Commercial	Industrial	Units
T _J	Junction temperature		$-20 \text{ to} + 85^2$	-40 to +100 ²	°C
VCC	1.5 V DC core supply vo	oltage ³	1.425 to 1.575	1.425 to 1.575	V
	1.2 V–1.5 V wide range	core voltage ^{4,5}	1.14 to 1.575	1.14 to 1.575	V
VJTAG	JTAG DC voltage		1.4 to 3.6	1.4 to 3.6	V
VPUMP ⁶	Programming voltage	Programming mode	3.15 to 3.45	3.15 to 3.45	V
		Operation	0 to 3.6	0 to 3.6	V
VCCPLL ⁷	CPLL ⁷ Analog power supply	1.5 V DC core supply voltage ³	1.425 to 1.575	1.425 to 1.575	V
	(PLL)	1.2 V–1.5 V wide range core supply voltage ⁴	1.14 to 1.575	1.14 to 1.575	V
VCCI and	1.2 V DC supply voltage	. 4	1.14 to 1.26	1.14 to 1.26	V
VMV ^{8,9}	1.2 V DC wide range su	pply voltage ⁴	1.14 to 1.575	1.14 to 1.575	V
	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	3.3 V DC wide range su	pply voltage ¹⁰	2.7 to 3.6	2.7 to 3.6	V

Notes:

- 1. All parameters representing voltages are measured with respect to GND unless otherwise specified.
- 2. Default Junction Temperature Range in the Libero SoC software is set to 0°C to +70°C for commercial, and -40°C to +85°C for industrial. To ensure targeted reliability standards are met across the full range of junction temperatures, Microsemi recommends using custom settings for temperature range before running timing and power analysis tools. For more information regarding custom settings, refer to the New Project Dialog Box in the Libero Online Help.
- 3. For IGLOO® nano V5 devices
- 4. For IGLOO nano V2 devices only, operating at VCCI ≥ VCC
- 5. IGLOO nano V5 devices can be programmed with the VCC core voltage at 1.5 V only. IGLOO nano V2 devices can be programmed with the VCC core voltage at 1.2 V (with FlashPro4 only) or 1.5 V. If you are using FlashPro3 and want to do in-system programming using 1.2 V, please contact the factory.
- 6. V_{PUMP} can be left floating during operation (not programming mode).
- 7. VCCPLL pins should be tied to VCC pins. See the "Pin Descriptions" chapter for further information.
- 8. VMV pins must be connected to the corresponding VCCI pins. See the Pin Descriptions chapter of the IGLOO nano FPGA Fabric User's Guide for further information.
- 9. The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-21 on page 2-19. VCCI should be at the same voltage within a given I/O bank.
- 10. 3.3 V wide range is compliant to the JESD8-B specification and supports 3.0 V VCCI operation.

Table 2-3 • Flash Programming Limits – Retention, Storage, and Operating Temperature¹

Product Grade		Program Retention (biased/unbiased)	Maximum Storage Temperature T _{STG} (°C) ²	Maximum Operating Junction Temperature T _J (°C) ²
Commercial	500	20 years	110	100
Industrial	500	20 years	110	100

Notes:

- 1. This is a stress rating only; functional operation at any condition other than those indicated is not implied.
- These limits apply for program/data retention only. Refer to Table 2-1 on page 2-1 and Table 2-2 for device operating conditions and absolute limits.

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Table 2-4 • Overshoot and Undershoot Limits 1

vccı	Average VCCI–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle ²	Maximum Overshoot/ Undershoot ²
2.7 V or less	10%	1.4 V
	5%	1.49 V
3 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

Notes:

- 1. Based on reliability requirements at 85°C.
- 2. The duration is allowed at one out of six clock cycles. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.

I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every IGLOO nano device. These circuits ensure easy transition from the powered-off state to the powered-up state of the device. The many different supplies can power up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 2-1 on page 2-4.

There are five regions to consider during power-up.

IGLOO nano I/Os are activated only if ALL of the following three conditions are met:

- 1. VCC and VCCI are above the minimum specified trip points (Figure 2-1 and Figure 2-2 on page 2-5).
- 2. VCCI > VCC 0.75 V (typical)
- 3. Chip is in the operating mode.

VCCI Trip Point:

Ramping up (V5 devices): 0.6 V < trip_point_up < 1.2 V Ramping down (V5 devices): 0.5 V < trip_point_down < 1.1 V Ramping up (V2 devices): 0.75 V < trip_point_up < 1.05 V Ramping down (V2 devices): 0.65 V < trip_point_down < 0.95 V

VCC Trip Point:

Ramping up (V5 devices): 0.6 V < trip_point_up < 1.1 V
Ramping down (V5 devices): 0.5 V < trip_point_down < 1.0 V
Ramping up (V2 devices): 0.65 V < trip_point_up < 1.05 V
Ramping down (V2 devices): 0.55 V < trip_point_down < 0.95 V

VCC and VCCI ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

- During programming, I/Os become tristated and weakly pulled up to VCCI.
- JTAG supply, PLL power supplies, and charge pump VPUMP supply have no influence on I/O behavior.

PLL Behavior at Brownout Condition

Microsemi recommends using monotonic power supplies or voltage regulators to ensure proper powerup behavior. Power ramp-up should be monotonic at least until VCC and VCCPLX exceed brownout activation levels (see Figure 2-1 and Figure 2-2 on page 2-5 for more details).

When PLL power supply voltage and/or VCC levels drop below the VCC brownout levels (0.75 V \pm 0.25 V for V5 devices, and 0.75 V \pm 0.2 V for V2 devices), the PLL output lock signal goes LOW and/or the output clock is lost. Refer to the "Brownout Voltage" section in the "Power-Up/-Down Behavior of Low Power Flash Devices" chapter of the *IGLOO nano FPGA Fabric User's Guide* for information on clock and lock recovery.

Internal Power-Up Activation Sequence

- Core
- 2. Input buffers
- 3. Output buffers, after 200 ns delay from input buffer activation

To make sure the transition from input buffers to output buffers is clean, ensure that there is no path longer than 100 ns from input buffer to output buffer in your design.

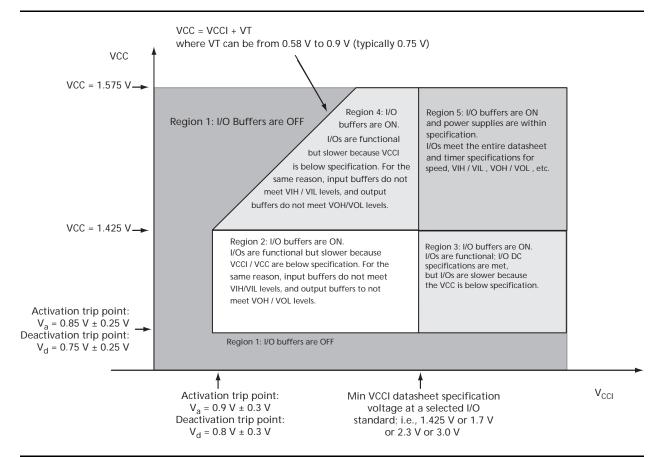


Figure 2-1 • V5 Devices – I/O State as a Function of VCCI and VCC Voltage Levels

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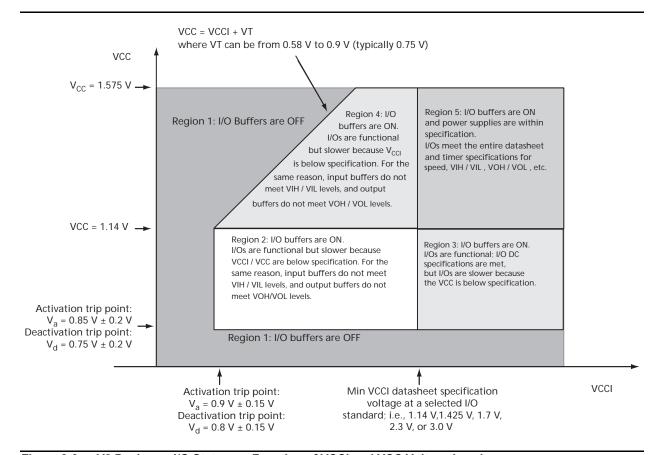


Figure 2-2 • V2 Devices – I/O State as a Function of VCCI and VCC Voltage Levels

Thermal Characteristics

Introduction

The temperature variable in the Microsemi Designer software refers to the junction temperature, not the ambient temperature. This is an important distinction because dynamic and static power consumption cause the chip junction temperature to be higher than the ambient temperature.

EQ 1 can be used to calculate junction temperature.

$$T_J$$
 = Junction Temperature = $\Delta T + T_A$

EQ 1

where:

 T_A = Ambient temperature

 ΔT = Temperature gradient between junction (silicon) and ambient ΔT = θ_{ia} * P

 θ_{ia} = Junction-to-ambient of the package. θ_{ia} numbers are located in Figure 2-5.

P = Power dissipation

Package Thermal Characteristics

The device junction-to-case thermal resistivity is θ_{jc} and the junction-to-ambient air thermal resistivity is θ_{ja} . The thermal characteristics for θ_{ja} are shown for two air flow rates. The maximum operating junction temperature is 100°C. EQ 2 shows a sample calculation of the maximum operating power dissipation allowed for a 484-pin FBGA package at commercial temperature and in still air.

Maximum Power Allowed =
$$\frac{\text{Max. junction temp. (°C)} - \text{Max. ambient temp. (°C)}}{\theta_{ja}(°\text{C/W})} = \frac{100°\text{C} - 70°\text{C}}{20.5°\text{C/W}} = 1.46~\text{W}$$

EQ 2

Table 2-5 • Package Thermal Resistivities

Package Type	Pin Count	θ _{jc}	Still Air	200 ft./ min.	500 ft./ min.	Units
Chip Scale Package (CSP)	36	TBD	TBD	TBD	TBD	C/W
	81	TBD	TBD	TBD	TBD	C/W
Quad Flat No Lead (QFN)	48	TBD	TBD	TBD	TBD	C/W
	68	TBD	TBD	TBD	TBD	C/W
	100	TBD	TBD	TBD	TBD	C/W
Very Thin Quad Flat Pack (VQFP)	100	10.0	35.3	29.4	27.1	C/W

Temperature and Voltage Derating Factors

Table 2-6 • Temperature and Voltage Derating Factors for Timing Delays (normalized to T_J = 70°C, VCC = 1.425 V)

For IGLOO nano V2 or V5 Devices, 1.5 V DC Core Supply Voltage

Array Voltage	Junction Temperature (°C)										
VCC (V)	-40°C	–20°C	0°C	25°C	70°C	85°C	100°C				
1.425	0.947	0.956	0.965	0.978	1.000	1.009	1.013				
1.5	0.875	0.883	0.892	0.904	0.925	0.932	0.937				
1.575	0.821	0.829	0.837	0.848	0.868	0.875	0.879				

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Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays (normalized to T_J = 70°C, VCC = 1.14 V)

For IGLOO nano V2, 1.2 V DC Core Supply Voltage

Array Voltage	Junction Temperature (°C)									
VCC (V)	-40°C	-20°C	0°C	25°C	70°C	85°C	100°C			
1.14	0.968	0.974	0.979	0.991	1.000	1.006	1.009			
1.2	0.863	0.868	0.873	0.884	0.892	0.898	0.901			
1.26	0.792	0.797	0.801	0.811	0.819	0.824	0.827			

Calculating Power Dissipation

Quiescent Supply Current

Quiescent supply current (IDD) calculation depends on multiple factors, including operating voltages (VCC, VCCI, and VJTAG), operating temperature, system clock frequency, and power mode usage. Microsemi recommends using the Power Calculator and SmartPower software estimation tools to evaluate the projected static and active power based on the user design, power mode usage, operating voltage, and temperature.

Table 2-8 • Power Supply State per Mode

	Power Supply Configurations								
Modes/Power Supplies	VCC	VCCPLL	VCCI	VJTAG	VPUMP				
Flash*Freeze	On	On	On	On	On/off/floating				
Sleep	Off	Off	On	Off	Off				
Shutdown	Off	Off	Off	Off	Off				
No Flash*Freeze	On	On	On	On	On/off/floating				

Note: Off: Power Supply level = 0 V

Table 2-9 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Flash*Freeze Mode*

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
Typical (25°C)	1.2 V	1.9	3.3	3.3	8	13	20	μΑ
	1.5 V	5.8	6	6	10	18	34	μΑ

Note: *IDD includes VCC, VPUMP, VCCI, VCCPLL, and VMV currents. Values do not include I/O static contribution, which is shown in Table 2-13 on page 2-9 through Table 2-14 on page 2-9 and Table 2-15 on page 2-10 through Table 2-18 on page 2-11 (PDC6 and PDC7).

Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Sleep Mode*

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
VCCI= 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	1.7	1.7	1.7	1.7	μΑ
VCCI = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	1.8	1.8	1.8	1.8	μΑ
VCCI = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	1.9	1.9	1.9	1.9	μΑ
VCCI = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	2.2	2.2	2.2	2.2	μΑ
VCCI = 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	2.5	2.5	2.5	2.5	μΑ

Note: $*I_{DD} = N_{BANKS} * I_{CCI}$

Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Shutdown Mode

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
Typical (25°C)	1.2 V / 1.5 V	0	0	0	0	0	0	μА

Table 2-12 • Quiescent Supply Current (IDD), No IGLOO nano Flash*Freeze Mode¹

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units			
ICCA Current ²											
Typical (25°C)	1.2 V	3.7	5	5	10	13	18	μA			
	1.5 V	8	14	14	20	28	44	μΑ			
ICCI or IJTAG Current	CCI or IJTAG Current										
VCCI / VJTAG = 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	1.7	1.7	1.7	1.7	μA			
VCCI / VJTAG = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	1.8	1.8	1.8	1.8	μA			
VCCI / VJTAG = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	1.9	1.9	1.9	1.9	μA			
VCCI / VJTAG = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	2.2	2.2	2.2	2.2	μA			
VCCI / VJTAG = 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	2.5	2.5	2.5	2.5	μA			

Notes:

- 1. $IDD = N_{BANKS} * ICCI + ICCA$. JTAG counts as one bank when powered. 2. Includes VCC, VCCPLL, and VPUMP currents.

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Power per I/O Pin

Table 2-13 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings Applicable to IGLOO nano I/O Banks

	VCCI (V)	Dynamic Power PAC9 (μW/MHz) ¹
Single-Ended		
3.3 V LVTTL / 3.3 V LVCMOS	3.3	16.38
3.3 V LVTTL / 3.3 V LVCMOS – Schmitt Trigger	3.3	18.89
3.3 V LVCMOS Wide Range ²	3.3	16.38
3.3 V LVCMOS Wide Range – Schmitt Trigger	3.3	18.89
2.5 V LVCMOS	2.5	4.71
2.5 V LVCMOS – Schmitt Trigger	2.5	6.13
1.8 V LVCMOS	1.8	1.64
1.8 V LVCMOS – Schmitt Trigger	1.8	1.79
1.5 V LVCMOS (JESD8-11)	1.5	0.97
1.5 V LVCMOS (JESD8-11) – Schmitt Trigger	1.5	0.96
1.2 V LVCMOS ³	1.2	0.57
1.2 V LVCMOS – Schmitt Trigger ³	1.2	0.52
1.2 V LVCMOS Wide Range ³	1.2	0.57
1.2 V LVCMOS Wide Range – Schmitt Trigger ³	1.2	0.52

Notes:

- 1. PAC9 is the total dynamic power measured on V_{CCI}.
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 3. Applicable to IGLOO nano V2 devices operating at VCCI ≥ VCC.

Table 2-14 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings¹
Applicable to IGLOO nano I/O Banks

	C _{LOAD} (pF)	VCCI (V)	Dynamic Power PAC10 (μW/MHz) ²
Single-Ended			
3.3 V LVTTL / 3.3 V LVCMOS	5	3.3	107.98
3.3 V LVCMOS Wide Range ³	5	3.3	107.98
2.5 V LVCMOS	5	2.5	61.24
1.8 V LVCMOS	5	1.8	31.28
1.5 V LVCMOS (JESD8-11)	5	1.5	21.50
1.2 V LVCMOS ⁴	5	1.2	15.22

Notes:

- 1. Dynamic power consumption is given for standard load and software default drive strength and output slew.
- 2. PAC10 is the total dynamic power measured on VCCI.
- 3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 4. Applicable for IGLOO nano V2 devices operating at VCCI ≥ VCC.

Power Consumption of Various Internal Resources

Table 2-15 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices For IGLOO nano V2 or V5 Devices, 1.5 V Core Supply Voltage

			Device Spe	ecific Dyna	mic Power	· (µW/MHz)		
Parameter	Definition	AGLN250	AGLN125	AGLN060	AGLN020	AGLN015	AGLN010	
PAC1	Clock contribution of a Global Rib	4.421	4.493	2.700	0	0	0	
PAC2	Clock contribution of a Global Spine	2.704	1.976	1.982	4.002	4.002	2.633	
PAC3	Clock contribution of a VersaTile row	1.496	1.504	1.511	1.346	1.346	1.340	
PAC4	Clock contribution of a VersaTile used as a sequential module	0.152 0.153 0.153 0.148 0.148 0.14						
PAC5	First contribution of a VersaTile used as a sequential module	0.057						
PAC6	Second contribution of a VersaTile used as a sequential module	0.207						
PAC7	Contribution of a VersaTile used as a combinatorial module			0.1	17			
PAC8	Average contribution of a routing net			0.	.7			
PAC9	Contribution of an I/O input pin (standard-dependent)		Se	e Table 2-13	3 on page 2	?-9.		
PAC10	Contribution of an I/O output pin (standard-dependent)			See Tab	le 2-14.			
PAC11	Average contribution of a RAM block during a read operation	25.00 N/A						
PAC12	Average contribution of a RAM block during a write operation	30.00 N/A						
PAC13	Dynamic contribution for PLL		2.70			N/A		

Table 2-16 • Different Components Contributing to the Static Power Consumption in IGLOO nano Devices For IGLOO nano V2 or V5 Devices, 1.5 V Core Supply Voltage

			Device	-Specific	Static Powe	er (mW)		
Parameter	Definition	AGLN250	AGLN125	AGLN060	AGLN020	AGLN015	AGLN010	
PDC1	Array static power in Active mode	See Table 2-12 on page 2-8						
	Array static power in Static (Idle) mode	See Table 2-12 on page 2-8						
	Array static power in Flash*Freeze mode	See Table 2-9 on page 2-7						
PDC4 ¹	Static PLL contribution		1.84			N/A		
PDC5	Bank quiescent power (VCCI-dependent) ²	See Table 2-12 on page 2-8						

Notes:

- 1. Minimum contribution of the PLL when running at lowest frequency.
- 2. For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power spreadsheet calculator or the SmartPower tool in Libero SoC.

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Table 2-17 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices For IGLOO nano V2 Devices, 1.2 V Core Supply Voltage

		Device-Specific Dynamic Power (μW/MHz)						
Parameter	Definition	AGLN250	AGLN125	AGLN060	AGLN020	AGLN015	AGLN010	
PAC1	Clock contribution of a Global Rib	2.829	2.875	1.728	0	0	0	
PAC2	Clock contribution of a Global Spine	1.731	1.265	1.268	2.562	2.562	1.685	
PAC3	Clock contribution of a VersaTile row	0.957	0.963	0.967	0.862	0.862	0.858	
PAC4	Clock contribution of a VersaTile used as a sequential module	0.098	0.098	0.098	0.094	0.094	0.091	
PAC5	First contribution of a VersaTile used as a sequential module			0.0	45			
PAC6	Second contribution of a VersaTile used as a sequential module	0.186						
PAC7	Contribution of a VersaTile used as a combinatorial module	0.11						
PAC8	Average contribution of a routing net	0.45						
PAC9	Contribution of an I/O input pin (standard-dependent)	See Table 2-13 on page 2-9						
PAC10	Contribution of an I/O output pin (standard-dependent)	See Table 2-14 on page 2-9						
PAC11	Average contribution of a RAM block during a read operation	25.00			N/A			
PAC12	Average contribution of a RAM block during a write operation	30.00 N/A						
PAC13	Dynamic contribution for PLL		2.10			N/A		

Table 2-18 • Different Components Contributing to the Static Power Consumption in IGLOO nano Devices For IGLOO nano V2 Devices, 1.2 V Core Supply Voltage

			Device-Specific Static Power (mW)				
Parameter	Definition	AGLN250	AGLN125	AGLN060	AGLN020	AGLN015	AGLN010
PDC1	Array static power in Active mode		See Table 2-12 on page 2-8				
PDC2	Array static power in Static (Idle) mode		See Table 2-12 on page 2-8				
PDC3	Array static power in Flash*Freeze mode	See Table 2-9 on page 2-7					
PDC4 ¹	Static PLL contribution	0.90 N/A					
PDC5	Bank quiescent power (VCCI-dependent) ²	See Table 2-12 on page 2-8					

Notes:

- 1. Minimum contribution of the PLL when running at lowest frequency.
- 2. For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power spreadsheet calculator or the SmartPower tool in Libero SoC.

Power Calculation Methodology

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in Libero SoC software.

The power calculation methodology described below uses the following variables:

- · The number of PLLs as well as the number and the frequency of each output clock generated
- · The number of combinatorial and sequential cells used in the design
- · The internal clock frequencies
- · The number and the standard of I/O pins used in the design
- · The number of RAM blocks used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in Table 2-19 on page 2-14.
- Enable rates of output buffers—guidelines are provided for typical applications in Table 2-20 on page 2-14.
- Read rate and write rate to the memory—guidelines are provided for typical applications in Table 2-20 on page 2-14. The calculation should be repeated for each clock domain defined in the design.

Methodology

Total Power Consumption—P_{TOTAL}

 $P_{TOTAL} = P_{STAT} + P_{DYN}$

P_{STAT} is the total static power consumption.

P_{DYN} is the total dynamic power consumption.

Total Static Power Consumption—P_{STAT}

P_{STAT} = (PDC1 or PDC2 or PDC3) + N_{BANKS} * PDC5

N_{BANKS} is the number of I/O banks powered in the design.

Total Dynamic Power Consumption—P_{DYN}

PDYN = PCLOCK + PS-CELL + PC-CELL + PNET + PINPUTS + POUTPUTS + PMEMORY + PPLL

Global Clock Contribution—P_{CLOCK}

```
P<sub>CLOCK</sub> = (PAC1 + N<sub>SPINE</sub> * PAC2 + N<sub>ROW</sub> * PAC3 + N<sub>S-CELL</sub>* PAC4) * F<sub>CLK</sub>
```

N_{SPINE} is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the *IGLOO nano FPGA Fabric User's Guide*.

N_{ROW} is the number of VersaTile rows used in the design—guidelines are provided in the "Spine Architecture" section of the *IGLOO nano FPGA Fabric User's Guide*.

F_{CLK} is the global clock signal frequency.

N_{S-CFLL} is the number of VersaTiles used as sequential modules in the design.

PAC1, PAC2, PAC3, and PAC4 are device-dependent.

Sequential Cells Contribution—P_{S-CELL}

```
P_{S-CELL} = N_{S-CELL} * (PAC5 + \alpha_1 / 2 * PAC6) * F_{CLK}
```

N_{S-CELL} is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

 α_{1} is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-14.

F_{CLK} is the global clock signal frequency.

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Combinatorial Cells Contribution—P_{C-CELL}

 $P_{C-CELL} = N_{C-CELL} * \alpha_1 / 2 * PAC7 * F_{CLK}$

N_{C-CFLL} is the number of VersaTiles used as combinatorial modules in the design.

 α_1 is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-14.

F_{CLK} is the global clock signal frequency.

Routing Net Contribution—P_{NET}

 $P_{NET} = (N_{S-CELL} + N_{C-CELL}) * \alpha_1 / 2 * PAC8 * F_{CLK}$

N_{S-CELL} is the number of VersaTiles used as sequential modules in the design.

N_{C-CFLL} is the number of VersaTiles used as combinatorial modules in the design.

 α_1 is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-14.

F_{CLK} is the global clock signal frequency.

I/O Input Buffer Contribution—PINPUTS

 $P_{INPUTS} = N_{INPUTS} * \alpha_2 / 2 * PAC9 * F_{CLK}$

N_{INPUTS} is the number of I/O input buffers used in the design.

 α_2 is the I/O buffer toggle rate—guidelines are provided in Table 2-19 on page 2-14.

F_{CLK} is the global clock signal frequency.

I/O Output Buffer Contribution—POUTPUTS

 $P_{OUTPUTS} = N_{OUTPUTS} * \alpha_2 / 2 * \beta_1 * PAC10 * F_{CLK}$

 $N_{\mbox{OUTPUTS}}$ is the number of I/O output buffers used in the design.

 α_2 is the I/O buffer toggle rate—guidelines are provided in Table 2-19 on page 2-14.

 β_1 is the I/O buffer enable rate—guidelines are provided in Table 2-20 on page 2-14.

F_{CLK} is the global clock signal frequency.

RAM Contribution—P_{MEMORY}

 $\mathsf{P}_{\mathsf{MEMORY}} = \mathsf{PAC11} * \mathsf{N}_{\mathsf{BLOCKS}} * \mathsf{F}_{\mathsf{READ\text{-}CLOCK}} * \beta_2 + \mathsf{PAC12} * \mathsf{N}_{\mathsf{BLOCK}} * \mathsf{F}_{\mathsf{WRITE\text{-}CLOCK}} * \beta_3$

N_{BLOCKS} is the number of RAM blocks used in the design.

F_{READ-CLOCK} is the memory read clock frequency.

 β_2 is the RAM enable rate for read operations.

 $F_{WRITE\text{-}CLOCK}$ is the memory write clock frequency.

 β_3 is the RAM enable rate for write operations—guidelines are provided in Table 2-20 on page 2-14.

PLL Contribution—P_{PLL}

P_{PLL} = PDC4 + PAC13 *F_{CLKOUT}

F_{CLKOUT} is the output clock frequency.¹

If a PLL is used to generate more than one output clock, include each output clock in the formula by adding its corresponding contribution (PAC13* FCLKOUT product) to the total PLL contribution.

Guidelines

Toggle Rate Definition

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that this net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100% because all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
 - Bit 0 (LSB) = 100%
 - Bit 1 = 50%
 - Bit 2 = 25%
 - ...
 - Bit 7 (MSB) = 0.78125%
 - Average toggle rate = (100% + 50% + 25% + 12.5% + . . . + 0.78125%) / 8

Enable Rate Definition

Output enable rate is the average percentage of time during which tristate outputs are enabled. When nontristate output buffers are used, the enable rate should be 100%.

Table 2-19 • Toggle Rate Guidelines Recommended for Power Calculation

Component Definition		Guideline
α_1	Toggle rate of VersaTile outputs	10%
α_2	I/O buffer toggle rate	10%

Table 2-20 • Enable Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
β_1	I/O output buffer enable rate	100%
β_2	RAM enable rate for read operations	12.5%
β_3	RAM enable rate for write operations	12.5%

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User I/O Characteristics

Timing Model

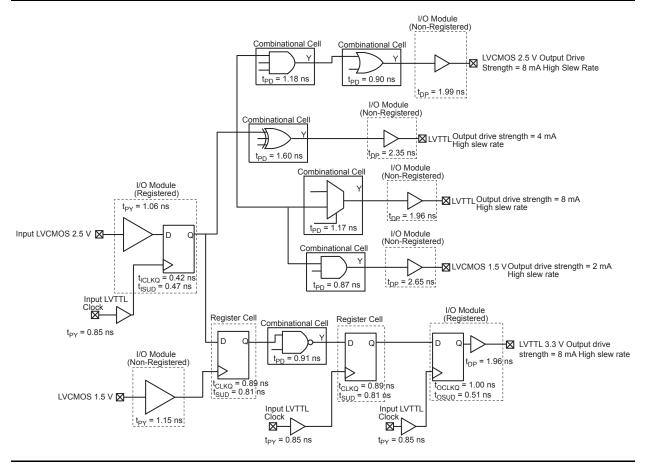
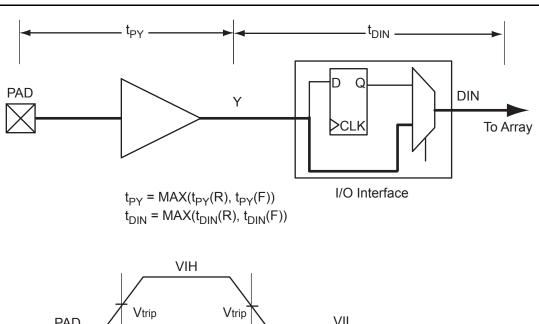


Figure 2-3 • Timing Model
Operating Conditions: STD Speed, Commercial Temperature Range (T_J = 70°C), Worst-Case
VCC = 1.425 V, for DC 1.5 V Core Voltage, Applicable to V2 and V5 Devices





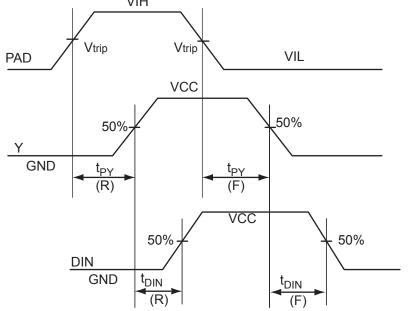


Figure 2-4 • Input Buffer Timing Model and Delays (example)

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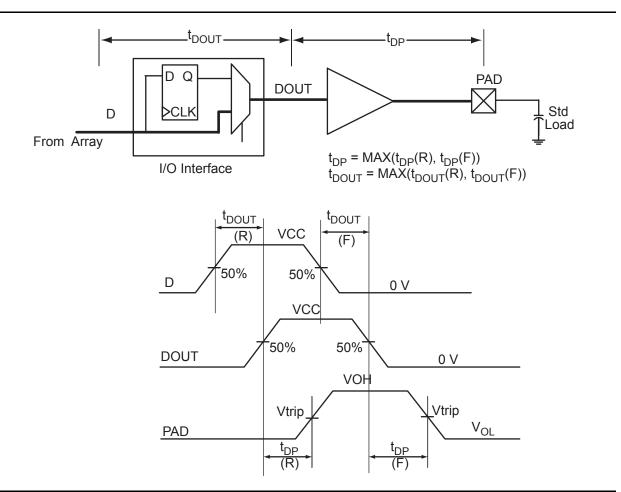


Figure 2-5 • Output Buffer Model and Delays (example)



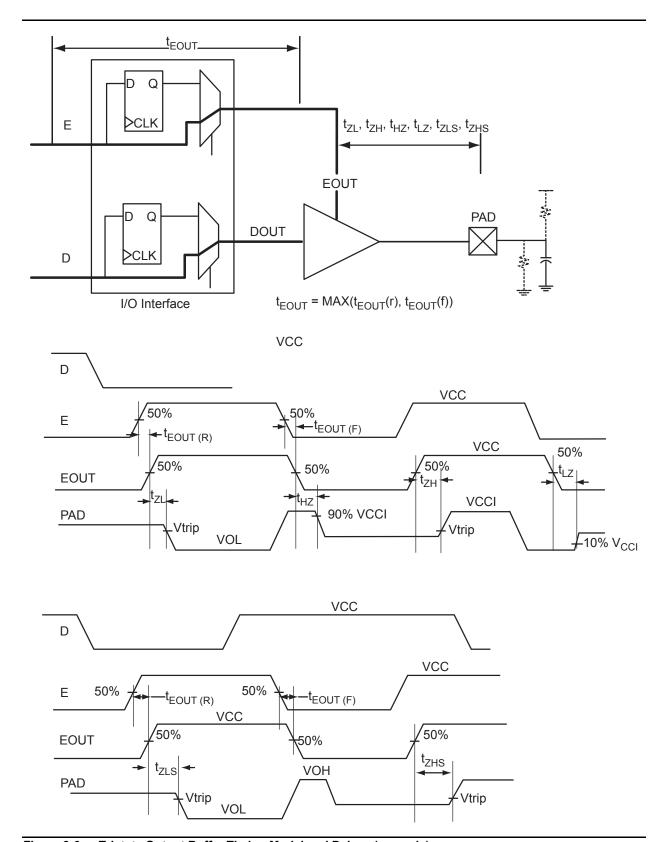


Figure 2-6 • Tristate Output Buffer Timing Model and Delays (example)

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Overview of I/O Performance

Summary of I/O DC Input and Output Levels – Default I/O Software Settings

Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels
Applicable to Commercial and Industrial Conditions—Software Default Settings

		Equivalent			VIL	VIH		VOL	VOH	IOL ¹	IOH ¹
I/O Standard	Drive Strength	Software Default Drive Strength ²	Slew Rate	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	8 mA	High	-0.3	0.8	2	3.6	0.4	2.4	8	8
3.3 V LVCMOS Wide Range ³	100 µA	8 mA	High	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	100 μΑ	100 μΑ
2.5 V LVCMOS	8 mA	8 mA	High	-0.3	0.7	1.7	3.6	0.7	1.7	8	8
1.8 V LVCMOS	4 mA	4 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4
1.5 V LVCMOS	2 mA	2 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2
1.2 V LVCMOS ⁴	1 mA	1 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	1	1
1.2 V LVCMOS Wide Range ^{4,5}	100 µA	1 mA	High	-0.3	0.3 * VCCI	0.7 * VCCI	3.6	0.1	VCCI - 0.1	100 μΑ	100 μΑ

Notes:

- 1. Currents are measured at 85°C junction temperature.
- 2. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
- 4. Applicable to IGLOO nano V2 devices operating at VCCI ≥ VCC.
- 5. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range, as specified in the JESD8-12 specification.

Table 2-22 • Summary of Maximum and Minimum DC Input Levels
Applicable to Commercial and Industrial Conditions

	Comi	nercial ¹	Industrial ²		
	IIL ³	IIH ⁴	IIL ³	IIH ⁴	
DC I/O Standards	μA	μΑ	μΑ	μΑ	
3.3 V LVTTL / 3.3 V LVCMOS	10	10	15	15	
3.3 V LVCOMS Wide Range	10	10	15	15	
2.5 V LVCMOS	10	10	15	15	
1.8 V LVCMOS	10	10	15	15	
1.5 V LVCMOS	10	10	15	15	
1.2 V LVCMOS ⁵	10	10	15	15	
1.2 V LVCMOS Wide Range ⁵	10	10	15	15	

Notes:

- 1. Commercial range (-20° C < T_A < 70° C)
- 2. Industrial range (-40°C < T_A < 85°C)
- 3. I_{IH} is the input leakage current per I/O pin over recommended operating conditions, where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 4. I_{II} is the input leakage current per I/O pin over recommended operating conditions, where -0.3 V < VIN < VIL.
- 5. Applicable to IGLOO nano V2 devices operating at VCCI ≥ VCC.

Summary of I/O Timing Characteristics – Default I/O Software Settings

Table 2-23 • Summary of AC Measuring Points

Standard	Measuring Trip Point (Vtrip)
3.3 V LVTTL / 3.3 V LVCMOS	1.4 V
3.3 V LVCMOS Wide Range	1.4 V
2.5 V LVCMOS	1.2 V
1.8 V LVCMOS	0.90 V
1.5 V LVCMOS	0.75 V
1.2 V LVCMOS	0.60 V
1.2 V LVCMOS Wide Range	0.60 V

Table 2-24 • I/O AC Parameter Definitions

Parameter	Parameter Definition		
t _{DP}	Data to Pad delay through the Output Buffer		
t _{PY}	Pad to Data delay through the Input Buffer		
t _{DOUT}	Data to Output Buffer delay through the I/O interface		
t _{EOUT}	Enable to Output Buffer Tristate Control delay through the I/O interface		
t _{DIN}	Input Buffer to Data delay through the I/O interface		
t_{HZ}	Enable to Pad delay through the Output Buffer—HIGH to Z		
t _{ZH}	Enable to Pad delay through the Output Buffer—Z to HIGH		
t_{LZ}	Enable to Pad delay through the Output Buffer—LOW to Z		
t_{ZL}	Enable to Pad delay through the Output Buffer—Z to LOW		
t _{ZHS}	Enable to Pad delay through the Output Buffer with delayed enable—Z to HIGH		
t _{ZLS}	Enable to Pad delay through the Output Buffer with delayed enable—Z to LOW		

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Applies to IGLOO nano at 1.5 V Core Operating Conditions

Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings STD Speed Grade, Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equivalent Software Default t Drive Strength Option ¹	Slew Rate	Capacitive Load (pF)	tроит	top	[‡] DIN	t _р ү	tpys	teour	^t ZL	tz ¹	t _{LZ}	t _{HZ}	Units
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	8 mA	High	5 pF	0.97	1.79	0.19	0.86	1.16	0.66	1.83	1.45	1.98	2.38	ns
3.3 V LVCMOS Wide Range ²	100 μΑ	8 mA	High	5 pF	0.97	2.56	0.19	1.20	1.66	0.66	2.57	2.02	2.82	3.31	ns
2.5 V LVCMOS	8 mA	8 mA	High	5 pF	0.97	1.81	0.19	1.10	1.24	0.66	1.85	1.63	1.97	2.26	ns
1.8 V LVCMOS	4 mA	4 mA	High	5 pF	0.97	2.08	0.19	1.03	1.44	0.66	2.12	1.95	1.99	2.19	ns
1.5 V LVCMOS	2 mA	2 mA	High	5 pF	0.97	2.39	0.19	1.19	1.52	0.66	2.44	2.24	2.02	2.15	ns

Notes:

- The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to IGLOO nano at 1.2 V Core Operating Conditions

Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings
STD Speed Grade, Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equiv. Software Default Drive Strength Option ¹	Slew Rate	Capacitive Load (pF)	tвоит	[€] DP	[‡] DIN	tpy)	t _{PYS}	^t EOUT	tzı.	tzн	t _{LZ}	thz	Units
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	8 mA	High	5 pF	1.55	2.31	0.26	0.97	1.36	1.10	2.34	1.90	2.43	3.14	ns
3.3 V LVCMOS Wide Range ²	100 μΑ	8 mA	High	5 pF	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns
2.5 V LVCMOS	8 mA	8 mA	High	5 pF	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns
1.8 V LVCMOS	4 mA	4 mA	High	5 pF	1.55	2.49	0.26	1.13	1.59	1.10	2.53	2.34	2.42	2.81	ns
1.5 V LVCMOS	2 mA	2 mA	High	5 pF	1.55	2.78	0.26	1.27	1.77	1.10	2.82	2.62	2.44	2.74	ns
1.2 V LVCMOS	1 mA	1 mA	High	5 pF	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns
1.2 V LVCMOS Wide Range ³	100 μΑ	1 mA	High	5 pF	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns

Notes:

- The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models..
- 2. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
- 3. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V side range as specified in the JESD8-12 specification.
- 4. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Detailed I/O DC Characteristics

Table 2-27 • Input Capacitance

Symbol	Definition	Conditions	Min.	Max.	Units
C _{IN}	Input capacitance	VIN = 0, f = 1.0 MHz		8	pF
C _{INCLK}	Input capacitance on the clock pin	VIN = 0, f = 1.0 MHz		8	pF

Table 2-28 • I/O Output Buffer Maximum Resistances ¹

Standard	Drive Strength	$R_{PULL-DOWN} \ (\Omega)^2$	R _{PULL-UP} (Ω) ³				
3.3 V LVTTL / 3.3V LVCMOS	2 mA	100	300				
	4 mA	100	300				
	6 mA	50	150				
	8 mA	50	150				
3.3 V LVCMOS Wide Range	100 μΑ	Same as equivalent software default drive					
2.5 V LVCMOS	2 mA	100	200				
	4 mA	100	200				
	6 mA	50	100				
	8 mA	50	100				
1.8 V LVCMOS	2 mA	200	225				
	4 mA	100	112				
1.5 V LVCMOS	2 mA	200	224				
1.2 V LVCMOS ⁴	1 mA	315	315				
1.2 V LVCMOS Wide Range ⁴	100 μΑ	315	315				

Notes:

^{1.} These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCCI, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models posted at http://www.microsemi.com/soc/download/ibis/default.aspx.

^{2.} $R_{(PULL\text{-}DOWN\text{-}MAX)} = (VOLspec) / IOLspec$

^{3.} $R_{(PULL-UP-MAX)} = (VCCImax - VOHspec) / I_{OHspec}$

^{4.} Applicable to IGLOO nano V2 devices operating at VCCI ≥ VCC.

Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

	R _{(WEAK PI}	_{JLL-UP)} 1 (Ω)	R _{(WEAK PULL}	$-DOWN)^2$ (Ω)
VCCI	Min.	Max.	Min.	Max.
3.3 V	10 K	45 K	10 K	45 K
3.3 V (wide range I/Os)	10 K	45 K	10 K	45 K
2.5 V	11 K	55 K	12 K	74 K
1.8 V	18 K	70 K	17 K	110 K
1.5 V	19 K	90 K	19 K	140 K
1.2 V	25 K	110 K	25 K	150 K
1.2 V (wide range I/Os)	19 K	110 K	19 K	150 K

Notes:

- 1. $R_{(WEAK\ PULL\ -UP\ -MAX)} = (VCCImax\ VOHspec)\ /\ I_{(WEAK\ PULL\ -UP\ -MIN)}$ 2. $R_{(WEAK\ PULL\ -DOWN\ -MAX)} = (VOLspec)\ /\ I_{(WEAK\ PULL\ -DOWN\ -MIN)}$

Table 2-30 • I/O Short Currents IOSH/IOSL

	Drive Strength	IOSL (mA)*	IOSH (mA)*
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	54	
3.3 V LVCMOS Wide Range	100 μΑ	Same as equivalent	software default drive
2.5 V LVCMOS	2 mA	16	18
	4 mA	16	18
	6 mA	32	37
	8 mA	32	37
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
1.5 V LVCMOS	2 mA	13	16
1.2 V LVCMOS	1 mA	10	13
1.2 V LVCMOS Wide Range	100 μΑ	10	13

Note: $*T_J = 100^{\circ}C$

2-24 Revision 17 The length of time an I/O can withstand IOSH/IOSL events depends on the junction temperature. The reliability data below is based on a 3.3 V, 8 mA I/O setting, which is the worst case for this type of analysis.

For example, at 100°C, the short current condition would have to be sustained for more than six months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

Table 2-31 • Duration of Short Circuit Event before Failure

Temperature	Time before Failure
-40°C	> 20 years
-20°C	> 20 years
0°C	> 20 years
25°C	> 20 years
70°C	5 years
85°C	2 years
100°C	6 months

Table 2-32 • Schmitt Trigger Input Hysteresis
Hysteresis Voltage Value (Typ.) for Schmitt Mode Input Buffers

Input Buffer Configuration	Hysteresis Value (typ.)
3.3 V LVTTL / LVCMOS (Schmitt trigger mode)	240 mV
2.5 V LVCMOS (Schmitt trigger mode)	140 mV
1.8 V LVCMOS (Schmitt trigger mode)	80 mV
1.5 V LVCMOS (Schmitt trigger mode)	60 mV
1.2 V LVCMOS (Schmitt trigger mode)	40 mV

Table 2-33 • I/O Input Rise Time, Fall Time, and Related I/O Reliability

Input Buffer	Input Rise/Fall Time (min.)	Input Rise/Fall Time (max.)	Reliability		
LVTTL/LVCMOS (Schmitt trigger disabled)	No requirement	10 ns *	20 years (100°C)		
LVTTL/LVCMOS (Schmitt trigger enabled)	No requirement	No requirement, but input noise voltage cannot exceed Schmitt hysteresis.	20 years (100°C)		

Note: *The maximum input rise/fall time is related to the noise induced into the input buffer trace. If the noise is low, then the rise time and fall time of input buffers can be increased beyond the maximum value. The longer the rise/fall times, the more susceptible the input signal is to the board noise. Microsemi recommends signal integrity evaluation/characterization of the system to ensure that there is no excessive noise coupling into input signals.

Single-Ended I/O Characteristics

3.3 V LVTTL / 3.3 V LVCMOS

Low-Voltage Transistor–Transistor Logic (LVTTL) is a general purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer.

Table 2-34 • Minimum and Maximum DC Input and Output Levels

3.3 V LVTTL / 3.3 V LVCMOS	VIL		V	IH	VOL	VOH	IOL	ЮН	IOSL IOSH		IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μ Α ⁴	μ Α ⁴
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	25	27	10	10
4 mA	-0.3	8.0	2	3.6	0.4	2.4	4	4	25	27	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	51	54	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	51	54	10	10

Notes:

- 1. I_{IL} is the input leakage current per I/O pin over recommended operating conditions where –0.3 < VIN < VIL.
- 2. I_{IH} is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

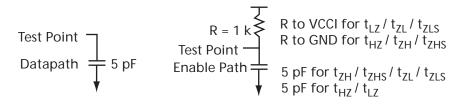


Figure 2-7 • AC Loading

Table 2-35 • 3.3 V LVTTL/LVCMOS AC Waveforms, Measuring Points, and Capacitive Loads

Input LOW (V)	Input HIGH (V)	Measuring Point* (V)	C _{LOAD} (pF)
0	3.3	1.4	5

Note: *Measuring point = Vtrip. See Table 2-23 on page 2-20 for a complete table of trip points.

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Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-36 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	3.52	0.19	0.86	1.16	0.66	3.59	3.42	1.75	1.90	ns
4 mA	STD	0.97	3.52	0.19	0.86	1.16	0.66	3.59	3.42	1.75	1.90	ns
6 mA	STD	0.97	2.90	0.19	0.86	1.16	0.66	2.96	2.83	1.98	2.29	ns
8 mA	STD	0.97	2.90	0.19	0.86	1.16	0.66	2.96	2.83	1.98	2.29	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-37 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	2.16	0.19	0.86	1.16	0.66	2.20	1.80	1.75	1.99	ns
4 mA	STD	0.97	2.16	0.19	0.86	1.16	0.66	2.20	1.80	1.75	1.99	ns
6 mA	STD	0.97	1.79	0.19	0.86	1.16	0.66	1.83	1.45	1.98	2.38	ns
8 mA	STD	0.97	1.79	0.19	0.86	1.16	0.66	1.83	1.45	1.98	2.38	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to 1.2 V DC Core Voltage

Table 2-38 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	4.09	0.26	0.97	1.36	1.10	4.16	3.91	2.19	2.64	ns
4 mA	STD	1.55	4.09	0.26	0.97	1.36	1.10	4.16	3.91	2.19	2.64	ns
6 mA	STD	1.55	3.45	0.26	0.97	1.36	1.10	3.51	3.32	2.43	3.03	ns
8 mA	STD	1.55	3.45	0.26	0.97	1.36	1.10	3.51	3.32	2.43	3.03	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-39 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 3.0 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	2.68	0.26	0.97	1.36	1.10	2.72	2.26	2.19	2.74	ns
4 mA	STD	1.55	2.68	0.26	0.97	1.36	1.10	2.72	2.26	2.19	2.74	ns
6 mA	STD	1.55	2.31	0.26	0.97	1.36	1.10	2.34	1.90	2.43	3.14	ns
8 mA	STD	1.55	2.31	0.26	0.97	1.36	1.10	2.34	1.90	2.43	3.14	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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3.3 V LVCMOS Wide Range

Table 2-40 • Minimum and Maximum DC Input and Output Levels for LVCMOS 3.3 V Wide Range

3.3 V LVCMOS Wide Range ¹	Software		ΊL	,	VIH	VOL	VOH	IOL	I _{OH}	IIL ²	IIH ³
Drive Strength	Default Drive Strength Option ⁴	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	μА	μА	μ Α ⁵	μ Α ⁵
100 μΑ	2 mA	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	100	100	10	10
100 μΑ	4 mA	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	100	100	10	10
100 μΑ	6 mA	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	100	100	10	10
100 μΑ	8 mA	-0.3	0.8	2	3.6	0.2	VCCI - 0.2	100	100	10	10

Notes:

- 1. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V Wide Range, as specified in the JEDEC JESD8-B specification.
- 2. I_{IL} is the input leakage current per I/O pin over recommended operating conditions where -0.3 < VIN < VIL.
- 3. I_{IH} is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 4. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 5. Currents are measured at 85°C junction temperature.
- 6. Software default selection is highlighted in gray.

Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-41 • 3.3 V LVCMOS Wide Range Low Slew – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	2 mA	STD	0.97	5.23	0.19	1.20	1.66	0.66	5.24	5.00	2.47	2.56	ns
100 μΑ	4 mA	STD	0.97	5.23	0.19	1.20	1.66	0.66	5.24	5.00	2.47	2.56	ns
100 μΑ	6 mA	STD	0.97	4.27	0.19	1.20	1.66	0.66	4.28	4.12	2.83	3.16	ns
100 μΑ	8 mA	STD	0.97	4.27	0.19	1.20	1.66	0.66	4.28	4.12	2.83	3.16	ns

Notes:

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-42 • 3.3 V LVCMOS Wide Range High Slew – Applies to 1.5 V DC Core Voltage
Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	2 mA	STD	0.97	3.11	0.19	1.20	1.66	0.66	3.13	2.55	2.47	2.70	ns
100 μΑ	4 mA	STD	0.97	3.11	0.19	1.20	1.66	0.66	3.13	2.55	2.47	2.70	ns
100 μΑ	6 mA	STD	0.97	2.56	0.19	1.20	1.66	0.66	2.57	2.02	2.82	3.31	ns
100 μΑ	8 mA	STD	0.97	2.56	0.19	1.20	1.66	0.66	2.57	2.02	2.82	3.31	ns

Notes:

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 3. Software default selection highlighted in gray.

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Applies to 1.2 V DC Core Voltage

Table 2-43 • 3.3 V LVCMOS Wide Range Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	2 mA	STD	1.55	6.01	0.26	1.31	1.91	1.10	6.01	5.66	3.02	3.49	ns
100 μΑ	4 mA	STD	1.55	6.01	0.26	1.31	1.91	1.10	6.01	5.66	3.02	3.49	ns
100 μΑ	6 mA	STD	1.55	5.02	0.26	1.31	1.91	1.10	5.02	4.76	3.38	4.10	ns
100 μΑ	8 mA	STD	1.55	5.02	0.26	1.31	1.91	1.10	5.02	4.76	3.38	4.10	ns

Notes:

Table 2-44 • 3.3 V LVCMOS Wide Range High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	2 mA	STD	1.55	3.82	0.26	1.31	1.91	1.10	3.82	3.15	3.01	3.65	ns
100 μΑ	4 mA	STD	1.55	3.82	0.26	1.31	1.91	1.10	3.82	3.15	3.01	3.65	ns
100 μΑ	6 mA	STD	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns
100 μΑ	8 mA	STD	1.55	3.25	0.26	1.31	1.91	1.10	3.25	2.61	3.38	4.27	ns

Notes:

- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 3. Software default selection highlighted in gray.

^{1.} The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

^{2.} For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

2.5 V LVCMOS

Low-Voltage CMOS for 2.5 V is an extension of the LVCMOS standard (JESD8-5) used for general purpose 2.5 V applications.

Table 2-45 • Minimum and Maximum DC Input and Output Levels

2.5 V LVCMOS	٧	TL.	V	IH	VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min., V	Max., V	Min., V	Max., V	Max., V	Min., V	mA	mA	Max., mA ³	Max., mA ³	μ Α ⁴	μ Α ⁴
2 mA	-0.3	0.7	1.7	3.6	0.7	1.7	2	2	16	18	10	10
4 mA	-0.3	0.7	1.7	3.6	0.7	1.7	4	4	16	18	10	10
6 mA	-0.3	0.7	1.7	3.6	0.7	1.7	6	6	32	37	10	10
8 mA	-0.3	0.7	1.7	3.6	0.7	1.7	8	8	32	37	10	10

Notes:

- 1. I_{IL} is the input leakage current per I/O pin over recommended operating conditions where -0.3 < VIN < VIL.
- 2. I_{IH} is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

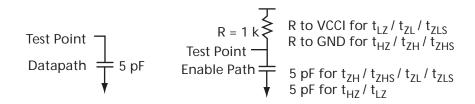


Figure 2-8 • AC Loading

Table 2-46 • 2.5 V LVCMOS AC Waveforms, Measuring Points, and Capacitive Loads

Input LOW (V)	Input HIGH (V)	Measuring Point* (V)	C _{LOAD} (pF)
0	2.5	1.2	5

Note: *Measuring point = Vtrip. See Table 2-23 on page 2-20 for a complete table of trip points.

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Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-47 • 2.5 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	4.13	0.19	1.10	1.24	0.66	4.01	4.13	1.73	1.74	ns
4 mA	STD	0.97	4.13	0.19	1.10	1.24	0.66	4.01	4.13	1.73	1.74	ns
8 mA	STD	0.97	3.39	0.19	1.10	1.24	0.66	3.31	3.39	1.98	2.19	ns
8 mA	STD	0.97	3.39	0.19	1.10	1.24	0.66	3.31	3.39	1.98	2.19	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-48 • 2.5 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	2.19	0.19	1.10	1.24	0.66	2.23	2.11	1.72	1.80	ns
4 mA	STD	0.97	2.19	0.19	1.10	1.24	0.66	2.23	2.11	1.72	1.80	ns
6 mA	STD	0.97	1.81	0.19	1.10	1.24	0.66	1.85	1.63	1.97	2.26	ns
8 mA	STD	0.97	1.81	0.19	1.10	1.24	0.66	1.85	1.63	1.97	2.26	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to 1.2 V DC Core Voltage

Table 2-49 • 2.5 LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	4.61	0.26	1.21	1.39	1.10	4.55	4.61	2.15	2.43	ns
4 mA	STD	1.55	4.61	0.26	1.21	1.39	1.10	4.55	4.61	2.15	2.43	ns
6 mA	STD	1.55	3.86	0.26	1.21	1.39	1.10	3.82	3.86	2.41	2.89	ns
8 mA	STD	1.55	3.86	0.26	1.21	1.39	1.10	3.82	3.86	2.41	2.89	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-50 • 2.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	2.68	0.26	1.21	1.39	1.10	2.72	2.54	2.15	2.51	ns
4 mA	STD	1.55	2.68	0.26	1.21	1.39	1.10	2.72	2.54	2.15	2.51	ns
6 mA	STD	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns
8 mA	STD	1.55	2.30	0.26	1.21	1.39	1.10	2.33	2.04	2.41	2.99	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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1.8 V LVCMOS

Low-voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

Table 2-51 • Minimum and Maximum DC Input and Output Levels

1.8 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL ¹	I _I H ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μ Α ⁴	μ Α ⁴
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	9	11	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4	17	22	10	10

Notes:

- 1. $I_{|L|}$ is the input leakage current per I/O pin over recommended operating conditions where -0.3 < VIN < VIL.
- 2. I_{IH} is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

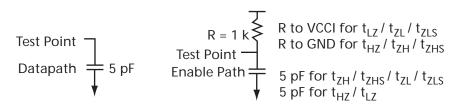


Figure 2-9 • AC Loading

Table 2-52 • 1.8 V LVCMOS AC Waveforms, Measuring Points, and Capacitive Loads

Input LOW (V)	Input HIGH (V)	Measuring Point* (V)	C _{LOAD} (pF)
0	1.8	0.9	5

Note: *Measuring point = Vtrip. See Table 2-23 on page 2-20 for a complete table of trip points.

Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-53 • 1.8 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t_{LZ}	t _{HZ}	Units
2 mA	STD	0.97	5.44	0.19	1.03	1.44	0.66	5.25	5.44	1.69	1.35	ns
4 mA	STD	0.97	4.44	0.19	1.03	1.44	0.66	4.37	4.44	1.99	2.11	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-54 • 1.8 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	2.64	0.19	1.03	1.44	0.66	2.59	2.64	1.69	1.40	ns
4 mA	STD	0.97	2.08	0.19	1.03	1.44	0.66	2.12	1.95	1.99	2.19	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to 1.2 V DC Core Voltage

Table 2-55 • 1.8 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	5.92	0.26	1.13	1.59	1.10	5.72	5.92	2.11	1.95	ns
4 mA	STD	1.55	4.91	0.26	1.13	1.59	1.10	4.82	4.91	2.42	2.73	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-56 • 1.8 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.7 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	3.05	0.26	1.13	1.59	1.10	3.01	3.05	2.10	2.00	ns
4 mA	STD	1.55	2.49	0.26	1.13	1.59	1.10	2.53	2.34	2.42	2.81	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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1.5 V LVCMOS (JESD8-11)

Low-Voltage CMOS for 1.5 V is an extension of the LVCMOS standard (JESD8-5) used for general purpose 1.5 V applications. It uses a 1.5 V input buffer and a push-pull output buffer.

Table 2-57 • Minimum and Maximum DC Input and Output Levels

1.5 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μ Α ⁴	μ Α ⁴
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2	13	16	10	10

Notes:

- 1. I_{IL} is the input leakage current per I/O pin over recommended operating conditions where –0.3 < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

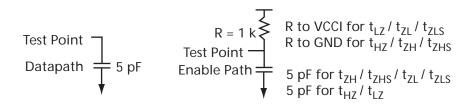


Figure 2-10 • AC Loading

Table 2-58 • 1.5 V LVCMOS AC Waveforms, Measuring Points, and Capacitive Loads

Input LOW (V)	Input HIGH (V)	Measuring Point* (V)	C _{LOAD} (pF)
0	1.5	0.75	5

Note: *Measuring point = Vtrip. See Table 2-23 on page 2-20 for a complete table of trip points.

Timing Characteristics

Applies to 1.5 V DC Core Voltage

Table 2-59 • 1.5 V LVCMOS Low Slew – Applies to 1.5 V DC Core Voltage Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	5.39	0.19	1.19	1.62	0.66	5.48	5.39	2.02	2.06	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-60 • 1.5 V LVCMOS High Slew – Applies to 1.5 V DC Core Voltage

Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	0.97	2.39	0.19	1.19	1.62	0.66	2.44	2.24	2.02	2.15	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Applies to 1.2 V DC Core Voltage

Table 2-61 • 1.5 V LVCMOS Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_{.J} = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	5.87	0.26	1.27	1.77	1.10	5.92	5.87	2.45	2.65	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-62 • 1.5 V LVCMOS High Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.4 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
2 mA	STD	1.55	2.78	0.26	1.27	1.77	1.10	2.82	2.62	2.44	2.74	ns

Notes:

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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1.2 V LVCMOS (JESD8-12A)

Low-Voltage CMOS for 1.2 V complies with the LVCMOS standard JESD8-12A for general purpose 1.2 V applications. It uses a 1.2 V input buffer and a push-pull output buffer.

Table 2-63 • Minimum and Maximum DC Input and Output Levels

1.2 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μ Α ⁴	μ Α ⁴
1 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	1	1	10	13	10	10

Notes:

- 1. I_{IL} is the input leakage current per I/O pin over recommended operating conditions where –0.3 < VIN < VIL.
- 2. I_{IH} is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

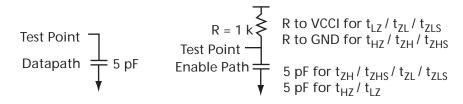


Figure 2-11 • AC Loading

Table 2-64 • 1.2 V LVCMOS AC Waveforms, Measuring Points, and Capacitive Loads

Input LOW (V)	Input HIGH (V)	Measuring Point* (V)	C _{LOAD} (pF)
0	1.2	0.6	5

Note: *Measuring point = Vtrip. See Table 2-23 on page 2-20 for a complete table of trip points.

Timing Characteristics

Applies to 1.2 V DC Core Voltage

Table 2-65 • 1.2 V LVCMOS Low Slew

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.14 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
1 mA	STD	1.55	8.30	0.26	1.56	2.27	1.10	7.97	7.54	2.56	2.55	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-66 • 1.2 V LVCMOS High Slew

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.14 V

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
1 mA	STD	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V LVCMOS Wide Range

Table 2-67 • Minimum and Maximum DC Input and Output Levels

1.2 V LVCMOS Wide Range		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	μ Α ⁴	μ Α ⁴
1 mA	-0.3	0.3 * VCCI	0.7 * VCCI	3.6	0.1	VCCI - 0.1	100	100	10	13	10	10

Notes:

- 1. $I_{|L|}$ is the input leakage current per I/O pin over recommended operating conditions where -0.3 < VIN < VIL.
- 2. I_{IH} is the input leakage current per I/O pin over recommended operating conditions where VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Applicable to IGLOO nano V2 devices operating at VCCI ≥ VCC.
- 6. Software default selection highlighted in gray.

Timing Characteristics

Applies to 1.2 V DC Core Voltage

Table 2-68 • 1.2 V LVCMOS Wide Range Low Slew – Applies to 1.2 V DC Core Voltage

Commercial-Case Conditions: T_{.I} = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.14 V

Drive	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	1 mA	STD	1.55	8.30	0.26	1.56	2.27	1.10	7.97	7.54	2.56	2.55	ns

Notes:

- The minimum drive strength for any LVCMOS 1.2 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-69 • 1.2 V LVCMOS Wide Range HIgh Slew – Applies to 1.2 V DC Core Voltage Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V, Worst-Case VCCI = 1.14 V

Drive	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{PYS}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	Units
100 μΑ	1 mA	STD	1.55	3.50	0.26	1.56	2.27	1.10	3.37	3.10	2.55	2.66	ns

Notes:

- 1. The minimum drive strength for any LVCMOS 1.2 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 3. Software default selection highlighted in gray.

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I/O Register Specifications

Fully Registered I/O Buffers with Asynchronous Preset

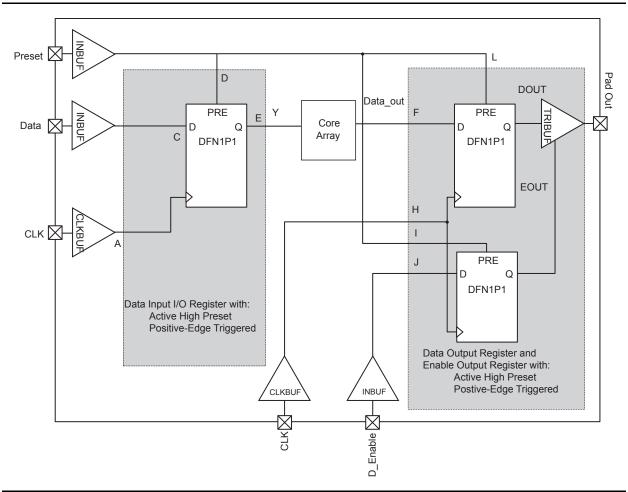


Figure 2-12 • Timing Model of Registered I/O Buffers with Asynchronous Preset

Table 2-70 • Parameter Definition and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t _{OCLKQ}	Clock-to-Q of the Output Data Register	H, DOUT
tosup	Data Setup Time for the Output Data Register	F, H
t _{OHD}	Data Hold Time for the Output Data Register	F, H
t _{OPRE2Q}	Asynchronous Preset-to-Q of the Output Data Register	L, DOUT
t _{OREMPRE}	Asynchronous Preset Removal Time for the Output Data Register	L, H
t _{ORECPRE}	Asynchronous Preset Recovery Time for the Output Data Register	L, H
t _{OECLKQ}	Clock-to-Q of the Output Enable Register	H, EOUT
t _{OESUD}	Data Setup Time for the Output Enable Register	J, H
t _{OEHD}	Data Hold Time for the Output Enable Register	J, H
t _{OEPRE2Q}	Asynchronous Preset-to-Q of the Output Enable Register	I, EOUT
t _{OEREMPRE}	Asynchronous Preset Removal Time for the Output Enable Register	I, H
t _{OERECPRE}	Asynchronous Preset Recovery Time for the Output Enable Register	I, H
t _{ICLKQ}	Clock-to-Q of the Input Data Register	A, E
t _{ISUD}	Data Setup Time for the Input Data Register	C, A
t _{IHD}	Data Hold Time for the Input Data Register	C, A
t _{IPRE2Q}	Asynchronous Preset-to-Q of the Input Data Register	D, E
t _{IREMPRE}	Asynchronous Preset Removal Time for the Input Data Register	D, A
t _{IRECPRE}	Asynchronous Preset Recovery Time for the Input Data Register	D, A

Note: *See Figure 2-12 on page 2-41 for more information.

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Fully Registered I/O Buffers with Asynchronous Clear

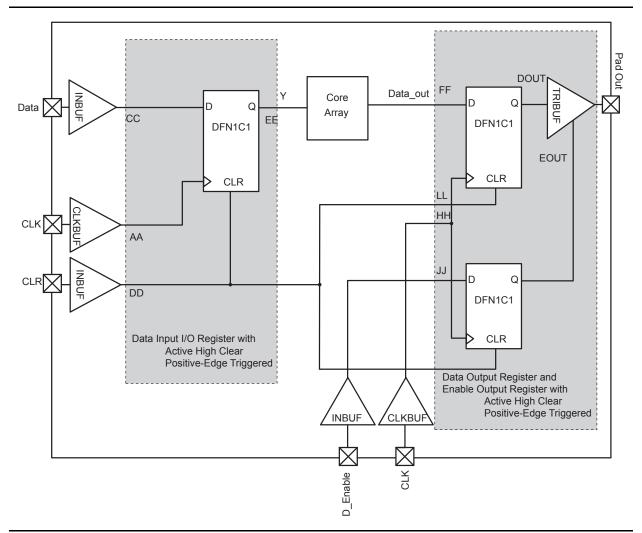


Figure 2-13 • Timing Model of the Registered I/O Buffers with Asynchronous Clear

Table 2-71 • Parameter Definition and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t _{OCLKQ}	Clock-to-Q of the Output Data Register	HH, DOUT
tosud	Data Setup Time for the Output Data Register	FF, HH
t _{OHD}	Data Hold Time for the Output Data Register	FF, HH
t _{OCLR2Q}	Asynchronous Clear-to-Q of the Output Data Register	LL, DOUT
t _{OREMCLR}	Asynchronous Clear Removal Time for the Output Data Register	LL, HH
t _{ORECCLR}	Asynchronous Clear Recovery Time for the Output Data Register	LL, HH
t _{OECLKQ}	Clock-to-Q of the Output Enable Register	HH, EOUT
t _{OESUD}	Data Setup Time for the Output Enable Register	JJ, HH
t _{OEHD}	Data Hold Time for the Output Enable Register	JJ, HH
t _{OECLR2Q}	Asynchronous Clear-to-Q of the Output Enable Register	II, EOUT
t _{OEREMCLR}	Asynchronous Clear Removal Time for the Output Enable Register	II, HH
toerecclr	Asynchronous Clear Recovery Time for the Output Enable Register	II, HH
t _{ICLKQ}	Clock-to-Q of the Input Data Register	AA, EE
t _{ISUD}	Data Setup Time for the Input Data Register	CC, AA
t _{IHD}	Data Hold Time for the Input Data Register	CC, AA
t _{ICLR2Q}	Asynchronous Clear-to-Q of the Input Data Register	DD, EE
t _{IREMCLR}	Asynchronous Clear Removal Time for the Input Data Register	DD, AA
t _{IRECCLR}	Asynchronous Clear Recovery Time for the Input Data Register	DD, AA

Note: *See Figure 2-13 on page 2-43 for more information.

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Input Register

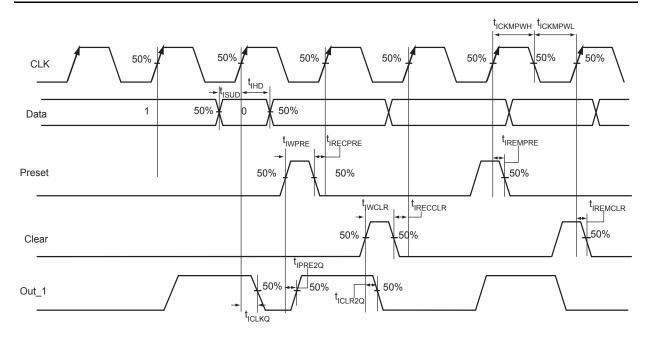


Figure 2-14 • Input Register Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-72 • Input Data Register Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{ICLKQ}	Clock-to-Q of the Input Data Register	0.42	ns
t _{ISUD}	Data Setup Time for the Input Data Register	0.47	ns
t _{IHD}	Data Hold Time for the Input Data Register	0.00	ns
t _{ICLR2Q}	Asynchronous Clear-to-Q of the Input Data Register	0.79	ns
t _{IPRE2Q}	Asynchronous Preset-to-Q of the Input Data Register	0.79	ns
t _{IREMCLR}	Asynchronous Clear Removal Time for the Input Data Register	0.00	ns
t _{IRECCLR}	Asynchronous Clear Recovery Time for the Input Data Register	0.24	ns
t _{IREMPRE}	Asynchronous Preset Removal Time for the Input Data Register	0.00	ns
t _{IRECPRE}	Asynchronous Preset Recovery Time for the Input Data Register	0.24	ns
t _{IWCLR}	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.19	ns
t _{IWPRE}	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.19	ns
t _{ICKMPWH}	Clock Minimum Pulse Width HIGH for the Input Data Register	0.31	ns
t _{ICKMPWL}	Clock Minimum Pulse Width LOW for the Input Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-73 • Input Data Register Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{ICLKQ}	Clock-to-Q of the Input Data Register	0.68	ns
t _{ISUD}	Data Setup Time for the Input Data Register	0.97	ns
t _{IHD}	Data Hold Time for the Input Data Register	0.00	ns
t _{ICLR2Q}	Asynchronous Clear-to-Q of the Input Data Register	1.19	ns
t _{IPRE2Q}	Asynchronous Preset-to-Q of the Input Data Register	1.19	ns
t _{IREMCLR}	Asynchronous Clear Removal Time for the Input Data Register	0.00	ns
t _{IRECCLR}	Asynchronous Clear Recovery Time for the Input Data Register	0.24	ns
t _{IREMPRE}	Asynchronous Preset Removal Time for the Input Data Register	0.00	ns
t _{IRECPRE}	Asynchronous Preset Recovery Time for the Input Data Register	0.24	ns
t _{IWCLR}	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.19	ns
t _{IWPRE}	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.19	ns
t _{ICKMPWH}	Clock Minimum Pulse Width HIGH for the Input Data Register	0.31	ns
t _{ICKMPWL}	Clock Minimum Pulse Width LOW for the Input Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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Output Register

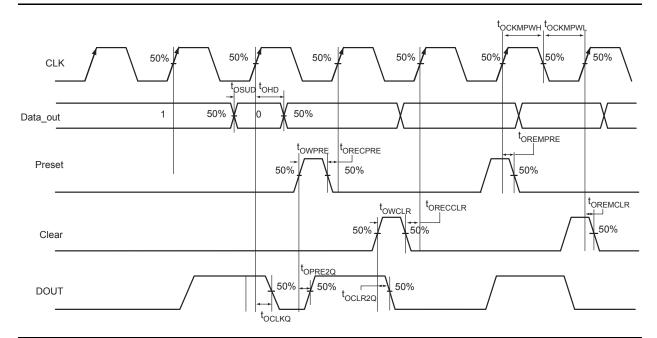


Figure 2-15 • Output Register Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-74 • Output Data Register Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{OCLKQ}	Clock-to-Q of the Output Data Register	1.00	ns
tosup	Data Setup Time for the Output Data Register	0.51	ns
t _{OHD}	Data Hold Time for the Output Data Register	0.00	ns
t _{OCLR2Q}	Asynchronous Clear-to-Q of the Output Data Register	1.34	ns
t _{OPRE2Q}	Asynchronous Preset-to-Q of the Output Data Register	1.34	ns
t _{OREMCLR}	Asynchronous Clear Removal Time for the Output Data Register	0.00	ns
t _{ORECCLR}	Asynchronous Clear Recovery Time for the Output Data Register	0.24	ns
t _{OREMPRE}	Asynchronous Preset Removal Time for the Output Data Register	0.00	ns
t _{ORECPRE}	Asynchronous Preset Recovery Time for the Output Data Register	0.24	ns
t _{OWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.19	ns
t _{OWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.19	ns
t _{OCKMPWH}	Clock Minimum Pulse Width HIGH for the Output Data Register	0.31	ns
t _{OCKMPWL}	Clock Minimum Pulse Width LOW for the Output Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-75 • Output Data Register Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{OCLKQ}	Clock-to-Q of the Output Data Register	1.52	ns
tosup	Data Setup Time for the Output Data Register	1.15	ns
t _{OHD}	Data Hold Time for the Output Data Register	0.00	ns
t _{OCLR2Q}	Asynchronous Clear-to-Q of the Output Data Register	1.96	ns
t _{OPRE2Q}	Asynchronous Preset-to-Q of the Output Data Register	1.96	ns
t _{OREMCLR}	Asynchronous Clear Removal Time for the Output Data Register	0.00	ns
t _{ORECCLR}	Asynchronous Clear Recovery Time for the Output Data Register	0.24	ns
t _{OREMPRE}	Asynchronous Preset Removal Time for the Output Data Register	0.00	ns
t _{ORECPRE}	Asynchronous Preset Recovery Time for the Output Data Register	0.24	ns
towclr	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.19	ns
t _{OWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.19	ns
tockmpwh	Clock Minimum Pulse Width HIGH for the Output Data Register	0.31	ns
t _{OCKMPWL}	Clock Minimum Pulse Width LOW for the Output Data Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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Output Enable Register

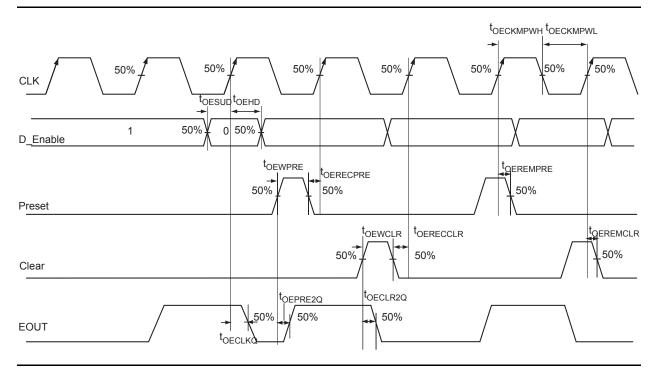


Figure 2-16 • Output Enable Register Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-76 • Output Enable Register Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{OECLKQ}	Clock-to-Q of the Output Enable Register	0.75	ns
t _{OESUD}	Data Setup Time for the Output Enable Register	0.51	ns
t _{OEHD}	Data Hold Time for the Output Enable Register	0.00	ns
t _{OECLR2Q}	Asynchronous Clear-to-Q of the Output Enable Register	1.13	ns
t _{OEPRE2Q}	Asynchronous Preset-to-Q of the Output Enable Register	1.13	ns
t _{OEREMCLR}	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
t _{OERECCLR}	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
t _{OEREMPRE}	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
t _{OERECPRE}	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
t _{OEWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
t _{OEWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
t _{OECKMPWH}	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
t _{OECKMPWL}	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-77 • Output Enable Register Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{OECLKQ}	Clock-to-Q of the Output Enable Register	1.10	ns
t _{OESUD}	Data Setup Time for the Output Enable Register	1.15	ns
t _{OEHD}	Data Hold Time for the Output Enable Register	0.00	ns
t _{OECLR2Q}	Asynchronous Clear-to-Q of the Output Enable Register	1.65	ns
t _{OEPRE2Q}	Asynchronous Preset-to-Q of the Output Enable Register	1.65	ns
t _{OEREMCLR}	Asynchronous Clear Removal Time for the Output Enable Register	0.00	ns
t _{OERECCLR}	Asynchronous Clear Recovery Time for the Output Enable Register	0.24	ns
t _{OEREMPRE}	Asynchronous Preset Removal Time for the Output Enable Register	0.00	ns
t _{OERECPRE}	Asynchronous Preset Recovery Time for the Output Enable Register	0.24	ns
t _{OEWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.19	ns
t _{OEWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.19	ns
t _{OECKMPWH}	Clock Minimum Pulse Width HIGH for the Output Enable Register	0.31	ns
t _{OECKMPWL}	Clock Minimum Pulse Width LOW for the Output Enable Register	0.28	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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DDR Module Specifications

Note: DDR is not supported for AGLN010, AGLN015, and AGLN020 devices.

Input DDR Module

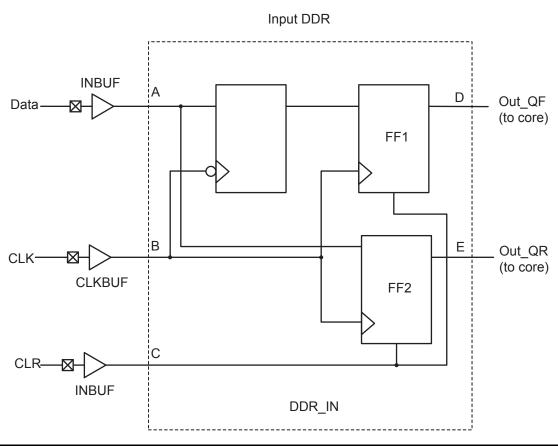


Figure 2-17 • Input DDR Timing Model

Table 2-78 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
t _{DDRICLKQ1}	Clock-to-Out Out_QR	B, D
t _{DDRICLKQ2}	Clock-to-Out Out_QF	B, E
t _{DDRISUD}	Data Setup Time of DDR input	A, B
t _{DDRIHD}	Data Hold Time of DDR input	A, B
t _{DDRICLR2Q1}	Clear-to-Out Out_QR	C, D
t _{DDRICLR2Q2}	Clear-to-Out Out_QF	C, E
t _{DDRIREMCLR}	Clear Removal	C, B
t _{DDRIRECCLR}	Clear Recovery	C, B

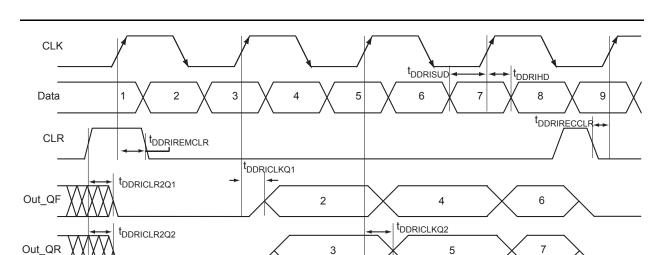


Figure 2-18 • Input DDR Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-79 • Input DDR Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.25 V

Parameter	Description	Std.	Units
t _{DDRICLKQ1}	Clock-to-Out Out_QR for Input DDR	0.48	ns
t _{DDRICLKQ2}	Clock-to-Out Out_QF for Input DDR	0.65	ns
t _{DDRISUD1}	Data Setup for Input DDR (negedge)	0.50	ns
t _{DDRISUD2}	Data Setup for Input DDR (posedge)	0.40	ns
t _{DDRIHD1}	Data Hold for Input DDR (negedge)	0.00	ns
t _{DDRIHD2}	Data Hold for Input DDR (posedge)	0.00	ns
t _{DDRICLR2Q1}	Asynchronous Clear-to-Out Out_QR for Input DDR	0.82	ns
t _{DDRICLR2Q2}	Asynchronous Clear-to-Out Out_QF for Input DDR	0.98	ns
t _{DDRIREMCLR}	Asynchronous Clear Removal Time for Input DDR	0.00	ns
t _{DDRIRECCLR}	Asynchronous Clear Recovery Time for Input DDR	0.23	ns
t _{DDRIWCLR}	Asynchronous Clear Minimum Pulse Width for Input DDR	0.19	ns
t _{DDRICKMPWH}	Clock Minimum Pulse Width HIGH for Input DDR	0.31	ns
t _{DDRICKMPWL}	Clock Minimum Pulse Width LOW for Input DDR	0.28	ns
F _{DDRIMAX}	Maximum Frequency for Input DDR	250.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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1.2 V DC Core Voltage

Table 2-80 • Input DDR Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{DDRICLKQ1}	Clock-to-Out Out_QR for Input DDR	0.76	ns
t _{DDRICLKQ2}	Clock-to-Out Out_QF for Input DDR	0.94	ns
t _{DDRISUD1}	Data Setup for Input DDR (negedge)	0.93	ns
t _{DDRISUD2}	Data Setup for Input DDR (posedge)	0.84	ns
t _{DDRIHD1}	Data Hold for Input DDR (negedge)	0.00	ns
t _{DDRIHD2}	Data Hold for Input DDR (posedge)	0.00	ns
t _{DDRICLR2Q1}	Asynchronous Clear-to-Out Out_QR for Input DDR	1.23	ns
t _{DDRICLR2Q2}	Asynchronous Clear-to-Out Out_QF for Input DDR	1.42	ns
t _{DDRIREMCLR}	Asynchronous Clear Removal Time for Input DDR	0.00	ns
t _{DDRIRECCLR}	Asynchronous Clear Recovery Time for Input DDR	0.24	ns
t _{DDRIWCLR}	Asynchronous Clear Minimum Pulse Width for Input DDR	0.19	ns
t _{DDRICKMPWH}	Clock Minimum Pulse Width HIGH for Input DDR	0.31	ns
t _{DDRICKMPWL}	Clock Minimum Pulse Width LOW for Input DDR	0.28	ns
F _{DDRIMAX}	Maximum Frequency for Input DDR	160.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Output DDR Module

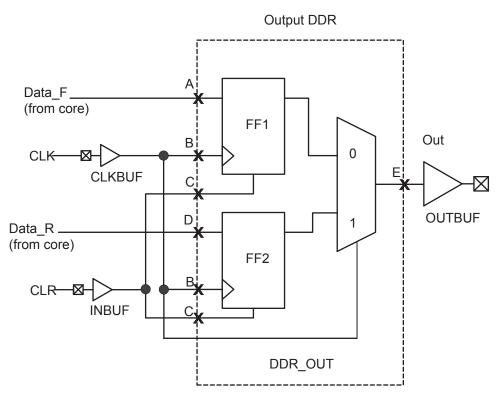


Figure 2-19 • Output DDR Timing Model

Table 2-81 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
t _{DDROCLKQ}	Clock-to-Out	B, E
t _{DDROCLR2Q}	Asynchronous Clear-to-Out	C, E
t _{DDROREMCLR}	Clear Removal	C, B
t _{DDRORECCLR}	Clear Recovery	C, B
t _{DDROSUD1}	Data Setup Data_F	A, B
t _{DDROSUD2}	Data Setup Data_R	D, B
t _{DDROHD1}	Data Hold Data_F	A, B
t _{DDROHD2}	Data Hold Data_R	D, B

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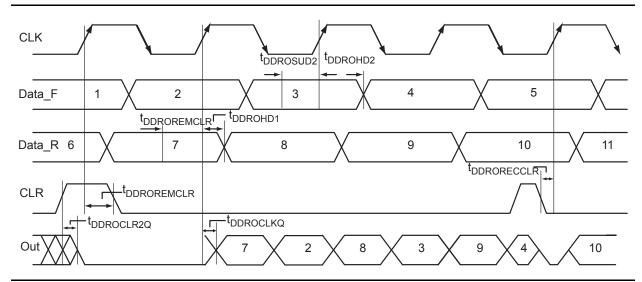


Figure 2-20 • Output DDR Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-82 • Output DDR Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{DDROCLKQ}	Clock-to-Out of DDR for Output DDR	1.07	ns
t _{DDROSUD1}	Data_F Data Setup for Output DDR	0.67	ns
t _{DDROSUD2}	Data_R Data Setup for Output DDR	0.67	ns
t _{DDROHD1}	Data_F Data Hold for Output DDR	0.00	ns
t _{DDROHD2}	Data_R Data Hold for Output DDR	0.00	ns
t _{DDROCLR2Q}	Asynchronous Clear-to-Out for Output DDR	1.38	ns
t _{DDROREMCLR}	Asynchronous Clear Removal Time for Output DDR	0.00	ns
t _{DDRORECCLR}	Asynchronous Clear Recovery Time for Output DDR	0.23	ns
t _{DDROWCLR1}	Asynchronous Clear Minimum Pulse Width for Output DDR	0.19	ns
t _{DDROCKMPWH}	Clock Minimum Pulse Width HIGH for the Output DDR	0.31	ns
t _{DDROCKMPWL}	Clock Minimum Pulse Width LOW for the Output DDR	0.28	ns
F _{DDOMAX}	Maximum Frequency for the Output DDR	250.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-83 • Output DDR Propagation Delays Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{DDROCLKQ}	Clock-to-Out of DDR for Output DDR	1.60	ns
t _{DDROSUD1}	Data_F Data Setup for Output DDR	1.09	ns
t _{DDROSUD2}	Data_R Data Setup for Output DDR	1.16	ns
t _{DDROHD1}	Data_F Data Hold for Output DDR	0.00	ns
t _{DDROHD2}	Data_R Data Hold for Output DDR	0.00	ns
t _{DDROCLR2Q}	Asynchronous Clear-to-Out for Output DDR	1.99	ns
t _{DDROREMCLR}	Asynchronous Clear Removal Time for Output DDR	0.00	ns
t _{DDRORECCLR}	Asynchronous Clear Recovery Time for Output DDR	0.24	ns
t _{DDROWCLR1}	Asynchronous Clear Minimum Pulse Width for Output DDR	0.19	ns
t _{DDROCKMPWH}	Clock Minimum Pulse Width HIGH for the Output DDR	0.31	ns
t _{DDROCKMPWL}	Clock Minimum Pulse Width LOW for the Output DDR	0.28	ns
F _{DDOMAX}	Maximum Frequency for the Output DDR	160.00	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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VersaTile Characteristics

VersaTile Specifications as a Combinatorial Module

The IGLOO nano library offers all combinations of LUT-3 combinatorial functions. In this section, timing characteristics are presented for a sample of the library. For more details, refer to the *Fusion, IGLOO/e, and ProASIC3/ E Macro Library Guide*.

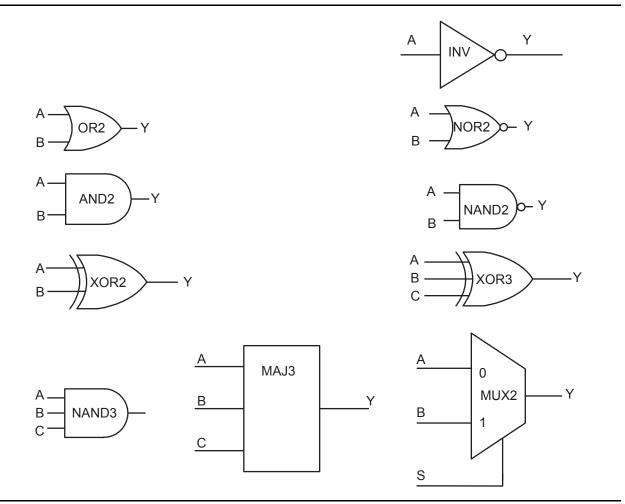


Figure 2-21 • Sample of Combinatorial Cells



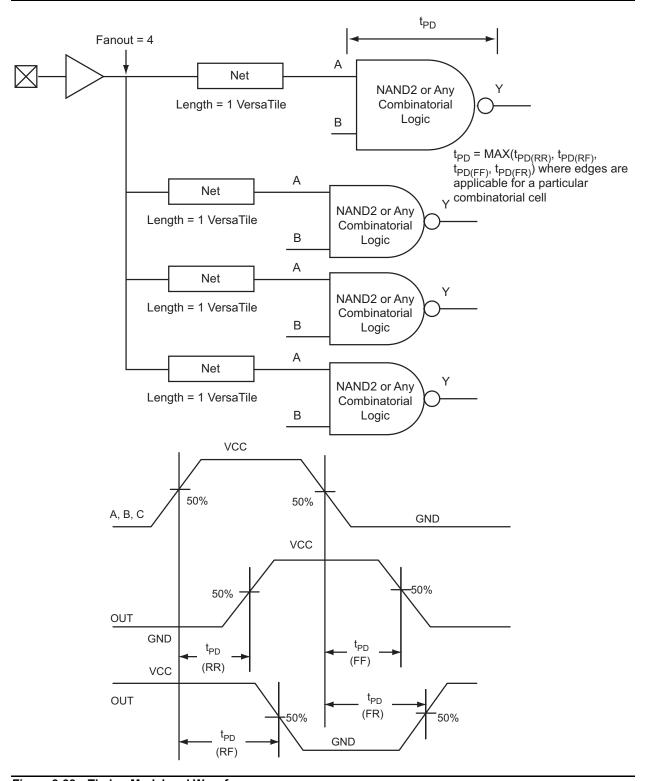


Figure 2-22 • Timing Model and Waveforms

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Timing Characteristics

1.5 V DC Core Voltage

Table 2-84 • Combinatorial Cell Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Combinatorial Cell	Equation	Parameter	Std.	Units
INV	Y = !A	t _{PD}	0.76	ns
AND2	Y = A · B	t _{PD}	0.87	ns
NAND2	Y = !(A · B)	t _{PD}	0.91	ns
OR2	Y = A + B	t _{PD}	0.90	ns
NOR2	Y = !(A + B)	t _{PD}	0.94	ns
XOR2	Y = A ⊕ B	t _{PD}	1.39	ns
MAJ3	Y = MAJ(A, B, C)	t _{PD}	1.44	ns
XOR3	$Y = A \oplus B \oplus C$	t _{PD}	1.60	ns
MUX2	Y = A !S + B S	t _{PD}	1.17	ns
AND3	$Y = A \cdot B \cdot C$	t _{PD}	1.18	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-85 • Combinatorial Cell Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Combinatorial Cell	Equation	Parameter	Std.	Units
INV	Y = !A	t _{PD}	1.33	ns
AND2	Y = A · B	t _{PD}	1.48	ns
NAND2	Y = !(A · B)	t _{PD}	1.58	ns
OR2	Y = A + B	t _{PD}	1.53	ns
NOR2	Y = !(A + B)	t _{PD}	1.63	ns
XOR2	Y = A ⊕ B	t _{PD}	2.34	ns
MAJ3	Y = MAJ(A, B, C)	t _{PD}	2.59	ns
XOR3	Y = A ⊕ B ⊕ C	t _{PD}	2.74	ns
MUX2	Y = A !S + B S	t _{PD}	2.03	ns
AND3	$Y = A \cdot B \cdot C$	t _{PD}	2.11	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

VersaTile Specifications as a Sequential Module

The IGLOO nano library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library. For more details, refer to the *Fusion, IGLOO/e, and ProASIC3/E Macro Library Guide*.

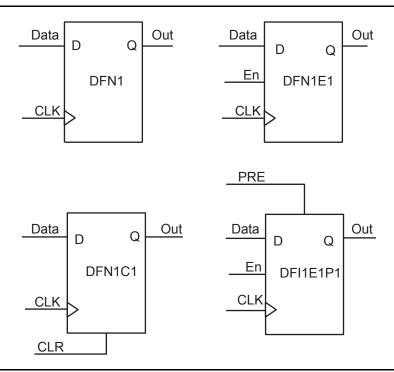


Figure 2-23 • Sample of Sequential Cells

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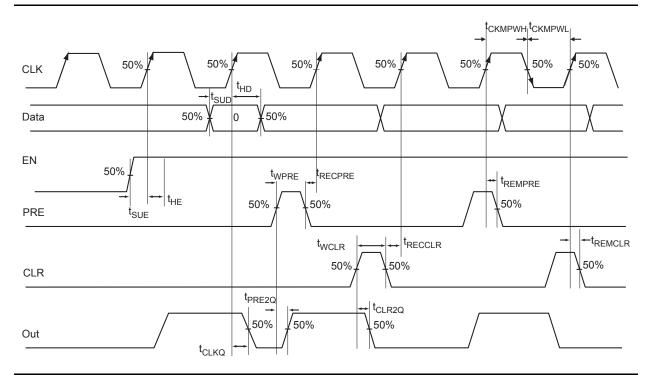


Figure 2-24 • Timing Model and Waveforms

Timing Characteristics

1.5 V DC Core Voltage

Table 2-86 • Register Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{CLKQ}	Clock-to-Q of the Core Register	0.89	ns
t _{SUD}	Data Setup Time for the Core Register	0.81	ns
t _{HD}	Data Hold Time for the Core Register	0.00	ns
t _{SUE}	Enable Setup Time for the Core Register	0.73	ns
t _{HE}	Enable Hold Time for the Core Register	0.00	ns
t _{CLR2Q}	Asynchronous Clear-to-Q of the Core Register	0.60	ns
t _{PRE2Q}	Asynchronous Preset-to-Q of the Core Register	0.62	ns
t _{REMCLR}	Asynchronous Clear Removal Time for the Core Register	0.00	ns
t _{RECCLR}	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
t _{REMPRE}	Asynchronous Preset Removal Time for the Core Register	0.00	ns
t _{RECPRE}	Asynchronous Preset Recovery Time for the Core Register	0.23	ns
t _{WCLR}	Asynchronous Clear Minimum Pulse Width for the Core Register	0.30	ns
t _{WPRE}	Asynchronous Preset Minimum Pulse Width for the Core Register	0.30	ns
t _{CKMPWH}	Clock Minimum Pulse Width HIGH for the Core Register	0.56	ns
t _{CKMPWL}	Clock Minimum Pulse Width LOW for the Core Register	0.56	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-87 • Register Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{CLKQ}	Clock-to-Q of the Core Register	1.61	ns
t _{SUD}	Data Setup Time for the Core Register	1.17	ns
t_{HD}	Data Hold Time for the Core Register	0.00	ns
t _{SUE}	Enable Setup Time for the Core Register	1.29	ns
t _{HE}	Enable Hold Time for the Core Register	0.00	ns
t _{CLR2Q}	Asynchronous Clear-to-Q of the Core Register	0.87	ns
t _{PRE2Q}	Asynchronous Preset-to-Q of the Core Register	0.89	ns
t _{REMCLR}	Asynchronous Clear Removal Time for the Core Register	0.00	ns
t _{RECCLR}	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
t _{REMPRE}	Asynchronous Preset Removal Time for the Core Register	0.00	ns
t _{RECPRE}	Asynchronous Preset Recovery Time for the Core Register	0.24	ns
t _{WCLR}	Asynchronous Clear Minimum Pulse Width for the Core Register	0.46	ns
t _{WPRE}	Asynchronous Preset Minimum Pulse Width for the Core Register	0.46	ns
t _{CKMPWH}	Clock Minimum Pulse Width HIGH for the Core Register	0.95	ns
t _{CKMPWL}	Clock Minimum Pulse Width LOW for the Core Register	0.95	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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Global Resource Characteristics

AGLN125 Clock Tree Topology

Clock delays are device-specific. Figure 2-25 is an example of a global tree used for clock routing. The global tree presented in Figure 2-25 is driven by a CCC located on the west side of the AGLN125 device. It is used to drive all D-flip-flops in the device.

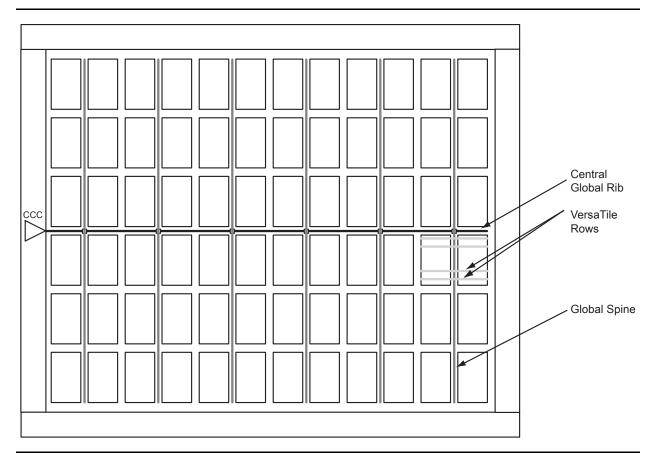


Figure 2-25 • Example of Global Tree Use in an AGLN125 Device for Clock Routing

Global Tree Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard–dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-70. Table 2-88 to Table 2-96 on page 2-68 present minimum and maximum global clock delays within each device. Minimum and maximum delays are measured with minimum and maximum loading.

Timing Characteristics

1.5 V DC Core Voltage

Table 2-88 • AGLN010 Global Resource

Commercial-Case Conditions: T_{.I} = 70°C, VCC = 1.425 V

		S	Std.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.13	1.42	ns
t _{RCKH}	Input High Delay for Global Clock	1.15	1.50	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.35	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-89 • AGLN015 Global Resource Commercial-Case Conditions: T_{.I} = 70°C, VCC = 1.425 V

		S	Std.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.21	1.55	ns
t _{RCKH}	Input High Delay for Global Clock	1.23	1.65	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.42	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Table 2-90 • AGLN020 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V

		Std.		
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.21	1.55	ns
t _{RCKH}	Input High Delay for Global Clock	1.23	1.65	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.42	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-91 • AGLN060 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V

			Std.	
Parameter	Description	Min	¹ Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.3	2 1.62	ns
t _{RCKH}	Input High Delay for Global Clock	1.3	1.71	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.4)	ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.6	5	ns
t _{RCKSW}	Maximum Skew for Global Clock		0.38	ns

Notes:

- Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-92 • AGLN125 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V

			Std.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.36	1.71	ns
t _{RCKH}	Input High Delay for Global Clock	1.39	1.82	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.43	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-93 • AGLN250 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.425 V

		Std.			
Parameter	Description	Min. ¹	Max. ²	Units	
t _{RCKL}	Input Low Delay for Global Clock	1.39	1.73	ns	
t _{RCKH}	Input High Delay for Global Clock	1.41	1.84	ns	
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns	
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns	
t _{RCKSW}	Maximum Skew for Global Clock		0.43	ns	

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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1.2 V DC Core Voltage

Table 2-94 • AGLN010 Global Resource

Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

			Std.		
Parameter	Description	•	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock		1.71	2.09	ns
t _{RCKH}	Input High Delay for Global Clock		1.78	2.31	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock		1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock		1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock			0.53	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Table 2-95 • AGLN015 Global Resource
Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

		Std.		
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.81	2.26	ns
t _{RCKH}	Input High Delay for Global Clock	1.90	2.51	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.61	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Table 2-96 • AGLN020 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

		s	Std.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	1.81	2.26	ns
t _{RCKH}	Input High Delay for Global Clock	1.90	2.51	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.61	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Table 2-97 • AGLN060 Global Resource
Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

			Std.		
Parameter	Description	N	/lin. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	2	2.02	2.42	ns
t _{RCKH}	Input High Delay for Global Clock	2	2.09	2.65	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock			0.56	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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Table 2-98 • AGLN125 Global Resource Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

		s	td.	
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	2.08	2.54	ns
t _{RCKH}	Input High Delay for Global Clock	2.15	2.77	ns
t _{RCKMPWH}	Minimum Pulse Width HIGH for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width LOW for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.62	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Table 2-99 • AGLN250 Global Resource
Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

		Std.		
Parameter	Description	Min. ¹	Max. ²	Units
t _{RCKL}	Input Low Delay for Global Clock	2.11	2.57	ns
t _{RCKH}	Input High Delay for Global Clock	2.19	2.81	ns
t _{RCKMPWH}	Minimum Pulse Width High for Global Clock	1.40		ns
t _{RCKMPWL}	Minimum Pulse Width Low for Global Clock	1.65		ns
t _{RCKSW}	Maximum Skew for Global Clock		0.62	ns

Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

Clock Conditioning Circuits

CCC Electrical Specifications

Timing Characteristics

Table 2-100 • IGLOO nano CCC/PLL Specification For IGLOO nano V2 OR V5 Devices, 1.5 V DC Core Supply Voltage

Parameter		Min.	Тур.	Max.	Units
Clock Conditioning Circuitry Input Frequency f _{IN_CCC}		1.5		250	MHz
Clock Conditioning Circuitry Output Frequency f _{OUT_CC}	C	0.75		250	MHz
Delay Increments in Programmable Delay Blocks ^{1, 2}			360 ³		ps
Number of Programmable Values in Each Programmab	le Delay Block			32	
Serial Clock (SCLK) for Dynamic PLL ^{4,9}				100	MHz
put Cycle-to-Cycle Jitter (peak magnitude)				1	ns
Acquisition Time					
	LockControl = 0			300	μs
	LockControl = 1			6.0	ms
Tracking Jitter ⁵					
	LockControl = 0			2.5	ns
	LockControl = 1			1.5	ns
Output Duty Cycle		48.5		51.5	%
Delay Range in Block: Programmable Delay 1 1, 2		1.25		15.65	ns
Delay Range in Block: Programmable Delay 2 1, 2,		0.025		15.65	ns
Delay Range in Block: Fixed Delay ^{1, 2}			3.5		ns
VCO Output Peak-to-Peak Period Jitter F _{CCC_OUT} ⁶	Max Peak-to-Pea	k Jitter Da	ta ^{6,7,8}		
	SSO ≤ 2	SSO ≤ 4	SSO ≤ 8	SSO ≤ 16	
0.75 MHz to 50 MHz	0.50	0.60	0.80	1.20	%
50 MHz to 250 MHz	2.50	4.00	6.00	12.00	%

Notes:

- 1. This delay is a function of voltage and temperature. See Table 2-6 on page 2-6 and Table 2-7 on page 2-7 for deratings.
- 2. $T_{.I} = 25^{\circ}C$, VCC = 1.5 V
- 3. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help associated with the core for more information.
- 4. Maximum value obtained for a STD speed grade device in Worst-Case Commercial conditions. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 and Table 2-7 on page 2-7 for derating values.
- 5. Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by the period jitter parameter.
- 6. VCO output jitter is calculated as a percentage of the VCO frequency. The jitter (in ps) can be calculated by multiplying the VCO period by the % jitter. The VCO jitter (in ps) applies to CCC_OUT, regardless of the output divider settings. For example, if the jitter on VCO is 300 ps, the jitter on CCC_OUT is also 300 ps, no matter what the settings are for the output divider.
- 7. Measurements done with LVTTL 3.3 V 8 mA I/O drive strength and high slew rate. VCC/VCCPLL = 1.425 V, VCCI = 3.3 V, VQ/PQ/TQ type of packages, 20 pF load.
- 8. SSOs are outputs that are synchronous to a single clock domain and have their clock-to-out times within ±200 ps of each other. Switching I/Os are placed outside of the PLL bank. Refer to the "Simultaneously Switching Outputs (SSOs) and Printed Circuit Board Layout" section in the IGLOO nano FPGA Fabric User's Guide.
- 9. The AGLN010, AGLN015, and AGLN020 devices do not support PLLs.

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Table 2-101 • IGLOO nano CCC/PLL Specification
For IGLOO nano V2 Devices, 1.2 V DC Core Supply Voltage

Parameter		Min.	Тур.	Max.	Units
Clock Conditioning Circuitry Input Frequency f _{IN_CCC}		1.5		160	MHz
Clock Conditioning Circuitry Output Frequency f _{OUT_CC}	0	0.75		160	MHz
Delay Increments in Programmable Delay Blocks ^{1, 2}			580 ³		ps
lumber of Programmable Values in Each Programmable Delay Block				32	
Serial Clock (SCLK) for Dynamic PLL ^{4,9}				60	
put Cycle-to-Cycle Jitter (peak magnitude)				0.25	ns
Acquisition Time					
	LockControl = 0			300	μs
	LockControl = 1			6.0	ms
Tracking Jitter ⁵					
	LockControl = 0			4	ns
	LockControl = 1			3	ns
Output Duty Cycle	•	48.5		51.5	%
Delay Range in Block: Programmable Delay 1 1, 2		2.3		20.86	ns
Delay Range in Block: Programmable Delay 2 1, 2		0.025		20.86	ns
Delay Range in Block: Fixed Delay ^{1, 2}			5.7		ns
VCO Output Peak-to-Peak Period Jitter F _{CCC_OUT} ⁶		Max Pe	ak-to-Peal	Reriod Jitte	er ^{6,7,8}
	SSO ≤ 2	SSO ≤ 4	SSO ≤ 8	SSO ≤ 16	
0.75 MHz to 50MHz	0.50	1.20	2.00	3.00	%
50 MHz to 100 MHz	2.50	5.00	7.00	15.00	%

Notes:

- 1. This delay is a function of voltage and temperature. See Table 2-6 on page 2-6 and Table 2-7 on page 2-7 for deratings.
- 2. $T_J = 25$ °C, $V_{CC} = 1.2 V$.
- 3. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help associated with the core for more information.
- 4. Maximum value obtained for a STD speed grade device in Worst-Case Commercial conditions. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 and Table 2-7 on page 2-7 for derating values.
- 5. Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to the PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by the period jitter parameter.
- 6. VCO output jitter is calculated as a percentage of the VCO frequency. The jitter (in ps) can be calculated by multiplying the VCO period by the % jitter. The VCO jitter (in ps) applies to CCC_OUT, regardless of the output divider settings. For example, if the jitter on VCO is 300 ps, the jitter on CCC_OUT is also 300 ps, no matter what the settings are for the output divider.
- 7. Measurements done with LVTTL 3.3 V 8 mA I/O drive strength and high slew rate. VCC/VCCPLL = 1.14 V, VCCI = 3.3 V, VQ/PQ/TQ type of packages, 20 pF load.
- 8. SSOs are outputs that are synchronous to a single clock domain and have their clock-to-out times within ±200 ps of each other. Switching I/Os are placed outside of the PLL bank. Refer to the "Simultaneously Switching Outputs (SSOs) and Printed Circuit Board Layout" section in the IGLOO nano FPGA Fabric User's Guide.
- 9. The AGLN010, AGLN015, and AGLN020 devices do not support PLLs.

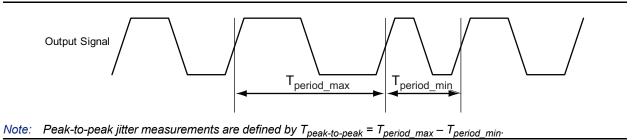


Figure 2-26 • Peak-to-Peak Jitter Definition

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Embedded SRAM and FIFO Characteristics

SRAM

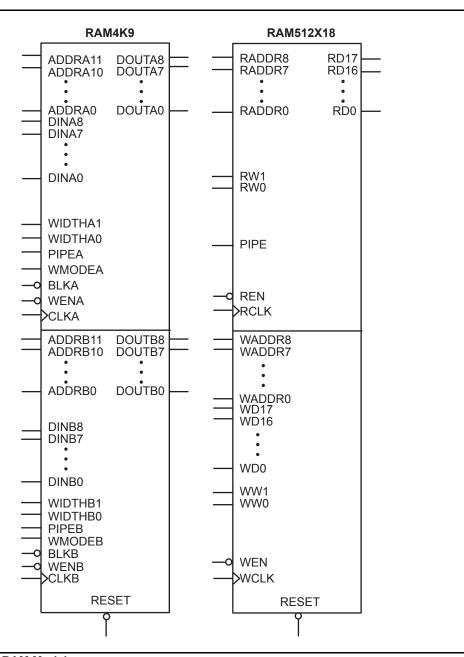


Figure 2-27 • RAM Models

Timing Waveforms

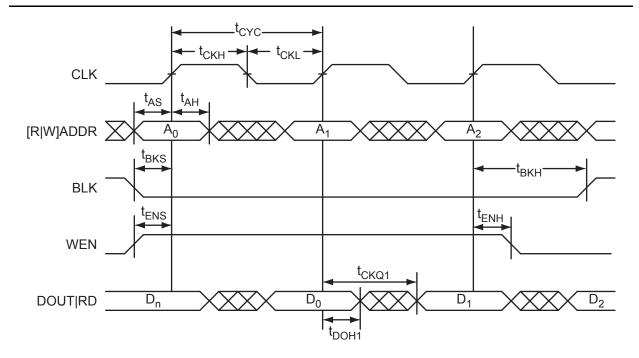


Figure 2-28 • RAM Read for Pass-Through Output. Applicable to Both RAM4K9 and RAM512x18.

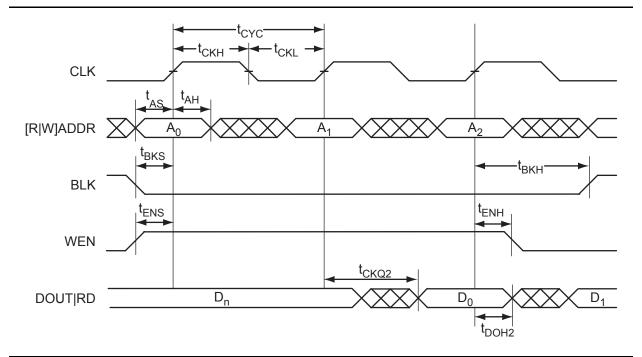


Figure 2-29 • RAM Read for Pipelined Output. Applicable to Both RAM4K9 and RAM512x18.

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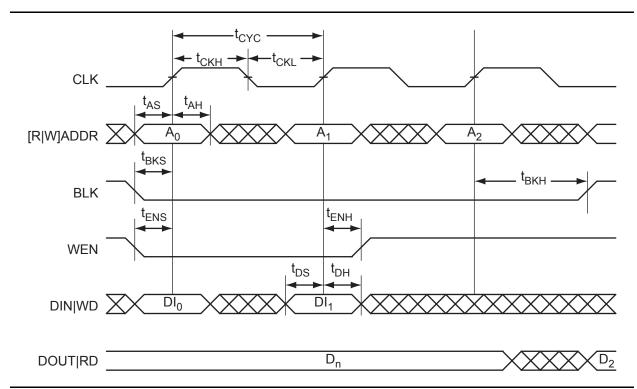


Figure 2-30 • RAM Write, Output Retained (WMODE = 0). Applicable to Both RAM4K9 and RAM512x18.

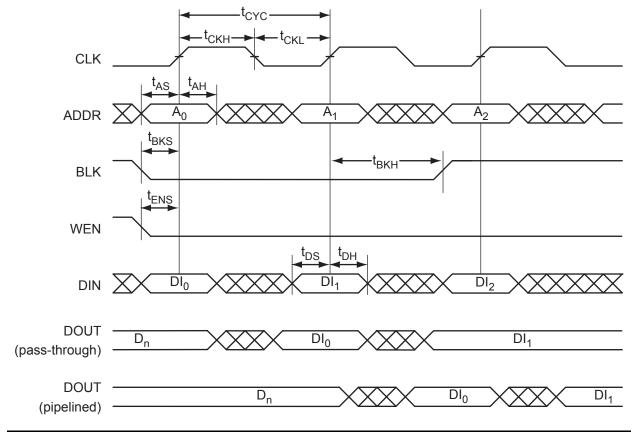


Figure 2-31 • RAM Write, Output as Write Data (WMODE = 1). Applicable to RAM4K9 Only.

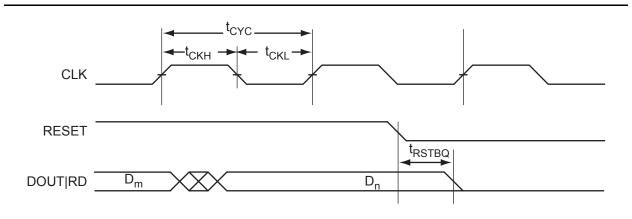


Figure 2-32 • RAM Reset. Applicable to Both RAM4K9 and RAM512x18.

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Timing Characteristics

1.5 V DC Core Voltage

Table 2-102 • RAM4K9

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{AS}	Address setup time	0.69	ns
t _{AH}	Address hold time	0.13	ns
t _{ENS}	REN, WEN setup time	0.68	ns
t _{ENH}	REN, WEN hold time	0.13	ns
t _{BKS}	BLK setup time	1.37	ns
t _{BKH}	BLK hold time	0.13	ns
t _{DS}	Input data (DIN) setup time	0.59	ns
t _{DH}	Input data (DIN) hold time	0.30	ns
t _{CKQ1}	Clock HIGH to new data valid on DOUT (output retained, WMODE = 0)	2.94	ns
	Clock HIGH to new data valid on DOUT (flow-through, WMODE = 1)	2.55	ns
t _{CKQ2}	Clock HIGH to new data valid on DOUT (pipelined)	1.51	ns
t _{C2CWWL} 1	Address collision clk-to-clk delay for reliable write after write on same address; applicable to closing edge	0.23	ns
t _{C2CRWH} 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.35	ns
t _{C2CWRH} 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	0.41	ns
t _{RSTBQ}	RESET Low to data out Low on DOUT (flow-through)	1.72	ns
	RESET Low to data out Low on DOUT (pipelined)	1.72	ns
t _{REMRSTB}	RESET removal	0.51	ns
t _{RECRSTB}	RESET recovery	2.68	ns
t _{MPWRSTB}	RESET minimum pulse width	0.68	ns
t _{CYC}	Clock cycle time	6.24	ns
F _{MAX}	Maximum frequency	160	MHz

Notes:

- For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-103 • RAM512X18

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{AS}	Address setup time	0.69	ns
t _{AH}	Address hold time	0.13	ns
t _{ENS}	REN, WEN setup time	0.61	ns
t _{ENH}	REN, WEN hold time	0.07	ns
t _{DS}	Input data (WD) setup time	0.59	ns
t _{DH}	Input data (WD) hold time	0.30	ns
t _{CKQ1}	Clock HIGH to new data valid on RD (output retained)	3.51	ns
t _{CKQ2}	Clock HIGH to new data valid on RD (pipelined)	1.43	ns
t _{C2CRWH} ¹	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.35	ns
t _{C2CWRH} 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	0.42	ns
t _{RSTBQ}	RESET Low to data out Low on RD (flow-through)	1.72	ns
	RESET Low to data out Low on RD (pipelined)	1.72	ns
t _{REMRSTB}	RESET removal	0.51	0.51
t _{RECRSTB}	RESET recovery	2.68	ns
t _{MPWRSTB}	RESET minimum pulse width	0.68	ns
t _{CYC}	Clock cycle time	6.24	ns
F _{MAX}	Maximum frequency	160	MHz

Notes:

2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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^{1.} For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.



1.2 V DC Core Voltage

Table 2-104 • RAM4K9

Commercial-Case Conditions: $T_J = 70$ °C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{AS}	Address setup time	1.28	ns
t _{AH}	Address hold time	0.25	ns
t _{ENS}	REN, WEN setup time	1.25	ns
t _{ENH}	REN, WEN hold time	0.25	ns
t _{BKS}	BLK setup time	2.54	ns
t _{BKH}	BLK hold time	0.25	ns
t _{DS}	Input data (DIN) setup time	1.10	ns
t _{DH}	Input data (DIN) hold time	0.55	ns
t _{CKQ1}	Clock HIGH to new data valid on DOUT (output retained, WMODE = 0)	5.51	ns
	Clock HIGH to new data valid on DOUT (flow-through, WMODE = 1)	4.77	ns
t _{CKQ2}	Clock HIGH to new data valid on DOUT (pipelined)	2.82	ns
t _{C2CWWL} 1	Address collision clk-to-clk delay for reliable write after write on same address; applicable to closing edge	0.30	ns
t _{C2CRWH} 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.89	ns
t _{C2CWRH} 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	1.01	ns
t _{RSTBQ}	RESET LOW to data out LOW on DOUT (flow-through)	3.21	ns
	RESET LOW to data out LOW on DO (pipelined)	3.21	ns
t _{REMRSTB}	RESET removal	0.93	ns
t _{RECRSTB}	RESET recovery	4.94	ns
t _{MPWRSTB}	RESET minimum pulse width	1.18	ns
t _{CYC}	Clock cycle time	10.90	ns
F _{MAX}	Maximum frequency	92	MHz

Notes:

2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

^{1.} For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.

Table 2-105 • RAM512X18

Commercial-Case Conditions: $T_J = 70$ °C, Worst-Case VCC = 1.14 V

Parameter	Description	Std.	Units
t _{AS}	Address setup time	1.28	ns
t _{AH}	Address hold time	0.25	ns
t _{ENS}	REN, WEN setup time	1.13	ns
t _{ENH}	REN, WEN hold time	0.13	ns
t _{DS}	Input data (WD) setup time	1.10	ns
t _{DH}	Input data (WD) hold time	0.55	ns
t _{CKQ1}	Clock High to new data valid on RD (output retained)	6.56	ns
t _{CKQ2}	Clock High to new data valid on RD (pipelined)	2.67	ns
t _{C2CRWH} 1	Address collision clk-to-clk delay for reliable read access after write on same address; applicable to opening edge	0.87	ns
t _{C2CWRH} 1	Address collision clk-to-clk delay for reliable write access after read on same address; applicable to opening edge	1.04	ns
t _{RSTBQ}	RESET LOW to data out LOW on RD (flow through)	3.21	ns
	RESET LOW to data out LOW on RD (pipelined)	3.21	ns
t _{REMRSTB}	RESET removal	0.93	ns
t _{RECRSTB}	RESET recovery	4.94	ns
t _{MPWRSTB}	RESET minimum pulse width	1.18	ns
t _{CYC}	Clock cycle time	10.90	ns
F _{MAX}	Maximum frequency	92	MHz

Notes:

2. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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^{1.} For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.

FIFO

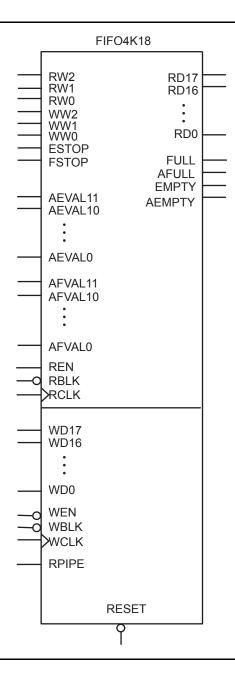


Figure 2-33 • FIFO Model

Timing Waveforms

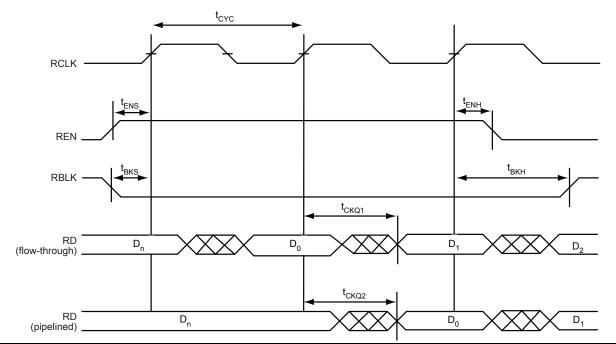


Figure 2-34 • FIFO Read

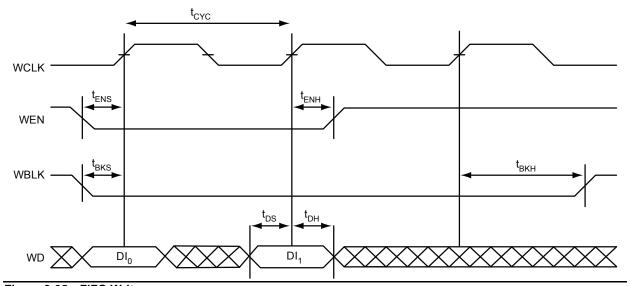


Figure 2-35 • FIFO Write

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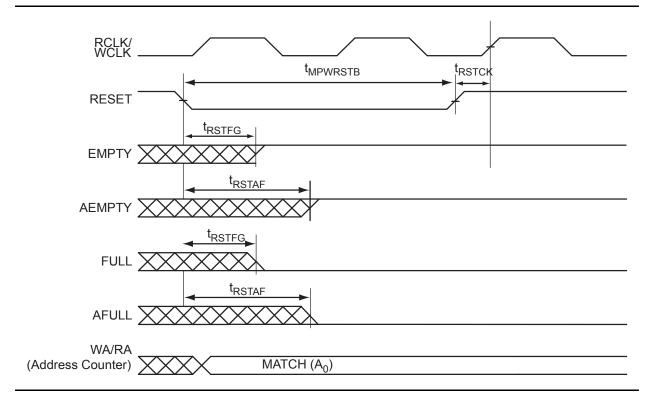


Figure 2-36 • FIFO Reset

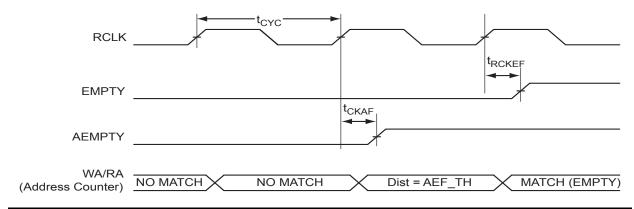


Figure 2-37 • FIFO EMPTY Flag and AEMPTY Flag Assertion

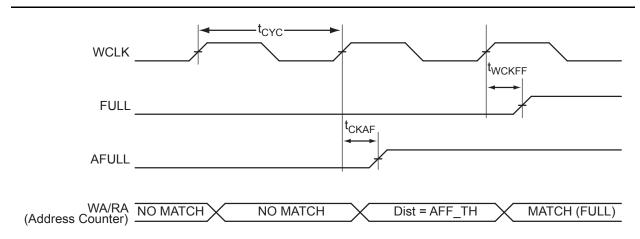


Figure 2-38 • FIFO FULL Flag and AFULL Flag Assertion

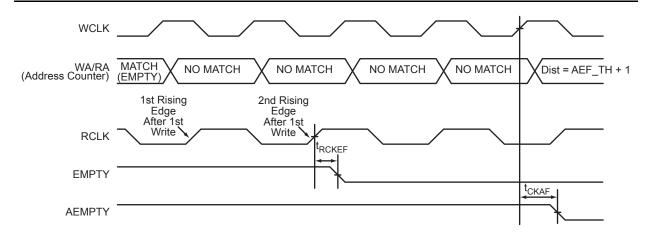


Figure 2-39 • FIFO EMPTY Flag and AEMPTY Flag Deassertion

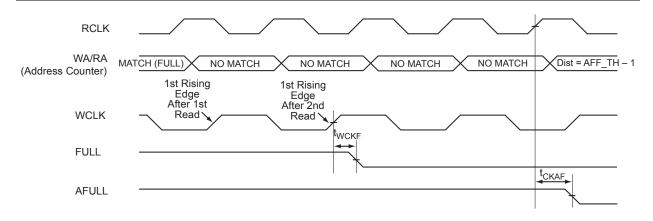


Figure 2-40 • FIFO FULL Flag and AFULL Flag Deassertion

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Timing Characteristics

1.5 V DC Core Voltage

Table 2-106 • FIFO

Worst Commercial-Case Conditions: $T_J = 70$ °C, VCC = 1.425 V

Parameter	Description	Std.	Units
t _{ENS}	REN, WEN Setup Time	1.66	ns
t _{ENH}	REN, WEN Hold Time	0.13	ns
t _{BKS}	BLK Setup Time	0.30	ns
t _{BKH}	BLK Hold Time	0.00	ns
t _{DS}	Input Data (WD) Setup Time	0.63	ns
t _{DH}	Input Data (WD) Hold Time	0.20	ns
t _{CKQ1}	Clock High to New Data Valid on RD (flow-through)	2.77	ns
t _{CKQ2}	Clock High to New Data Valid on RD (pipelined)	1.50	ns
t _{RCKEF}	RCLK High to Empty Flag Valid	2.94	ns
t _{WCKFF}	WCLK High to Full Flag Valid	2.79	ns
t _{CKAF}	Clock High to Almost Empty/Full Flag Valid	10.71	ns
t _{RSTFG}	RESET Low to Empty/Full Flag Valid	2.90	ns
t _{RSTAF}	RESET Low to Almost Empty/Full Flag Valid	10.60	ns
t _{RSTBQ}	RESET Low to Data Out LOW on RD (flow-through)	1.68	ns
	RESET Low to Data Out LOW on RD (pipelined)	1.68	ns
t _{REMRSTB}	RESET Removal	0.51	ns
t _{RECRSTB}	RESET Recovery	2.68	ns
t _{MPWRSTB}	RESET Minimum Pulse Width	0.68	ns
t _{CYC}	Clock Cycle Time	6.24	ns
F _{MAX}	Maximum Frequency for FIFO	160	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-107 • FIFO

Worst Commercial-Case Conditions: T_J = 70°C, VCC = 1.14 V

Parameter	Description	Std.	Units
t _{ENS}	REN, WEN Setup Time	3.44	ns
t _{ENH}	REN, WEN Hold Time	0.26	ns
t _{BKS}	BLK Setup Time	0.30	ns
t _{BKH}	BLK Hold Time	0.00	ns
t _{DS}	Input Data (DI) Setup Time	1.30	ns
t _{DH}	Input Data (DI) Hold Time	0.41	ns
t _{CKQ1}	Clock High to New Data Valid on RD (flow-through)	5.67	ns
t _{CKQ2}	Clock High to New Data Valid on RD (pipelined)	3.02	ns
t _{RCKEF}	RCLK High to Empty Flag Valid	6.02	ns
t _{WCKFF}	WCLK High to Full Flag Valid	5.71	ns
t _{CKAF}	Clock High to Almost Empty/Full Flag Valid	22.17	ns
t _{RSTFG}	RESET LOW to Empty/Full Flag Valid	5.93	ns
t _{RSTAF}	RESET LOW to Almost Empty/Full Flag Valid	21.94	ns
t _{RSTBQ}	RESET LOW to Data Out Low on RD (flow-through)	3.41	ns
	RESET LOW to Data Out Low on RD (pipelined)	4.09	3.41
t _{REMRSTB}	RESET Removal	1.02	ns
t _{RECRSTB}	RESET Recovery	5.48	ns
t _{MPWRSTB}	RESET Minimum Pulse Width	1.18	ns
t _{CYC}	Clock Cycle Time	10.90	ns
F _{MAX}	Maximum Frequency for FIFO	92	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

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Embedded FlashROM Characteristics

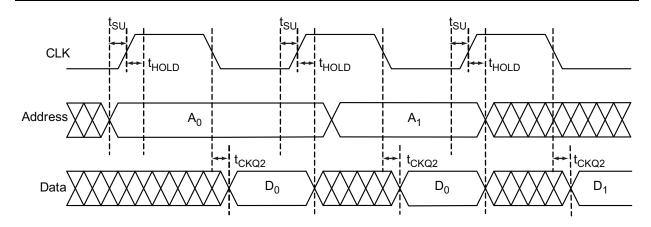


Figure 2-41 • Timing Diagram

Timing Characteristics

1.5 V DC Core Voltage

Table 2-108 • Embedded FlashROM Access Time Worst Commercial-Case Conditions: $T_J = 70^{\circ}C$, VCC = 1.425 V

Parameter	Description	Std.	Units
t _{SU}	Address Setup Time	0.57	ns
t _{HOLD}	Address Hold Time	0.00	ns
t _{CK2Q}	Clock to Out	20.90	ns
F _{MAX}	Maximum Clock Frequency	15	MHz

1.2 V DC Core Voltage

Table 2-109 • Embedded FlashROM Access Time Worst Commercial-Case Conditions: $T_J = 70^{\circ}\text{C}$, VCC = 1.14 V

Parameter	Description	Std.	Units
t _{su}	Address Setup Time	0.59	ns
t _{HOLD}	Address Hold Time	0.00	ns
t _{CK2Q}	Clock to Out	35.74	ns
F _{MAX}	Maximum Clock Frequency	10	MHz

JTAG 1532 Characteristics

JTAG timing delays do not include JTAG I/Os. To obtain complete JTAG timing, add I/O buffer delays to the corresponding standard selected; refer to the I/O timing characteristics in the "User I/O Characteristics" section on page 2-15 for more details.

Timing Characteristics

1.5 V DC Core Voltage

Table 2-110 • JTAG 1532

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	Std.	Units
t _{DISU}	Test Data Input Setup Time	1.00	ns
t _{DIHD}	Test Data Input Hold Time	2.00	ns
t _{TMSSU}	Test Mode Select Setup Time	1.00	ns
t _{TMDHD}	Test Mode Select Hold Time	2.00	ns
t _{TCK2Q}	Clock to Q (data out)	8.00	ns
t _{RSTB2Q}	Reset to Q (data out)	25.00	ns
F _{TCKMAX}	TCK Maximum Frequency	15	MHz
t _{TRSTREM}	ResetB Removal Time	0.58	ns
t _{TRSTREC}	ResetB Recovery Time	0.00	ns
t _{TRSTMPW}	ResetB Minimum Pulse	TBD	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

1.2 V DC Core Voltage

Table 2-111 • JTAG 1532

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.14 V

Parameter	Description	St	d.	Units
t _{DISU}	Test Data Input Setup Time	1.9	50	ns
t _{DIHD}	Test Data Input Hold Time	3.0	00	ns
t _{TMSSU}	Test Mode Select Setup Time	1.5	50	ns
t _{TMDHD}	Test Mode Select Hold Time	3.0	00	ns
t _{TCK2Q}	Clock to Q (data out)	11.	00	ns
t _{RSTB2Q}	Reset to Q (data out)	30.	.00	ns
F _{TCKMAX}	TCK Maximum Frequency	9.0	00	MHz
t _{TRSTREM}	ResetB Removal Time	1.	18	ns
t _{TRSTREC}	ResetB Recovery Time	0.0	00	ns
t _{TRSTMPW}	ResetB Minimum Pulse	TE	BD	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



3 - Pin Descriptions

Supply Pins

GND Ground

Ground supply voltage to the core, I/O outputs, and I/O logic.

GNDQ Ground (quiet)

Quiet ground supply voltage to input buffers of I/O banks. Within the package, the GNDQ plane is decoupled from the simultaneous switching noise originated from the output buffer ground domain. This minimizes the noise transfer within the package and improves input signal integrity. GNDQ must always be connected to GND on the board.

VCC Core Supply Voltage

Supply voltage to the FPGA core, nominally 1.5 V for IGLOO nano V5 devices, and 1.2 V or 1.5 V for IGLOO nano V2 devices. VCC is required for powering the JTAG state machine in addition to VJTAG. Even when a device is in bypass mode in a JTAG chain of interconnected devices, both VCC and VJTAG must remain powered to allow JTAG signals to pass through the device.

VCCIBx I/O Supply Voltage

Supply voltage to the bank's I/O output buffers and I/O logic. Bx is the I/O bank number. There are up to eight I/O banks on low power flash devices plus a dedicated VJTAG bank. Each bank can have a separate VCCI connection. All I/Os in a bank will run off the same VCCIBx supply. VCCI can be 1.2 V, 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VCCI pins tied to GND.

VMVx I/O Supply Voltage (quiet)

Quiet supply voltage to the input buffers of each I/O bank. *x* is the bank number. Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks. This minimizes the noise transfer within the package and improves input signal integrity. Each bank must have at least one VMV connection, and no VMV should be left unconnected. All I/Os in a bank run off the same VMVx supply. VMV is used to provide a quiet supply voltage to the input buffers of each I/O bank. VMVx can be 1.2 V, 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VMV pins tied to GND. VMV and VCCI should be at the same voltage within a given I/O bank. Used VMV pins must be connected to the corresponding VCCI pins of the same bank (i.e., VMV0 to VCCIB0, VMV1 to VCCIB1, etc.).

VCCPLA/B/C/D/E/F PLL Supply Voltage

Supply voltage to analog PLL, nominally 1.5 V or 1.2 V.

When the PLLs are not used, the Microsemi Designer place-and-route tool automatically disables the unused PLLs to lower power consumption. The user should tie unused VCCPLx and VCOMPLx pins to ground. Microsemi recommends tying VCCPLx to VCC and using proper filtering circuits to decouple VCC noise from the PLLs. Refer to the PLL Power Supply Decoupling section of the "Clock Conditioning Circuits in IGLOO and ProASIC3 Devices" chapter in the *IGLOO nano FPGA Fabric User's Guide* for a complete board solution for the PLL analog power supply and ground.

There is one VCCPLF pin on IGLOO nano devices.

VCOMPLA/B/C/D/E/F PLL Ground

Ground to analog PLL power supplies. When the PLLs are not used, the Microsemi Designer place-and-route tool automatically disables the unused PLLs to lower power consumption. The user should tie unused VCCPLx and VCOMPLx pins to ground.

There is one VCOMPLF pin on IGLOO nano devices.

VJTAG JTAG Supply Voltage

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG



Pin Descriptions

interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND. It should be noted that VCC is required to be powered for JTAG operation; VJTAG alone is insufficient. If a device is in a JTAG chain of interconnected boards, the board containing the device can be powered down, provided both VJTAG and VCC to the part remain powered; otherwise, JTAG signals will not be able to transition the device, even in bypass mode.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

VPUMP Programming Supply Voltage

IGLOO nano devices support single-voltage ISP of the configuration flash and FlashROM. For programming, VPUMP should be 3.3 V nominal. During normal device operation, VPUMP can be left floating or can be tied (pulled up) to any voltage between 0 V and the VPUMP maximum. Programming power supply voltage (VPUMP) range is listed in the datasheet.

When the VPUMP pin is tied to ground, it will shut off the charge pump circuitry, resulting in no sources of oscillation from the charge pump circuitry.

For proper programming, $0.01~\mu F$ and $0.33~\mu F$ capacitors (both rated at 16 V) are to be connected in parallel across VPUMP and GND, and positioned as close to the FPGA pins as possible.

Microsemi recommends that VPUMP and VJTAG power supplies be kept separate with independent filtering capacitors rather than supplying them from a common rail.

User Pins

I/O User Input/Output

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Input and output signal levels are compatible with the I/O standard selected.

During programming, I/Os become tristated and weakly pulled up to VCCI. With VCCI, VMV, and VCC supplies continuously powered up, when the device transitions from programming to operating mode, the I/Os are instantly configured to the desired user configuration.

Unused I/Os are configured as follows:

- Output buffer is disabled (with tristate value of high impedance)
- Input buffer is disabled (with tristate value of high impedance)
- Weak pull-up is programmed

GL Globals

GL I/Os have access to certain clock conditioning circuitry (and the PLL) and/or have direct access to the global network (spines). Additionally, the global I/Os can be used as regular I/Os, since they have identical capabilities. Unused GL pins are configured as inputs with pull-up resistors.

See more detailed descriptions of global I/O connectivity in the "Clock Conditioning Circuits in IGLOO and ProASIC3 Devices" chapter in the IGLOO nano FPGA Fabric User's Guide. All inputs labeled GC/GF are direct inputs into the quadrant clocks. For example, if GAA0 is used for an input, GAA1 and GAA2 are no longer available for input to the quadrant globals. All inputs labeled GC/GF are direct inputs into the chip-level globals, and the rest are connected to the quadrant globals. The inputs to the global network are multiplexed, and only one input can be used as a global input.

Refer to the "I/O Structures in nano Devices" chapter of the IGLOO nano FPGA Fabric User's Guide for an explanation of the naming of global pins.

FF Flash*Freeze Mode Activation Pin

Flash*Freeze is available on IGLOO nano devices. The FF pin is a dedicated input pin used to enter and exit Flash*Freeze mode. The FF pin is active low, has the same characteristics as a single-ended I/O, and must meet the maximum rise and fall times. When Flash*Freeze mode is not used in the design, the FF pin is available as a regular I/O.

When Flash*Freeze mode is used, the FF pin must not be left floating to avoid accidentally entering Flash*Freeze mode. While in Flash*Freeze mode, the Flash*Freeze pin should be constantly asserted.

The Flash*Freeze pin can be used with any single-ended I/O standard supported by the I/O bank in which the pin is located, and input signal levels compatible with the I/O standard selected. The FF pin

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should be treated as a sensitive asynchronous signal. When defining pin placement and board layout, simultaneously switching outputs (SSOs) and their effects on sensitive asynchronous pins must be considered.

Unused FF or I/O pins are tristated with weak pull-up. This default configuration applies to both Flash*Freeze mode and normal operation mode. No user intervention is required.

Table 3-1 shows the Flash*Freeze pin location on the available packages for IGLOO nano devices. The Flash*Freeze pin location is independent of device (except for a PQ208 package), allowing migration to larger or smaller IGLOO nano devices while maintaining the same pin location on the board. Refer to the "Flash*Freeze Technology and Low Power Modes" chapter of the IGLOO nano FPGA Fabric User's Guide for more information on I/O states during Flash*Freeze mode.

Table 3-1 • Flash*Freeze Pin Locations for IGLOO nano Devices

Package	Flash*Freeze Pin
CS81/UC81	H2
QN48	14
QN68	18
VQ100	27
UC36	E2

JTAG Pins

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the part must be supplied to allow JTAG signals to transition the device. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND.

TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500 Ω to 1 k Ω will satisfy the requirements. Refer to Table 3-2 for more information.

Table 3-2 • Recommended Tie-Off Values for the TCK and TRST Pins

VJTAG	Tie-Off Resistance ^{1,2}
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

Notes:

- 1. The TCK pin can be pulled-up or pulled-down.
- 2. The TRST pin is pulled-down.
- 3. Equivalent parallel resistance if more than one device is on the JTAG chain



Pin Descriptions

Table 3-3 • TRST and TCK Pull-Down Recommendations

VJTAG	Tie-Off Resistance*
VJTAG at 3.3 V	200 Ω to 1 k Ω
VJTAG at 2.5 V	200 Ω to 1 k Ω
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

Note: Equivalent parallel resistance if more than one device is on the JTAG chain

TDI Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

TMS Test Mode Select

The TMS pin controls the use of the IEEE 1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

TRST Boundary Scan Reset Pin

The TRST pin functions as an active-low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the test access port (TAP) is held in reset mode. The resistor values must be chosen from Table 3-2 and must satisfy the parallel resistance value requirement. The values in Table 3-2 correspond to the resistor recommended when a single device is used, and the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entrance to an undesired JTAG state. In such cases, Microsemi recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all VJTAG voltages, 500 Ω to 1 k Ω will satisfy the requirements.

Special Function Pins

NC No Connect

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

DC Do Not Connect

This pin should not be connected to any signals on the PCB. These pins should be left unconnected.

Packaging

Semiconductor technology is constantly shrinking in size while growing in capability and functional integration. To enable next-generation silicon technologies, semiconductor packages have also evolved to provide improved performance and flexibility.

Microsemi consistently delivers packages that provide the necessary mechanical and environmental protection to ensure consistent reliability and performance. Microsemi IC packaging technology efficiently supports high-density FPGAs with large-pin-count Ball Grid Arrays (BGAs), but is also flexible enough to accommodate stringent form factor requirements for Chip Scale Packaging (CSP). In addition, Microsemi offers a variety of packages designed to meet your most demanding application and economic requirements for today's embedded and mobile systems.

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Related Documents

User's Guides

IGLOO nano FPGA Fabric User's Guide
http://www.microsemi.com/soc/documents/IGLOO nano UG.pdf

Packaging Documents

The following documents provide packaging information and device selection for low power flash devices.

Product Catalog

http://www.microsemi.com/soc/documents/ProdCat_PIB.pdf

Lists devices currently recommended for new designs and the packages available for each member of the family. Use this document or the datasheet tables to determine the best package for your design, and which package drawing to use.

Package Mechanical Drawings

http://www.microsemi.com/soc/documents/PckgMechDrwngs.pdf

This document contains the package mechanical drawings for all packages currently or previously supplied by Microsemi. Use the bookmarks to navigate to the package mechanical drawings.

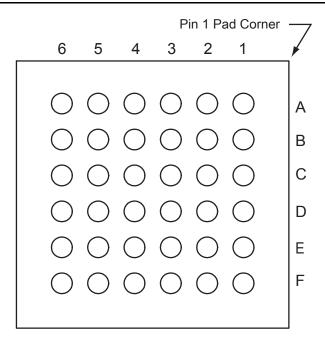
Additional packaging materials are on the Microsemi SoC Products Group website:

http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



4 – Package Pin Assignments

UC36



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



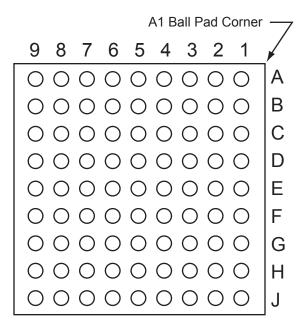
Paci	kage	Pin	Assia	nments

11000		
UC36		
Pin Number	AGLN010 Function	
A1	IO21RSB1	
A2	IO18RSB1	
A3	IO13RSB1	
A4	GDC0/IO00RSB0	
A5	IO06RSB0	
A6	GDA0/IO04RSB0	
B1	GEC0/IO37RSB1	
B2	IO20RSB1	
В3	IO15RSB1	
B4	IO09RSB0	
B5	IO08RSB0	
В6	IO07RSB0	
C1	IO22RSB1	
C2	GEA0/IO34RSB1	
C3	GND	
C4	GND	
C5	VCCIB0	
C6	IO02RSB0	
D1	IO33RSB1	
D2	VCCIB1	
D3	VCC	
D4	VCC	
D5	IO10RSB0	
D6	IO11RSB0	
E1	IO32RSB1	
E2	FF/IO31RSB1	
E3	TCK	
E4	VPUMP	
E5	TRST	
E6	VJTAG	
F1	IO29RSB1	
F2	IO25RSB1	
F3	IO23RSB1	
F4	TDI	

UC36	
Pin Number	AGLN010 Function
F5	TMS
F6	TDO

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UC81



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



UC81		
Pin Number	AGLN020 Function	
A1	IO64RSB2	
A2	IO54RSB2	
A3	IO57RSB2	
A4	IO36RSB1	
A5	IO32RSB1	
A6	IO24RSB1	
A7	IO20RSB1	
A8	IO04RSB0	
A9	IO08RSB0	
B1	IO59RSB2	
B2	IO55RSB2	
В3	IO62RSB2	
B4	IO34RSB1	
B5	IO28RSB1	
В6	IO22RSB1	
В7	IO18RSB1	
B8	IO00RSB0	
В9	IO03RSB0	
C1	IO51RSB2	
C2	IO50RSB2	
C3	NC	
C4	NC	
C5	NC	
C6	NC	
C7	NC	
C8	IO10RSB0	
C9	IO07RSB0	
D1	IO49RSB2	
D2	IO44RSB2	
D3	NC	
D4	VCC	
D5	VCCIB2	
D6	GND	
D7	NC	
D8	IO13RSB0	
D9	IO12RSB0	

UC81		
Pin Number	AGLN020 Function	
E1	GEC0/IO48RSB2	
E2	GEA0/IO47RSB2	
E3	NC	
E4	VCCIB1	
E5	VCC	
E6	VCCIB0	
E7	NC	
E8	GDA0/IO15RSB0	
E9	GDC0/IO14RSB0	
F1	IO46RSB2	
F2	IO45RSB2	
F3	NC	
F4	GND	
F5	VCCIB1	
F6	NC	
F7	NC	
F8	IO16RSB0	
F9	IO17RSB0	
G1	IO43RSB2	
G2	IO42RSB2	
G3	IO41RSB2	
G4	IO31RSB1	
G5	NC	
G6	IO21RSB1	
G7	NC	
G8	VJTAG	
G9	TRST	
H1	IO40RSB2	
H2	FF/IO39RSB1	
НЗ	IO35RSB1	
H4	IO29RSB1	
H5	IO26RSB1	
H6	IO25RSB1	
H7	IO19RSB1	
H8	TDI	
H9	TDO	

UC81		
Pin Number	AGLN020 Function	
J1	IO38RSB1	
J2	IO37RSB1	
J3	IO33RSB1	
J4	IO30RSB1	
J5	IO27RSB1	
J6	IO23RSB1	
J7	TCK	
J8	TMS	
J9	VPUMP	

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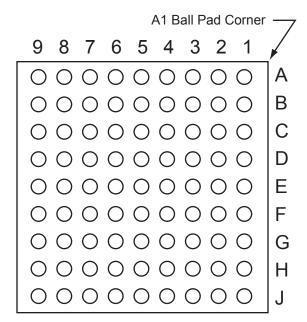
UC81			
	AGLN030Z		
Pin Number	Function		
A1	IO00RSB0		
A2	IO02RSB0		
A3	IO06RSB0		
A4	IO11RSB0		
A5	IO16RSB0		
A6	IO19RSB0		
A7	IO22RSB0		
A8	IO24RSB0		
A9	IO26RSB0		
B1	IO81RSB1		
B2	IO04RSB0		
В3	IO10RSB0		
B4	IO13RSB0		
B5	IO15RSB0		
В6	IO20RSB0		
В7	IO21RSB0		
B8	IO28RSB0		
В9	IO25RSB0		
C1	IO79RSB1		
C2	IO80RSB1		
C3	IO08RSB0		
C4	IO12RSB0		
C5	IO17RSB0		
C6	IO14RSB0		
C7	IO18RSB0		
C8	IO29RSB0		
C9	IO27RSB0		
D1	IO74RSB1		
D2	IO76RSB1		
D3	IO77RSB1		
D4	VCC		
D5	VCCIB0		
D6	GND		
D7	IO23RSB0		
D8	IO31RSB0		

UC81		
	AGLN030Z	
Pin Number	Function	
D9	IO30RSB0	
E1	GEB0/IO71RSB1	
E2	GEA0/IO72RSB1	
E3	GEC0/IO73RSB1	
E4	VCCIB1	
E5	VCC	
E6	VCCIB0	
E7	GDC0/IO32RSB0	
E8	GDA0/IO33RSB0	
E9	GDB0/IO34RSB0	
F1	IO68RSB1	
F2	IO67RSB1	
F3	IO64RSB1	
F4	GND	
F5	VCCIB1	
F6	IO47RSB1	
F7	IO36RSB0	
F8	IO38RSB0	
F9	IO40RSB0	
G1	IO65RSB1	
G2	IO66RSB1	
G3	IO57RSB1	
G4	IO53RSB1	
G5	IO49RSB1	
G6	IO45RSB1	
G7	IO46RSB1	
G8	VJTAG	
G9	TRST	
H1	IO62RSB1	
H2	FF/IO60RSB1	
H3	IO58RSB1	
H4	IO54RSB1	
H5	IO48RSB1	
H6	IO43RSB1	
H7	IO42RSB1	

UC81		
Pin Number	AGLN030Z Function	
H8	TDI	
H9	TDO	
J1	IO63RSB1	
J2	IO61RSB1	
J3	IO59RSB1	
J4	IO56RSB1	
J5	IO52RSB1	
J6	IO44RSB1	
J7	TCK	
J8	TMS	
J9	VPUMP	



CS81



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

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Pin Number AGLN020 Function A1 IO64RSB2 A2 IO54RSB2 A3 IO57RSB2 A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2	CS81		
A2 IO54RSB2 A3 IO57RSB2 A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO33RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND	Pin Number	AGLN020 Function	
A3 IO57RSB2 A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC <t< td=""><td>A1</td><td>IO64RSB2</td></t<>	A1	IO64RSB2	
A4 IO36RSB1 A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO33RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A2	IO54RSB2	
A5 IO32RSB1 A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A3	IO57RSB2	
A6 IO24RSB1 A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A4	IO36RSB1	
A7 IO20RSB1 A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A5	IO32RSB1	
A8 IO04RSB0 A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A6	IO24RSB1	
A9 IO08RSB0 B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A7	IO20RSB1	
B1 IO59RSB2 B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A8	IO04RSB0	
B2 IO55RSB2 B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	A9	IO08RSB0	
B3 IO62RSB2 B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B1	IO59RSB2	
B4 IO34RSB1 B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO33RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B2	IO55RSB2	
B5 IO28RSB1 B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В3	IO62RSB2	
B6 IO22RSB1 B7 IO18RSB1 B8 IO00RSB0 B9 IO3RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B4	IO34RSB1	
B7 IO18RSB1 B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B5	IO28RSB1	
B8 IO00RSB0 B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В6	IO22RSB1	
B9 IO03RSB0 C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В7	IO18RSB1	
C1 IO51RSB2 C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	B8	IO00RSB0	
C2 IO50RSB2 C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	В9	IO03RSB0	
C3 NC C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C1	IO51RSB2	
C4 NC C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C2	IO50RSB2	
C5 NC C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C3	NC	
C6 NC C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C4	NC	
C7 NC C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C5	NC	
C8 IO10RSB0 C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C6	NC	
C9 IO07RSB0 D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C7	NC	
D1 IO49RSB2 D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C8	IO10RSB0	
D2 IO44RSB2 D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	C9	IO07RSB0	
D3 NC D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	D1	IO49RSB2	
D4 VCC D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	D2	IO44RSB2	
D5 VCCIB2 D6 GND D7 NC D8 IO13RSB0	D3	NC	
D6 GND D7 NC D8 IO13RSB0	D4	VCC	
D7 NC D8 IO13RSB0	D5	VCCIB2	
D8 IO13RSB0	D6	GND	
	D7	NC	
D9 IO12RSB0	D8	IO13RSB0	
	D9	IO12RSB0	

CS81		
Pin Number	AGLN020 Function	
E1	GEC0/IO48RSB2	
E2	GEA0/IO47RSB2	
E3	NC	
E4	VCCIB1	
E5	VCC	
E6	VCCIB0	
E7	NC	
E8	GDA0/IO15RSB0	
E9	GDC0/IO14RSB0	
F1	IO46RSB2	
F2	IO45RSB2	
F3	NC	
F4	GND	
F5	VCCIB1	
F6	NC	
F7	NC	
F8	IO16RSB0	
F9	IO17RSB0	
G1	IO43RSB2	
G2	IO42RSB2	
G3	IO41RSB2	
G4	IO31RSB1	
G5	NC	
G6	IO21RSB1	
G7	NC	
G8	VJTAG	
G9	TRST	
H1	IO40RSB2	
H2	FF/IO39RSB1	
H3	IO35RSB1	
H4	IO29RSB1	
H5	IO26RSB1	
H6	IO25RSB1	
H7	IO19RSB1	
H8	TDI	
H9	TDO	

	CS81
Pin Number	AGLN020 Function
J1	IO38RSB1
J2	IO37RSB1
J3	IO33RSB1
J4	IO30RSB1
J5	IO27RSB1
J6	IO23RSB1
J7	TCK
J8	TMS
J9	VPUMP



CS81	
	AGLN030Z
Pin Number	Function
A1	IO00RSB0
A2	IO02RSB0
А3	IO06RSB0
A4	IO11RSB0
A5	IO16RSB0
A6	IO19RSB0
A7	IO22RSB0
A8	IO24RSB0
A9	IO26RSB0
B1	IO81RSB1
B2	IO04RSB0
В3	IO10RSB0
B4	IO13RSB0
B5	IO15RSB0
B6	IO20RSB0
В7	IO21RSB0
B8	IO28RSB0
В9	IO25RSB0
C1	IO79RSB1
C2	IO80RSB1
C3	IO08RSB0
C4	IO12RSB0
C5	IO17RSB0
C6	IO14RSB0
C7	IO18RSB0
C8	IO29RSB0
C9	IO27RSB0
D1	IO74RSB1
D2	IO76RSB1
D3	IO77RSB1
D4	VCC
D5	VCCIB0
D6	GND
D7	IO23RSB0
D8	IO31RSB0

CS81	
AGLN030Z	
AGLN030Z Function	
IO30RSB0	
GEB0/IO71RSB1	
GEA0/IO72RSB1	
GEC0/IO73RSB1	
VCCIB1	
VCC	
VCCIB0	
GDC0/IO32RSB0	
GDA0/IO33RSB0	
GDB0/IO34RSB0	
IO68RSB1	
IO67RSB1	
IO64RSB1	
GND	
VCCIB1	
IO47RSB1	
IO36RSB0	
IO38RSB0	
IO40RSB0	
IO65RSB1	
IO66RSB1	
IO57RSB1	
IO53RSB1	
IO49RSB1	
IO44RSB1	
IO46RSB1	
VJTAG	
TRST	
IO62RSB1	
FF/IO60RSB1	
IO58RSB1	
IO54RSB1	
IO48RSB1	
IO43RSB1	
IO42RSB1	

CS81	
Pin Number	AGLN030Z Function
H8	TDI
H9	TDO
J1	IO63RSB1
J2	IO61RSB1
J3	IO59RSB1
J4	IO56RSB1
J5	IO52RSB1
J6	IO45RSB1
J7	TCK
J8	TMS
J9	VPUMP

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CS81	
Pin Number	AGLN060 Function
A1	GAA0/IO02RSB0
A2	GAA1/IO03RSB0
A3	GAC0/IO06RSB0
A4	IO09RSB0
A5	IO13RSB0
A6	IO18RSB0
A7	GBB0/IO21RSB0
A8	GBA1/IO24RSB0
A9	GBA2/IO25RSB0
B1	GAA2/IO95RSB1
B2	GAB0/IO04RSB0
В3	GAC1/IO07RSB0
B4	IO08RSB0
B5	IO15RSB0
B6	GBC0/IO19RSB0
B7	GBB1/IO22RSB0
B8	IO26RSB0
В9	GBB2/IO27RSB0
C1	GAB2/IO93RSB1
C2	IO94RSB1
C3	GND
C4	IO10RSB0
C5	IO17RSB0
C6	GND
C7	GBA0/IO23RSB0
C8	GBC2/IO29RSB0
C9	IO31RSB0
D1	GAC2/IO91RSB1
D2	IO92RSB1
D3	GFA2/IO80RSB1
D4	VCC
D5	VCCIB0
D6	GND
D7	GCC2/IO43RSB0

CS81	
Pin Number	AGLN060 Function
D8	GCC1/IO35RSB0
D9	GCC0/IO36RSB0
E1	GFB0/IO83RSB1
E2	GFB1/IO84RSB1
E3	GFA1/IO81RSB1
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	GCA1/IO39RSB0
E8	GCA0/IO40RSB0
E9	GCB2/IO42RSB0
F1 ¹	VCCPLF
F2 ¹	VCOMPLF
F3	GND
F4	GND
F5	VCCIB1
F6	GND
F7	GDA1/IO49RSB0
F8	GDC1/IO45RSB0
F9	GDC0/IO46RSB0
G1	GEA0/IO69RSB1
G2	GEC1/IO74RSB1
G3	GEB1/IO72RSB1
G4	IO63RSB1
G5	IO60RSB1
G6	IO54RSB1
G7	GDB2/IO52RSB1
G8	VJTAG
G9	TRST
H1	GEA1/IO70RSB1
H2	FF/GEB2/IO67RSB1
Н3	IO65RSB1
H4	IO62RSB1
H5	IO59RSB1

CS81	
Pin Number	AGLN060 Function
H6	IO56RSB1
H7 ²	GDA2/IO51RSB1
H8	TDI
H9	TDO
J1	GEA2/IO68RSB1
J2	GEC2/IO66RSB1
J3	IO64RSB1
J4	IO61RSB1
J5	IO58RSB1
J6	IO55RSB1
J7	TCK
J8	TMS
J9	VPUMP

Notes:

- 1. Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN060-CS81.
- 2. The bus hold attribute (hold previous I/O state in Flash*Freeze mode) is not supported for pin H7 in AGLN060-CS81.



Pin Number AGLN060Z Function A1 GAA0/IO02RSB0 A2 GAA1/IO03RSB0 A3 GACO/IO06RSB0 A4 IO09RSB0 A5 IO13RSB0 A6 IO18RSB0 A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C9 IO31RSB0 C9 IO31RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1	CS81	
A2 GAA1/IO03RSB0 A3 GAC0/IO06RSB0 A4 IO09RSB0 A5 IO13RSB0 A6 IO18RSB0 A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6	Pin Number	AGLN060Z Function
A3 GACO/IO06RSB0 A4 IO09RSB0 A5 IO13RSB0 A6 IO18RSB0 A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A1	GAA0/IO02RSB0
A4 IO09RSB0 A5 IO13RSB0 A6 IO18RSB0 A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A2	GAA1/IO03RSB0
A5 IO13RSB0 A6 IO18RSB0 A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A3	GAC0/IO06RSB0
A6 IO18RSB0 A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A4	IO09RSB0
A7 GBB0/IO21RSB0 A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A5	IO13RSB0
A8 GBA1/IO24RSB0 A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A6	IO18RSB0
A9 GBA2/IO25RSB0 B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A7	GBB0/IO21RSB0
B1 GAA2/IO95RSB1 B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A8	GBA1/IO24RSB0
B2 GAB0/IO04RSB0 B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	A9	GBA2/IO25RSB0
B3 GAC1/IO07RSB0 B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	B1	GAA2/IO95RSB1
B4 IO08RSB0 B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	B2	GAB0/IO04RSB0
B5 IO15RSB0 B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	В3	GAC1/IO07RSB0
B6 GBC0/IO19RSB0 B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	B4	IO08RSB0
B7 GBB1/IO22RSB0 B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	B5	IO15RSB0
B8 IO26RSB0 B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	В6	GBC0/IO19RSB0
B9 GBB2/IO27RSB0 C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	В7	GBB1/IO22RSB0
C1 GAB2/IO93RSB1 C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	B8	IO26RSB0
C2 IO94RSB1 C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	В9	GBB2/IO27RSB0
C3 GND C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C1	GAB2/IO93RSB1
C4 IO10RSB0 C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C2	IO94RSB1
C5 IO17RSB0 C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C3	GND
C6 GND C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C4	IO10RSB0
C7 GBA0/IO23RSB0 C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C5	IO17RSB0
C8 GBC2/IO29RSB0 C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C6	GND
C9 IO31RSB0 D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C7	GBA0/IO23RSB0
D1 GAC2/IO91RSB1 D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C8	GBC2/IO29RSB0
D2 IO92RSB1 D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	C9	IO31RSB0
D3 GFA2/IO80RSB1 D4 VCC D5 VCCIB0 D6 GND	D1	GAC2/IO91RSB1
D4 VCC D5 VCCIB0 D6 GND	D2	IO92RSB1
D5 VCCIB0 D6 GND	D3	GFA2/IO80RSB1
D6 GND	D4	VCC
	D5	VCCIB0
D7 GCC2/IO43RSB0	D6	GND
	D7	GCC2/IO43RSB0

CS81	
Pin Number	AGLN060Z Function
D8	GCC1/IO35RSB0
D9	GCC0/IO36RSB0
E1	GFB0/IO83RSB1
E2	GFB1/IO84RSB1
E3	GFA1/IO81RSB1
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	GCA1/IO39RSB0
E8	GCA0/IO40RSB0
E9	GCB2/IO42RSB0
F1 ¹	VCCPLF
F2 ¹	VCOMPLF
F3	GND
F4	GND
F5	VCCIB1
F6	GND
F7	GDA1/IO49RSB0
F8	GDC1/IO45RSB0
F9	GDC0/IO46RSB0
G1	GEA0/IO69RSB1
G2	GEC1/IO74RSB1
G3	GEB1/IO72RSB1
G4	IO63RSB1
G5	IO60RSB1
G6	IO54RSB1
G7	GDB2/IO52RSB1
G8	VJTAG
G9	TRST
H1	GEA1/IO70RSB1
H2	FF/GEB2/IO67RSB1
H3	IO65RSB1
H4	IO62RSB1
H5	IO59RSB1

CS81	
Pin Number	AGLN060Z Function
H6	IO56RSB1
H7 ²	GDA2/IO51RSB1
H8	TDI
H9	TDO
J1	GEA2/IO68RSB1
J2	GEC2/IO66RSB1
J3	IO64RSB1
J4	IO61RSB1
J5	IO58RSB1
J6	IO55RSB1
J7	TCK
J8	TMS
J9	VPUMP

Notes:

- 1. Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN060Z-CS81.
- 2. The bus hold attribute (hold previous I/O state in Flash*Freeze mode) is not supported for pin H7 in AGLN060Z-CS81.

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CS81	
Pin Number	AGLN125 Function
A1	GAA0/IO00RSB0
A2	GAA1/IO01RSB0
A3	GAC0/IO04RSB0
A4	IO13RSB0
A5	IO22RSB0
A6	IO32RSB0
A7	GBB0/IO37RSB0
A8	GBA1/IO40RSB0
A9	GBA2/IO41RSB0
B1	GAA2/IO132RSB1
B2	GAB0/IO02RSB0
В3	GAC1/IO05RSB0
B4	IO11RSB0
B5	IO25RSB0
В6	GBC0/IO35RSB0
В7	GBB1/IO38RSB0
В8	IO42RSB0
В9	GBB2/IO43RSB0
C1	GAB2/IO130RSB1
C2	IO131RSB1
C3	GND
C4	IO15RSB0
C5	IO28RSB0
C6	GND
C7	GBA0/IO39RSB0
C8	GBC2/IO45RSB0
C9	IO47RSB0
D1	GAC2/IO128RSB1
D2	IO129RSB1
D3	GFA2/IO117RSB1
D4	VCC
D5	VCCIB0
D6	GND
D7	GCC2/IO59RSB0
D8	GCC1/IO51RSB0
D9	GCC0/IO52RSB0

Pin Number AGLN125 Function E1 GFB0/IO120RSB1 E2 GFB1/IO121RSB1 E3 GFA1/IO118RSB1 E4 VCCIB1 E5 VCC E6 VCCIB0 E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST H1 GEA1/IO105RSB1		CS81
E2 GFB1/IO121RSB1 E3 GFA1/IO118RSB1 E4 VCCIB1 E5 VCC E6 VCCIB0 E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	Pin Number	AGLN125 Function
E3 GFA1/IO118RSB1 E4 VCCIB1 E5 VCC E6 VCCIB0 E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E1	GFB0/IO120RSB1
E4 VCCIB1 E5 VCC E6 VCCIB0 E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E2	GFB1/IO121RSB1
E5 VCC E6 VCCIB0 E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E3	GFA1/IO118RSB1
E6 VCCIB0 E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E4	VCCIB1
E7 GCA0/IO56RSB0 E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E5	VCC
E8 GCA1/IO55RSB0 E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E6	VCCIB0
E9 GCB2/IO58RSB0 F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E7	GCA0/IO56RSB0
F1* VCCPLF F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E8	GCA1/IO55RSB0
F2* VCOMPLF F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	E9	GCB2/IO58RSB0
F3 GND F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F1*	VCCPLF
F4 GND F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F2*	VCOMPLF
F5 VCCIB1 F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F3	GND
F6 GND F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F4	GND
F7 GDA1/IO65RSB0 F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F5	VCCIB1
F8 GDC1/IO61RSB0 F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F6	GND
F9 GDC0/IO62RSB0 G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F7	GDA1/IO65RSB0
G1 GEA0/IO104RSB1 G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F8	GDC1/IO61RSB0
G2 GEC0/IO108RSB1 G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	F9	GDC0/IO62RSB0
G3 GEB1/IO107RSB1 G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	G1	GEA0/IO104RSB1
G4 IO96RSB1 G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	G2	GEC0/IO108RSB1
G5 IO92RSB1 G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	G3	GEB1/IO107RSB1
G6 IO72RSB1 G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	G4	IO96RSB1
G7 GDB2/IO68RSB1 G8 VJTAG G9 TRST	G5	IO92RSB1
G8 VJTAG G9 TRST	G6	IO72RSB1
G9 TRST	G7	GDB2/IO68RSB1
	G8	VJTAG
H1 GEA1/IO105RSB1	G9	TRST
	H1	GEA1/IO105RSB1
H2 FF/GEB2/IO102RSB1	H2	FF/GEB2/IO102RSB1
H3 IO99RSB1	H3	IO99RSB1
H4 IO94RSB1	H4	IO94RSB1
H5 IO91RSB1	H5	IO91RSB1
H6 IO81RSB1	H6	IO81RSB1
H7 GDA2/IO67RSB1	H7	GDA2/IO67RSB1
H8 TDI	H8	TDI
H9 TDO	H9	TDO

CS81	
Pin Number	AGLN125 Function
J1	GEA2/IO103RSB1
J2	GEC2/IO101RSB1
J3	IO97RSB1
J4	IO93RSB1
J5	IO90RSB1
J6	IO78RSB1
J7	TCK
J8	TMS
J9	VPUMP

Note: * Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN125-CS81.



	CS8	
Pin Number AGLN125Z Function		
A1	GAA0/IO00RSB0	
A2	GAA1/IO01RSB0	
A3	GAC0/IO04RSB0	
A4	IO13RSB0	
A5	IO22RSB0	
A6	IO32RSB0	
A7	GBB0/IO37RSB0	
A8	GBA1/IO40RSB0	
A9	GBA2/IO41RSB0	
B1	GAA2/IO132RSB1	
B2	GAB0/IO02RSB0	
В3	GAC1/IO05RSB0	
B4	IO11RSB0	
B5	IO25RSB0	
B6	GBC0/IO35RSB0	
B7	GBB1/IO38RSB0	
B8	IO42RSB0	
В9	GBB2/IO43RSB0	
C1	GAB2/IO130RSB1	
C2	IO131RSB1	
C3	GND	
C4	IO15RSB0	
C5	IO28RSB0	
C6	GND	
C7	GBA0/IO39RSB0	
C8	GBC2/IO45RSB0	
C9	IO47RSB0	
D1	GAC2/IO128RSB1	
D2	IO129RSB1	
D3	GFA2/IO117RSB1	
D4	VCC	
D5	VCCIB0	
D6	GND	
D7	GCC2/IO59RSB0	
D8	GCC1/IO51RSB0	
D9	GCC0/IO52RSB0	

	CS8
Pin Number	AGLN125Z Function
E1	GFB0/IO120RSB1
E2	GFB1/IO121RSB1
E3	GFA1/IO118RSB1
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	GCA0/IO56RSB0
E8	GCA1/IO55RSB0
E9	GCB2/IO58RSB0
F1*	VCCPLF
F2*	VCOMPLF
F3	GND
F4	GND
F5	VCCIB1
F6	GND
F7	GDA1/IO65RSB0
F8	GDC1/IO61RSB0
F9	GDC0/IO62RSB0
G1	GEA0/IO104RSB1
G2	GEC0/IO108RSB1
G3	GEB1/IO107RSB1
G4	IO96RSB1
G5	IO92RSB1
G6	IO72RSB1
G7	GDB2/IO68RSB1
G8	VJTAG
G9	TRST
H1	GEA1/IO105RSB1
H2	FF/GEB2/IO102RSB1
НЗ	IO99RSB1
H4	IO94RSB1
H5	IO91RSB1
H6	IO81RSB1
H7	GDA2/IO67RSB1
H8	TDI
H9	TDO

CS8	
Pin Number	AGLN125Z Function
J1	GEA2/IO103RSB1
J2	GEC2/IO101RSB1
J3	IO97RSB1
J4	IO93RSB1
J5	IO90RSB1
J6	IO78RSB1
J7	TCK
J8	TMS
J9	VPUMP

Note: * Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN125Z-CS81.

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	CS81
Pin Number	AGLN250 Function
A1	GAA0/IO00RSB0
A2	GAA1/IO01RSB0
A3	GAC0/IO04RSB0
A4	IO13RSB0
A5	IO21RSB0
A6	IO27RSB0
A7	GBB0/IO37RSB0
A8	GBA1/IO40RSB0
A9	GBA2/IO41PPB1
B1	GAA2/IO118UPB3
B2	GAB0/IO02RSB0
В3	GAC1/IO05RSB0
B4	IO11RSB0
B5	IO23RSB0
В6	GBC0/IO35RSB0
В7	GBB1/IO38RSB0
B8	IO41NPB1
В9	GBB2/IO42PSB1
C1	GAB2/IO117UPB3
C2	IO118VPB3
C3	GND
C4	IO15RSB0
C5	IO25RSB0
C6	GND
C7	GBA0/IO39RSB0
C8	GBC2/IO43B1
C9	IO43NDB1
D1	GAC2/IO116USB3
D2	IO117VPB3
D3	GFA2/IO107PSB3
D4	VCC
D5	VCCIB0
D6	GND
D7	IO52NPB1
D8	GCC1/IO48PDB1
D9	GCC0/IO48NDB1

CS81	
Pin Number	AGLN250 Function
E1	GFB0/IO109NDB3
E2	GFB1/IO109PDB3
E3	GFA1/IO108PSB3
E4	VCCIB3
E5	VCC
E6	VCCIB1
E7	GCA0/IO50NDB1
E8	GCA1/IO50PDB1
E9	GCB2/IO52PPB1
F1*	VCCPLF
F2*	VCOMPLF
F3	GND
F4	GND
F5	VCCIB2
F6	GND
F7	GDA1/IO60USB1
F8	GDC1/IO58UDB1
F9	GDC0/IO58VDB1
G1	GEA0/IO98NDB3
G2	GEC1/IO100PDB3
G3	GEC0/IO100NDB3
G4	IO91RSB2
G5	IO86RSB2
G6	IO71RSB2
G7	GDB2/IO62RSB2
G8	VJTAG
G9	TRST
H1	GEA1/IO98PDB3
H2	FF/GEB2/IO96RSB2
H3	IO93RSB2
H4	IO90RSB2
H5	IO85RSB2
H6	IO77RSB2
H7	GDA2/IO61RSB2
H8	TDI
H9	TDO

	CS81	
Pin Number	AGLN250 Function	
J1	GEA2/IO97RSB2	
J2	GEC2/IO95RSB2	
J3	IO92RSB2	
J4	IO88RSB2	
J5	IO84RSB2	
J6	IO74RSB2	
J7	TCK	
J8	TMS	
J9	VPUMP	

Note: * Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN250-CS81.



CS81	
Pin Number	AGLN250Z Function
A1	GAA0/IO00RSB0
A2	GAA1/IO01RSB0
A3	GAC0/IO04RSB0
A4	IO07RSB0
A5	IO09RSB0
A6	IO12RSB0
A7	GBB0/IO16RSB0
A8	GBA1/IO19RSB0
A9	GBA2/IO20RSB1
B1	GAA2/IO67RSB3
B2	GAB0/IO02RSB0
В3	GAC1/IO05RSB0
B4	IO06RSB0
B5	IO10RSB0
В6	GBC0/IO14RSB0
В7	GBB1/IO17RSB0
B8	IO21RSB1
В9	GBB2/IO22RSB1
C1	GAB2/IO65RSB3
C2	IO66RSB3
C3	GND
C4	IO08RSB0
C5	IO11RSB0
C6	GND
C7	GBA0/IO18RSB0
C8	GBC2/IO23RSB1
C9	IO24RSB1
D1	GAC2/IO63RSB3
D2	IO64RSB3
D3	GFA2/IO56RSB3
D4	VCC
D5	VCCIB0
D6	GND
D7	IO30RSB1
D8	GCC1/IO25RSB1
D9	GCC0/IO26RSB1

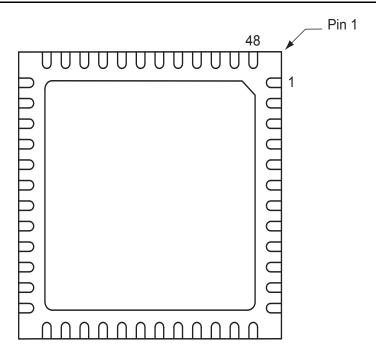
CS81	
Pin Number AGLN250Z Functio	
E1	GFB0/IO59RSB3
E2	GFB1/IO60RSB3
E3	GFA1/IO58RSB3
E4	VCCIB3
E5	VCC
E6	VCCIB1
E7	GCA0/IO28RSB1
E8	GCA1/IO27RSB1
E9	GCB2/IO29RSB1
F1*	VCCPLF
F2*	VCOMPLF
F3	GND
F4	GND
F5	VCCIB2
F6	GND
F7	GDA1/IO33RSB1
F8	GDC1/IO31RSB1
F9	GDC0/IO32RSB1
G1	GEA0/IO51RSB3
G2	GEC1/IO54RSB3
G3	GEC0/IO53RSB3
G4	IO45RSB2
G5	IO42RSB2
G6	IO37RSB2
G7	GDB2/IO35RSB2
G8	VJTAG
G9	TRST
H1	GEA1/IO52RSB3
H2	FF/GEB2/IO49RSB2
H3	IO47RSB2
H4	IO44RSB2
H5	IO41RSB2
H6	IO39RSB2
H7	GDA2/IO34RSB2
H8	TDI
H9	TDO

CS81	
Pin Number	AGLN250Z Function
J1	GEA2/IO50RSB2
J2	GEC2/IO48RSB2
J3	IO46RSB2
J4	IO43RSB2
J5	IO40RSB2
J6	IO38RSB2
J7	TCK
J8	TMS
J9	VPUMP

Note: * Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN250Z-CS81.

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QN48



Notes:

- 1. This is the bottom view of the package.
- 2. The die attach paddle of the package is tied to ground (GND).

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.



(QN48	
Pin Number	AGLN010 Function	
1	GEC0/IO37RSB1	
2	IO36RSB1	
3	GEA0/IO34RSB1	
4	IO22RSB1	
5	GND	
6	VCCIB1	
7	IO24RSB1	
8	IO33RSB1	
9	IO26RSB1	
10	IO32RSB1	
11	IO27RSB1	
12	IO29RSB1	
13	IO30RSB1	
14	FF/IO31RSB1	
15	IO28RSB1	
16	IO25RSB1	
17	IO23RSB1	
18	VCC	
19	VCCIB1	
20	IO17RSB1	
21	IO14RSB1	
22	TCK	
23	TDI	
24	TMS	
25	VPUMP	
26	TDO	
27	TRST	
28	VJTAG	
29	IO11RSB0	
30	IO10RSB0	
31	IO09RSB0	
32	IO08RSB0	
33	VCCIB0	
34	GND	
35	VCC	

	QN48
Pin Number	AGLN010 Function
36	IO07RSB0
37	IO06RSB0
38	GDA0/IO05RSB0
39	IO03RSB0
40	GDC0/IO01RSB0
41	IO12RSB1
42	IO13RSB1
43	IO15RSB1
44	IO16RSB1
45	IO18RSB1
46	IO19RSB1
47	IO20RSB1
48	IO21RSB1

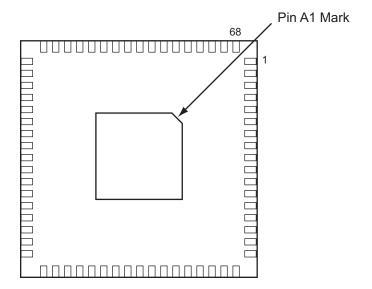
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	QN48		
Pin Number AGLN030Z Function			
1	IO82RSB1		
2	GEC0/IO73RSB1		
3	GEA0/IO72RSB1		
4	GEB0/IO71RSB1		
5	GND		
6	VCCIB1		
7	IO68RSB1		
8	IO67RSB1		
9	IO66RSB1		
10	IO65RSB1		
11	IO64RSB1		
12	IO62RSB1		
13	IO61RSB1		
14	FF/IO60RSB1		
15	IO57RSB1		
16	IO55RSB1		
17	IO53RSB1		
18	VCC		
19	VCCIB1		
20	IO46RSB1		
21	IO42RSB1		
22	TCK		
23	TDI		
24	TMS		
25	VPUMP		
26	TDO		
27	TRST		
28	VJTAG		
29	IO38RSB0		
30	GDB0/IO34RSB0		
31	GDA0/IO33RSB0		
32	GDC0/IO32RSB0		
33	VCCIB0		
34	GND		
35	VCC		
36	IO25RSB0		
	.020.1020		

QN48		
Pin Number	AGLN030Z Function	
37	IO24RSB0	
38	IO22RSB0	
39	IO20RSB0	
40	IO18RSB0	
41	IO16RSB0	
42	IO14RSB0	
43	IO10RSB0	
44	IO08RSB0	
45	IO06RSB0	
46	IO04RSB0	
47	IO02RSB0	
48	IO00RSB0	

QN68



Notes:

- 1. This is the bottom view of the package.
- 2. The die attach paddle of the package is tied to ground (GND).

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

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QN68		
AGLN015		
Pin Number	Function	
1	IO60RSB2	
2	IO54RSB2	
3	IO52RSB2	
4	IO50RSB2	
5	IO49RSB2	
6	GEC0/IO48RSB2	
7	GEA0/IO47RSB2	
8	VCC	
9	GND	
10	VCCIB2	
11	IO46RSB2	
12	IO45RSB2	
13	IO44RSB2	
14	IO43RSB2	
15	IO42RSB2	
16	IO41RSB2	
17	IO40RSB2	
18	FF/IO39RSB1	
19	IO37RSB1	
20	IO35RSB1	
21	IO33RSB1	
22	IO31RSB1	
23	IO30RSB1	
24	VCC	
25	GND	
26	VCCIB1	
27	IO27RSB1	
28	IO25RSB1	
29	IO23RSB1	
30	IO21RSB1	
31	IO19RSB1	
32	TCK	
33	TDI	
34	TMS	
35	VPUMP	

QN68		
Pin Number	AGLN015 Function	
36	TDO	
37	TRST	
38	VJTAG	
39	IO17RSB0	
40	IO16RSB0	
41	GDA0/IO15RSB0	
42	GDC0/IO14RSB0	
43	IO13RSB0	
44	VCCIB0	
45	GND	
46	VCC	
47	IO12RSB0	
48	IO11RSB0	
49	IO09RSB0	
50	IO05RSB0	
51	IO00RSB0	
52	IO07RSB0	
53	IO03RSB0	
54	IO18RSB1	
55	IO20RSB1	
56	IO22RSB1	
57	IO24RSB1	
58	IO28RSB1	
59	NC	
60	GND	
61	NC	
62	IO32RSB1	
63	IO34RSB1	
64	IO36RSB1	
65	IO61RSB2	
66	IO58RSB2	
67	IO56RSB2	
68	IO63RSB2	



QN68		
AGLN020		
Pin Number	Function	
1	IO60RSB2	
2	IO54RSB2	
3	IO52RSB2	
4	IO50RSB2	
5	IO49RSB2	
6	GEC0/IO48RSB2	
7	GEA0/IO47RSB2	
8	VCC	
9	GND	
10	VCCIB2	
11	IO46RSB2	
12	IO45RSB2	
13	IO44RSB2	
14	IO43RSB2	
15	IO42RSB2	
16	IO41RSB2	
17	IO40RSB2	
18	FF/IO39RSB1	
19	IO37RSB1	
20	IO35RSB1	
21	IO33RSB1	
22	IO31RSB1	
23	IO30RSB1	
24	VCC	
25	GND	
26	VCCIB1	
27	IO27RSB1	
28	IO25RSB1	
29	IO23RSB1	
30	IO21RSB1	
31	IO19RSB1	
32	TCK	
33	TDI	
34	TMS	
35	VPUMP	

QN68		
Pin Number	AGLN020 Function	
36	TDO	
37	TRST	
38	VJTAG	
39	IO17RSB0	
40	IO16RSB0	
41	GDA0/IO15RSB0	
42	GDC0/IO14RSB0	
43	IO13RSB0	
44	VCCIB0	
45	GND	
46	VCC	
47	IO12RSB0	
48	IO11RSB0	
49	IO09RSB0	
50	IO05RSB0	
51	IO00RSB0	
52	IO07RSB0	
53	IO03RSB0	
54	IO18RSB1	
55	IO20RSB1	
56	IO22RSB1	
57	IO24RSB1	
58	IO28RSB1	
59	NC	
60	GND	
61	NC	
62	IO32RSB1	
63	IO34RSB1	
64	IO36RSB1	
65	IO61RSB2	
66	IO58RSB2	
67	IO56RSB2	
68	IO63RSB2	
68	IO63RSB2	

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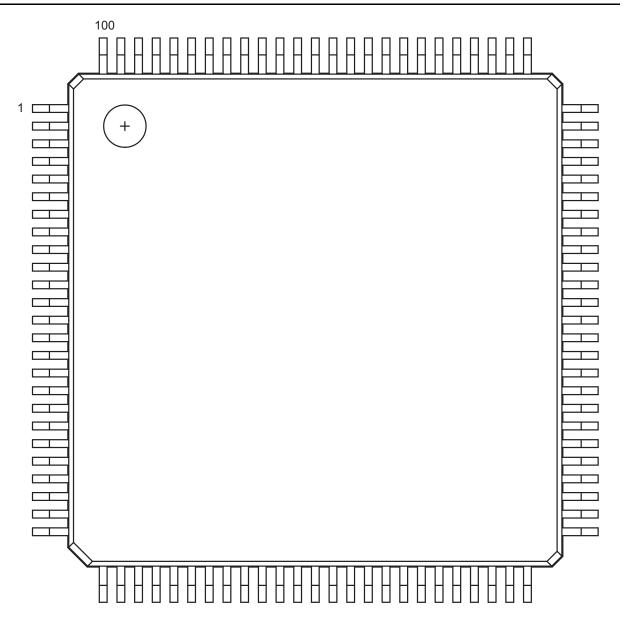


QN68		
	AGLN030Z	
Pin Number	Function	
1	IO82RSB1	
2	IO80RSB1	
3	IO78RSB1	
4	IO76RSB1	
5	GEC0/IO73RSB1	
6	GEA0/IO72RSB1	
7	GEB0/IO71RSB1	
8	VCC	
9	GND	
10	VCCIB1	
11	IO68RSB1	
12	IO67RSB1	
13	IO66RSB1	
14	IO65RSB1	
15	IO64RSB1	
16	IO63RSB1	
17	IO62RSB1	
18	FF/IO60RSB1	
19	IO58RSB1	
20	IO56RSB1	
21	IO54RSB1	
22	IO52RSB1	
23	IO51RSB1	
24	VCC	
25	GND	
26	VCCIB1	
27	IO50RSB1	
28	IO48RSB1	
29	IO46RSB1	
30	IO44RSB1	
31	IO42RSB1	
32	TCK	
33	TDI	
34	TMS	
35	VPUMP	

QN68		
AGLN030Z		
Pin Number	Function	
36	TDO	
37	TRST	
38	VJTAG	
39	IO40RSB0	
40	IO37RSB0	
41	GDB0/IO34RSB0	
42	GDA0/IO33RSB0	
43	GDC0/IO32RSB0	
44	VCCIB0	
45	GND	
46	VCC	
47	IO31RSB0	
48	IO29RSB0	
49	IO28RSB0	
50	IO27RSB0	
51	IO25RSB0	
52	IO24RSB0	
53	IO22RSB0	
54	IO21RSB0	
55	IO19RSB0	
56	IO17RSB0	
57	IO15RSB0	
58	IO14RSB0	
59	VCCIB0	
60	GND	
61	VCC	
62	IO12RSB0	
63	IO10RSB0	
64	IO08RSB0	
65	IO06RSB0	
66	IO04RSB0	
67	IO02RSB0	
68	IO00RSB0	



VQ100



Note: This is the top view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/soc/products/solutions/package/docs.aspx.

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VQ100		
	AGLN030Z	
Pin Number	Function	
1	GND	
2	IO82RSB1	
3	IO81RSB1	
4	IO80RSB1	
5	IO79RSB1	
6	IO78RSB1	
7	IO77RSB1	
8	IO76RSB1	
9	GND	
10	IO75RSB1	
11	IO74RSB1	
12	GEC0/IO73RSB1	
13	GEA0/IO72RSB1	
14	GEB0/IO71RSB1	
15	IO70RSB1	
16	IO69RSB1	
17	VCC	
18	VCCIB1	
19	IO68RSB1	
20	IO67RSB1	
21	IO66RSB1	
22	IO65RSB1	
23	IO64RSB1	
24	IO63RSB1	
25	IO62RSB1	
26	IO61RSB1	
27	FF/IO60RSB1	
28	IO59RSB1	
29	IO58RSB1	
30	IO57RSB1	
31	IO56RSB1	
32	IO55RSB1	
33	IO54RSB1	
34	IO53RSB1	
35	IO52RSB1	

V0400			
VQ100			
Pin Number	AGLN030Z Function		
36	IO51RSB1		
37	VCC		
38	GND		
39	VCCIB1		
40	IO49RSB1		
41	IO47RSB1		
42	IO46RSB1		
43	IO45RSB1		
44	IO44RSB1		
45	IO43RSB1		
46	IO42RSB1		
47	TCK		
48	TDI		
49	TMS		
50	NC		
51	GND		
52	VPUMP		
53	NC		
54	TDO		
55	TRST		
56	VJTAG		
57	IO41RSB0		
58	IO40RSB0		
59	IO39RSB0		
60	IO38RSB0		
61	IO37RSB0		
62	IO36RSB0		
63	GDB0/IO34RSB0		
64	GDA0/IO33RSB0		
65	GDC0/IO32RSB0		
66	VCCIB0		
67	GND		
68	VCC		
69	IO31RSB0		
70	IO30RSB0		

VQ100				
AGLN030Z				
Pin Number	Function			
71	IO29RSB0			
72	IO28RSB0			
73	IO27RSB0			
74	IO26RSB0			
75	IO25RSB0			
76	IO24RSB0			
77	IO23RSB0			
78	IO22RSB0			
79	IO21RSB0			
80	IO20RSB0			
81	IO19RSB0			
82	IO18RSB0			
83	IO17RSB0			
84	IO16RSB0			
85	IO15RSB0			
86	IO14RSB0			
87	VCCIB0			
88	GND			
89	VCC			
90	IO12RSB0			
91	IO10RSB0			
92	IO08RSB0			
93	IO07RSB0			
94	IO06RSB0			
95	IO05RSB0			
96	IO04RSB0			
97	IO03RSB0			
98	IO02RSB0			
99	IO01RSB0			
100	IO00RSB0			



VQ100		VQ100		
Pin Number	AGLN060 Function	Pin Number	AGLN060 Function	
1	GND	36	IO61RSB1	
2	GAA2/IO51RSB1	37	VCC	
3	IO52RSB1	38	GND	
4	GAB2/IO53RSB1	39	VCCIB1	
5	IO95RSB1	40	IO60RSB1	
6	GAC2/IO94RSB1	41	IO59RSB1	
7	IO93RSB1	42	IO58RSB1	
8	IO92RSB1	43	IO57RSB1	
9	GND	44	GDC2/IO56RSB1	
10	GFB1/IO87RSB1	45*	GDB2/IO55RSB1	
11	GFB0/IO86RSB1	46	GDA2/IO54RSB1	
12	VCOMPLF	47	TCK	
13	GFA0/IO85RSB1	48	TDI	
14	VCCPLF	49	TMS	
15	GFA1/IO84RSB1	50	VMV1	
16	GFA2/IO83RSB1	51	GND	
17	VCC	52	VPUMP	
18	VCCIB1	53	NC	
19	GEC1/IO77RSB1	54	TDO	
20	GEB1/IO75RSB1	55	TRST	
21	GEB0/IO74RSB1	56	VJTAG	
22	GEA1/IO73RSB1	57	GDA1/IO49RSB0	
23	GEA0/IO72RSB1	58	GDC0/IO46RSB0	
24	VMV1	59	GDC1/IO45RSB0	
25	GNDQ	60	GCC2/IO43RSB0	
26	GEA2/IO71RSB1	61	GCB2/IO42RSB0	
27	FF/GEB2/IO70RSB1	62	GCA0/IO40RSB0	
28	GEC2/IO69RSB1	63	GCA1/IO39RSB0	
29	IO68RSB1	64	GCC0/IO36RSB0	
30	IO67RSB1	65	GCC1/IO35RSB0	
31	IO66RSB1	66	VCCIB0	
32	IO65RSB1	67	GND	
33	IO64RSB1	68	VCC	
34	IO63RSB1	69	IO31RSB0	
35	IO62RSB1	70	GBC2/IO29RSB0	

	VQ100
Pin Number	AGLN060 Function
71	GBB2/IO27RSB0
72	IO26RSB0
73	GBA2/IO25RSB0
74	VMV0
75	GNDQ
76	GBA1/IO24RSB0
77	GBA0/IO23RSB0
78	GBB1/IO22RSB0
79	GBB0/IO21RSB0
80	GBC1/IO20RSB0
81	GBC0/IO19RSB0
82	IO18RSB0
83	IO17RSB0
84	IO15RSB0
85	IO13RSB0
86	IO11RSB0
87	VCCIB0
88	GND
89	VCC
90	IO10RSB0
91	IO09RSB0
92	IO08RSB0
93	GAC1/IO07RSB0
94	GAC0/IO06RSB0
95	GAB1/IO05RSB0
96	GAB0/IO04RSB0
97	GAA1/IO03RSB0
98	GAA0/IO02RSB0
99	IO01RSB0
100	IO00RSB0

Note: *The bus hold attribute (hold previous I/O state in Flash*Freeze mode) is not supported for pin 45 in AGLN060-VQ100.

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Pin Number AGLN060Z Function 1 GND 2 GAA2/IO51RSB1 3 IO52RSB1 4 GAB2/IO53RSB1 5 IO95RSB1 6 GAC2/IO94RSB1 7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 30 IO66RSB1 31	VQ100	
2 GAA2/IO51RSB1 3 IO52RSB1 4 GAB2/IO53RSB1 5 IO95RSB1 6 GAC2/IO94RSB1 7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	Pin Number	AGLN060Z Function
3 IO52RSB1 4 GAB2/IO53RSB1 5 IO95RSB1 6 GAC2/IO94RSB1 7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	1	GND
4 GAB2/IO53RSB1 5 IO95RSB1 6 GAC2/IO94RSB1 7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	2	GAA2/IO51RSB1
5 IO95RSB1 6 GAC2/IO94RSB1 7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1	3	IO52RSB1
6 GAC2/IO94RSB1 7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1	4	GAB2/IO53RSB1
7 IO93RSB1 8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1 31 IO66RSB1 31 IO66RSB1 31 IO66RSB1 31 IO66RSB1 30 IO67RSB1 30 IO67RSB1 30 IO67RSB1 31 IO66RSB1 30 IO67RSB1 30 IO67RSB1 30 IO66RSB1 30	5	IO95RSB1
8 IO92RSB1 9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1	6	GAC2/IO94RSB1
9 GND 10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1	7	IO93RSB1
10 GFB1/IO87RSB1 11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1	8	IO92RSB1
11 GFB0/IO86RSB1 12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1	9	GND
12 VCOMPLF 13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	10	GFB1/IO87RSB1
13 GFA0/IO85RSB1 14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	11	GFB0/IO86RSB1
14 VCCPLF 15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	12	VCOMPLF
15 GFA1/IO84RSB1 16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	13	GFA0/IO85RSB1
16 GFA2/IO83RSB1 17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	14	VCCPLF
17 VCC 18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	15	GFA1/IO84RSB1
18 VCCIB1 19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	16	GFA2/IO83RSB1
19 GEC1/IO77RSB1 20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	17	VCC
20 GEB1/IO75RSB1 21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	18	VCCIB1
21 GEB0/IO74RSB1 22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	19	GEC1/IO77RSB1
22 GEA1/IO73RSB1 23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	20	GEB1/IO75RSB1
23 GEA0/IO72RSB1 24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	21	GEB0/IO74RSB1
24 VMV1 25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	22	GEA1/IO73RSB1
25 GNDQ 26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	23	GEA0/IO72RSB1
26 GEA2/IO71RSB1 27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	24	VMV1
27 FF/GEB2/IO70RSB1 28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	25	GNDQ
28 GEC2/IO69RSB1 29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	26	GEA2/IO71RSB1
29 IO68RSB1 30 IO67RSB1 31 IO66RSB1	27	FF/GEB2/IO70RSB1
30 IO67RSB1 31 IO66RSB1	28	GEC2/IO69RSB1
31 IO66RSB1	29	IO68RSB1
	30	IO67RSB1
32 IO65RSB1	31	IO66RSB1
	32	IO65RSB1
33 IO64RSB1	33	IO64RSB1
34 IO63RSB1	34	IO63RSB1

	VQ100
Pin Number	-
35	IO62RSB1
36	IO61RSB1
37	VCC
38	GND
39	VCCIB1
40	IO60RSB1
41	IO59RSB1
42	IO58RSB1
43	IO57RSB1
44	GDC2/IO56RSB1
45*	GDB2/IO55RSB1
46	GDA2/IO54RSB1
47	TCK
48	TDI
49	TMS
50	VMV1
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO49RSB0
58	GDC0/IO46RSB0
59	GDC1/IO45RSB0
60	GCC2/IO43RSB0
61	GCB2/IO42RSB0
62	GCA0/IO40RSB0
63	GCA1/IO39RSB0
64	GCC0/IO36RSB0
65	GCC1/IO35RSB0
66	VCCIB0
67	GND
68	VCC

VQ100 Pin Number AGLN060Z Function 69 IO31RSB0 70 GBC2/IO29RSB0 71 GBB2/IO27RSB0 72 IO26RSB0 73 GBA2/IO25RSB0 74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 79 GBB0/IO23RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO03RSB0 96 GAB0/IO02RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0		
69 IO31RSB0 70 GBC2/IO29RSB0 71 GBB2/IO27RSB0 72 IO26RSB0 73 GBA2/IO25RSB0 74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO03RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 <t< th=""><th></th><th>VQ100</th></t<>		VQ100
70 GBC2/IO29RSB0 71 GBB2/IO27RSB0 72 IO26RSB0 73 GBA2/IO25RSB0 74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 91 IO09RSB0 92 GAB0/IO04RSB0 94 GACO/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	Pin Number	AGLN060Z Function
71 GBB2/IO27RSB0 72 IO26RSB0 73 GBA2/IO25RSB0 74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	69	IO31RSB0
72 IO26RSB0 73 GBA2/IO25RSB0 74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 91 IO09RSB0 91 GAC0/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	70	GBC2/IO29RSB0
73 GBA2/IO25RSB0 74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	71	GBB2/IO27RSB0
74 VMV0 75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	72	IO26RSB0
75 GNDQ 76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	73	GBA2/IO25RSB0
76 GBA1/IO24RSB0 77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	74	VMV0
77 GBA0/IO23RSB0 78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	75	GNDQ
78 GBB1/IO22RSB0 79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 91 IO09RSB0 92 IO8RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	76	GBA1/IO24RSB0
79 GBB0/IO21RSB0 80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	77	GBA0/IO23RSB0
80 GBC1/IO20RSB0 81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	78	GBB1/IO22RSB0
81 GBC0/IO19RSB0 82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	79	GBB0/IO21RSB0
82 IO18RSB0 83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	80	GBC1/IO20RSB0
83 IO17RSB0 84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0	81	GBC0/IO19RSB0
84 IO15RSB0 85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	82	IO18RSB0
85 IO13RSB0 86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	83	IO17RSB0
86 IO11RSB0 87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	84	IO15RSB0
87 VCCIB0 88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	85	IO13RSB0
88 GND 89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	86	IO11RSB0
89 VCC 90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	87	VCCIB0
90 IO10RSB0 91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	88	GND
91 IO09RSB0 92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	89	VCC
92 IO08RSB0 93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	90	IO10RSB0
93 GAC1/IO07RSB0 94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	91	IO09RSB0
94 GAC0/IO06RSB0 95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	92	IO08RSB0
95 GAB1/IO05RSB0 96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	93	GAC1/IO07RSB0
96 GAB0/IO04RSB0 97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	94	GAC0/IO06RSB0
97 GAA1/IO03RSB0 98 GAA0/IO02RSB0 99 IO01RSB0	95	GAB1/IO05RSB0
98 GAA0/IO02RSB0 99 IO01RSB0	96	GAB0/IO04RSB0
99 IO01RSB0	97	GAA1/IO03RSB0
	98	GAA0/IO02RSB0
100 IO00RSB0	99	IO01RSB0
	100	IO00RSB0

Note: *The bus hold attribute (hold previous I/O state in Flash*Freeze mode) is not supported for pin 45 in AGLN060Z-VQ100.



VQ100	
Pin Number	AGLN125 Function
1	GND
2	GAA2/IO67RSB1
3	IO68RSB1
4	GAB2/IO69RSB1
5	IO132RSB1
6	GAC2/IO131RSB1
7	IO130RSB1
8	IO129RSB1
9	GND
10	GFB1/IO124RSB1
11	GFB0/IO123RSB1
12	VCOMPLF
13	GFA0/IO122RSB1
14	VCCPLF
15	GFA1/IO121RSB1
16	GFA2/IO120RSB1
17	VCC
18	VCCIB1
19	GEC0/IO111RSB1
20	GEB1/IO110RSB1
21	GEB0/IO109RSB1
22	GEA1/IO108RSB1
23	GEA0/IO107RSB1
24	VMV1
25	GNDQ
26	GEA2/IO106RSB1
27	FF/GEB2/IO105RSB1
28	GEC2/IO104RSB1
29	IO102RSB1
30	IO100RSB1
31	IO99RSB1
32	IO97RSB1
33	IO96RSB1
34	IO95RSB1
35	IO94RSB1
36	IO93RSB1

	VQ100
Pin Number	AGLN125 Function
37	VCC
38	GND
39	VCCIB1
40	IO87RSB1
41	IO84RSB1
42	IO81RSB1
43	IO75RSB1
44	GDC2/IO72RSB1
45	GDB2/IO71RSB1
46	GDA2/IO70RSB1
47	TCK
48	TDI
49	TMS
50	VMV1
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO65RSB0
58	GDC0/IO62RSB0
59	GDC1/IO61RSB0
60	GCC2/IO59RSB0
61	GCB2/IO58RSB0
62	GCA0/IO56RSB0
63	GCA1/IO55RSB0
64	GCC0/IO52RSB0
65	GCC1/IO51RSB0
66	VCCIB0
67	GND
68	VCC
69	IO47RSB0
70	GBC2/IO45RSB0
71	GBB2/IO43RSB0
72	IO42RSB0
L	

VQ100	
Pin Number	AGLN125 Function
73	GBA2/IO41RSB0
74	VMV0
75	GNDQ
76	GBA1/IO40RSB0
77	GBA0/IO39RSB0
78	GBB1/IO38RSB0
79	GBB0/IO37RSB0
80	GBC1/IO36RSB0
81	GBC0/IO35RSB0
82	IO32RSB0
83	IO28RSB0
84	IO25RSB0
85	IO22RSB0
86	IO19RSB0
87	VCCIB0
88	GND
89	VCC
90	IO15RSB0
91	IO13RSB0
92	IO11RSB0
93	IO09RSB0
94	IO07RSB0
95	GAC1/IO05RSB0
96	GAC0/IO04RSB0
97	GAB1/IO03RSB0
98	GAB0/IO02RSB0
99	GAA1/IO01RSB0
100	GAA0/IO00RSB0

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	VQ100	
Pin Number	AGLN125Z Function	
1	GND	
2	GAA2/IO67RSB1	
3	IO68RSB1	
4	GAB2/IO69RSB1	
5	IO132RSB1	
6	GAC2/IO131RSB1	
7	IO130RSB1	
8	IO129RSB1	
9	GND	
10	GFB1/IO124RSB1	
11	GFB0/IO123RSB1	
12	VCOMPLF	
13	GFA0/IO122RSB1	
14	VCCPLF	
15	GFA1/IO121RSB1	
16	GFA2/IO120RSB1	
17	VCC	
18	VCCIB1	
19	GEC0/IO111RSB1	
20	GEB1/IO110RSB1	
21	GEB0/IO109RSB1	
22	GEA1/IO108RSB1	
23	GEA0/IO107RSB1	
24	VMV1	
25	GNDQ	
26	GEA2/IO106RSB1	
27	FF/GEB2/IO105RSB1	
28	GEC2/IO104RSB1	
29	IO102RSB1	
30	IO100RSB1	
31	IO99RSB1	
32	IO97RSB1	
33	IO96RSB1	
34	IO95RSB1	
35	IO94RSB1	

	V0400
	VQ100
Pin Number	AGLN125Z Function
36	IO93RSB1
37	VCC
38	GND
39	VCCIB1
40	IO87RSB1
41	IO84RSB1
42	IO81RSB1
43	IO75RSB1
44	GDC2/IO72RSB1
45	GDB2/IO71RSB1
46	GDA2/IO70RSB1
47	TCK
48	TDI
49	TMS
50	VMV1
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO65RSB0
58	GDC0/IO62RSB0
59	GDC1/IO61RSB0
60	GCC2/IO59RSB0
61	GCB2/IO58RSB0
62	GCA0/IO56RSB0
63	GCA1/IO55RSB0
64	GCC0/IO52RSB0
65	GCC1/IO51RSB0
66	VCCIB0
67	GND
68	VCC
69	IO47RSB0
70	GBC2/IO45RSB0

	VQ100
Pin	
Number	AGLN125Z Function
71	GBB2/IO43RSB0
72	IO42RSB0
73	GBA2/IO41RSB0
74	VMV0
75	GNDQ
76	GBA1/IO40RSB0
77	GBA0/IO39RSB0
78	GBB1/IO38RSB0
79	GBB0/IO37RSB0
80	GBC1/IO36RSB0
81	GBC0/IO35RSB0
82	IO32RSB0
83	IO28RSB0
84	IO25RSB0
85	IO22RSB0
86	IO19RSB0
87	VCCIB0
88	GND
89	VCC
90	IO15RSB0
91	IO13RSB0
92	IO11RSB0
93	IO09RSB0
94	IO07RSB0
95	GAC1/IO05RSB0
96	GAC0/IO04RSB0
97	GAB1/IO03RSB0
98	GAB0/IO02RSB0
99	GAA1/IO01RSB0
100	GAA0/IO00RSB0



	VQ100
Pin Number	AGLN250 Function
1	GND
2	GAA2/IO67RSB3
3	IO66RSB3
4	GAB2/IO65RSB3
5	IO64RSB3
6	GAC2/IO63RSB3
7	IO62RSB3
8	IO61RSB3
9	GND
10	GFB1/IO60RSB3
11	GFB0/IO59RSB3
12	VCOMPLF
13	GFA0/IO57RSB3
14	VCCPLF
15	GFA1/IO58RSB3
16	GFA2/IO56RSB3
17	VCC
18	VCCIB3
19	GFC2/IO55RSB3
20	GEC1/IO54RSB3
21	GEC0/IO53RSB3
22	GEA1/IO52RSB3
23	GEA0/IO51RSB3
24	VMV3
25	GNDQ
26	GEA2/IO50RSB2
27	FF/GEB2/IO49RSB2
28	GEC2/IO48RSB2
29	IO47RSB2
30	IO46RSB2
31	IO45RSB2
32	IO44RSB2
33	IO43RSB2
34	IO42RSB2
35	IO41RSB2
36	IO40RSB2

	VQ100
Pin Number	AGLN250 Function
37	VCC
38	GND
39	VCCIB2
40	IO39RSB2
41	IO38RSB2
42	IO37RSB2
43	GDC2/IO36RSB2
44	GDB2/IO35RSB2
45	GDA2/IO34RSB2
46	GNDQ
47	TCK
48	TDI
49	TMS
50	VMV2
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO33RSB1
58	GDC0/IO32RSB1
59	GDC1/IO31RSB1
60	IO30RSB1
61	GCB2/IO29RSB1
62	GCA1/IO27RSB1
63	GCA0/IO28RSB1
64	GCC0/IO26RSB1
65	GCC1/IO25RSB1
66	VCCIB1
67	GND
68	VCC
69	IO24RSB1
70	GBC2/IO23RSB1
71	GBB2/IO22RSB1
72	IO21RSB1

VQ100		
Pin Number	AGLN250 Function	
73	GBA2/IO20RSB1	
74	VMV1	
75	GNDQ	
76	GBA1/IO19RSB0	
77	GBA0/IO18RSB0	
78	GBB1/IO17RSB0	
79	GBB0/IO16RSB0	
80	GBC1/IO15RSB0	
81	GBC0/IO14RSB0	
82	IO13RSB0	
83	IO12RSB0	
84	IO11RSB0	
85	IO10RSB0	
86	IO09RSB0	
87	VCCIB0	
88	GND	
89	VCC	
90	IO08RSB0	
91	IO07RSB0	
92	IO06RSB0	
93	GAC1/IO05RSB0	
94	GAC0/IO04RSB0	
95	GAB1/IO03RSB0	
96	GAB0/IO02RSB0	
97	GAA1/IO01RSB0	
98	GAA0/IO00RSB0	
99	GNDQ	
100	VMV0	

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VQ100		
Pin Number AGLN250Z Function		
1	GND	
2	GAA2/IO67RSB3	
3	IO66RSB3	
4	GAB2/IO65RSB3	
5	IO64RSB3	
6	GAC2/IO63RSB3	
7	IO62RSB3	
8	IO61RSB3	
9	GND	
10	GFB1/IO60RSB3	
11	GFB0/IO59RSB3	
12	VCOMPLF	
13	GFA0/IO57RSB3	
14	VCCPLF	
15	GFA1/IO58RSB3	
16	GFA2/IO56RSB3	
17	VCC	
18	VCCIB3	
19	GFC2/IO55RSB3	
20	GEC1/IO54RSB3	
21	GEC0/IO53RSB3	
22	GEA1/IO52RSB3	
23	GEA0/IO51RSB3	
24	VMV3	
25	GNDQ	
26	GEA2/IO50RSB2	
27	FF/GEB2/IO49RSB2	
28	GEC2/IO48RSB2	
29	IO47RSB2	
30	IO46RSB2	
31	IO45RSB2	
32	IO44RSB2	
33	IO43RSB2	
34	IO42RSB2	
35	IO41RSB2	
36	IO40RSB2	

VQ100		
Pin Number AGLN250Z Functio		
37	VCC	
38	GND	
39	VCCIB2	
40	IO39RSB2	
41	IO38RSB2	
42	IO37RSB2	
43	GDC2/IO36RSB2	
44	GDB2/IO35RSB2	
45	GDA2/IO34RSB2	
46	GNDQ	
47	TCK	
48	TDI	
49	TMS	
50	VMV2	
51	GND	
52	VPUMP	
53	NC	
54	TDO	
55	TRST	
56	VJTAG	
57	GDA1/IO33RSB1	
58	GDC0/IO32RSB1	
59	GDC1/IO31RSB1	
60	IO30RSB1	
61	GCB2/IO29RSB1	
62	GCA1/IO27RSB1	
63	GCA0/IO28RSB1	
64	GCC0/IO26RSB1	
65	GCC1/IO25RSB1	
66	VCCIB1	
67	GND	
68	VCC	
69	IO24RSB1	
70	GBC2/IO23RSB1	
71	GBB2/IO22RSB1	
72	IO21RSB1	

VQ100		
Pin Number	AGLN250Z Function	
73	GBA2/IO20RSB1	
74	VMV1	
75	GNDQ	
76	GBA1/IO19RSB0	
77	GBA0/IO18RSB0	
78	GBB1/IO17RSB0	
79	GBB0/IO16RSB0	
80	GBC1/IO15RSB0	
81	GBC0/IO14RSB0	
82	IO13RSB0	
83	IO12RSB0	
84	IO11RSB0	
85	IO10RSB0	
86	IO09RSB0	
87	VCCIB0	
88	GND	
89	VCC	
90	IO08RSB0	
91	IO07RSB0	
92	IO06RSB0	
93	GAC1/IO05RSB0	
94	GAC0/IO04RSB0	
95	GAB1/IO03RSB0	
96	GAB0/IO02RSB0	
97	GAA1/IO01RSB0	
98	GAA0/IO00RSB0	
99	GNDQ	
100	VMV0	



5 - Datasheet Information

List of Changes

The following table lists critical changes that were made in each version of the IGLOO nano datasheet.

Revision	Changes	Page
Revision 17 (May 2013)	Deleted details related to Ambient temperature from "Enhanced Commercial Temperature Range", "IGLOO nano Ordering Information", "Temperature Grade Offerings", and Table 2-2 • Recommended Operating Conditions ¹ to remove ambiguities arising due to the same, and modified Note 2 (SAR 47063).	
Revision 16 (December 2012)	The "IGLOO nano Ordering Information" section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43174).	
	The note in Table 2-100 • IGLOO nano CCC/PLL Specification and Table 2-101 • IGLOO nano CCC/PLL Specification referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42565).	2-70, 2-71
	Live at Power-Up (LAPU) has been replaced with 'Instant On'.	NA
Revision 15 (September 2012)	The status of the AGLN125 device has been modified from 'Advance' to 'Production' in the "IGLOO nano Device Status" section (SAR 41416).	II
	Libero Integrated Design Environment (IDE) was changed to Libero System-on-Chip (SoC) throughout the document (SAR 40274).	NA
Revision 14 (September 2012)	The "Security" section was modified to clarify that Microsemi does not support read-back of programmed data.	1-2
Revision 13 (June 2012)	Figure Figure 2-34 • FIFO Read and Figure 2-35 • FIFO Write have been added (SAR 34842).	2-82
	The following sentence was removed from the "VMVx I/O Supply Voltage (quiet)" section in the "Pin Descriptions" section: "Within the package, the VMV plane is decoupled from the simultaneous switching noise originating from the output buffer VCCI domain" and replaced with "Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks" (SAR 38319). The datasheet mentions that "VMV pins must be connected to the corresponding VCCI pins" for an ESD enhancement.	3-1
Revision 12 (March 2012)	The "In-System Programming (ISP) and Security" section and "Security" section were revised to clarify that although no existing security measures can give an absolute guarantee, Microsemi FPGAs implement the best security available in the industry (SAR 34663).	I, 1-2
	Notes indicating that AGLN015 is not recommended for new designs have been added (SAR 35759). Notes indicating that nano-Z devices are not recommended for new designs have been added. The "Devices Not Recommended For New Designs" section is new (SAR 36759).	
	The Y security option and Licensed DPA Logo were added to the "IGLOO nano Ordering Information" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 34722).	III
	The following sentence was removed from the "Advanced Architecture" section: "In addition, extensive on-chip programming circuitry enables rapid, single-voltage (3.3 V) programming of IGLOO nano devices via an IEEE 1532 JTAG interface" (SAR 34683).	



Revision	Changes	Page
Revision 12	The "Specifying I/O States During Programming" section is new (SAR 34694).	1-9
(continued)	The reference to guidelines for global spines and VersaTile rows, given in the "Global Clock Contribution—P _{CLOCK} " section, was corrected to the "Spine Architecture" section of the Global Resources chapter in the <i>IGLOO nano FPGA Fabric User's Guide</i> (SAR 34732).	2-12
	Figure 2-4 has been modified for DIN waveform; the Rise and Fall time label has been changed to tDIN (37106).	2-16
	The AC Loading figures in the "Single-Ended I/O Characteristics" section were updated to match tables in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section (SAR 34885).	2-26, 2-20
	The notes regarding drive strength in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section, "3.3 V LVCMOS Wide Range" section and "1.2 V LVCMOS Wide Range" section tables were revised for clarification. They now state that the minimum drive strength for the default software configuration when run in wide range is $\pm 100~\mu A$. The drive strength displayed in software is supported in normal range only. For a detailed I/V curve, refer to the IBIS models (SAR 34765).	2-20, 2-29, 2-40
	Added values for minimum pulse width and removed the FRMAX row from Table 2-88 through Table 2-99 in the "Global Tree Timing Characteristics" section. Use the software to determine the FRMAX for the device you are using (SAR 36953).	2-64 to 2-69
	Table 2-100 • IGLOO nano CCC/PLL Specification and Table 2-101 • IGLOO nano CCC/PLL Specification were updated. A note was added indicating that when the CCC/PLL core is generated by Mircosemi core generator software, not all delay values of the specified delay increments are available (SAR 34817).	2-70 and 2-71
	The port names in the SRAM "Timing Waveforms", SRAM "Timing Characteristics" tables, Figure 2-36 • FIFO Reset, and the FIFO "Timing Characteristics" tables were revised to ensure consistency with the software names (SAR 35754). Reference was made to a new application note, Simultaneous Read-Write Operations in	2-74, 2-77, 2-85
	Dual-Port SRAM for Flash-Based cSoCs and FPGAs, which covers these cases in detail (SAR 34865).	
	The "Pin Descriptions" chapter has been added (SAR 34770).	3-1
	Package names used in the "Package Pin Assignments" section were revised to match standards given in <i>Package Mechanical Drawings</i> (SAR 34770).	4-1
Revision 11	The status of the AGLN060 device has changed from Advance to Production.	Ш
(Jul 2010)	The values for PAC1, PAC2, PAC3, and PAC4 were updated in Table 2-15 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices for 1.5 V core supply voltage (SAR 26404).	2-10
	The values for PAC1, PAC2, PAC3, and PAC4 were updated in Table 2-17 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices for 1.2 V core supply voltage (SAR 26404).	2-11
July 2010	The versioning system for datasheets has been changed. Datasheets are assigned a revision number that increments each time the datasheet is revised. The "IGLOO nano Device Status" table on page II indicates the status for each device in the device family.	N/A

5-2 Revision 17



Revision	Changes	Page
Revision 10 (Apr 2010)	References to differential inputs were removed from the datasheet, since IGLOO nano devices do not support differential inputs (SAR 21449).	N/A
	A parenthetical note, "hold previous I/O state in Flash*Freeze mode," was added to each occurrence of bus hold in the datasheet (SAR 24079).	N/A
	The "In-System Programming (ISP) and Security" section was revised to add 1.2 V programming.	I
	The note connected with the "IGLOO nano Ordering Information" table was revised to clarify features not available for Z feature grade devices.	III
	The "IGLOO nano Device Status" table is new.	П
	The definition of C in the "Temperature Grade Offerings" table was changed to "extended commercial temperature range."	IV
	1.2 V wide range was added to the list of voltage ranges in the "I/Os with Advanced I/O Standards" section.	1-8
	A note was added to Table 2-2 • Recommended Operating Conditions ¹ regarding switching from 1.2 V to 1.5 V core voltage for in-system programming. The VJTAG voltage was changed from "1.425 to 3.6" to "1.4 to 3.6" (SAR 24052). The note regarding voltage for programming V2 and V5 devices was revised (SAR 25213). The maximum value for VPUMP programming voltage (operation mode) was changed from 3.45 V to 3.6 V (SAR 25220).	2-2
	Table 2-6 • Temperature and Voltage Derating Factors for Timing Delays (normalized to TJ = 70°C, VCC = 1.425 V) and Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays (normalized to TJ = 70°C, VCC = 1.14 V) were updated. Table 2-8 • Power Supply State per Mode is new.	2-6, 2-7
	The tables in the "Quiescent Supply Current" section were updated (SAR 24882 and SAR 24112).	2-7
	VJTAG was removed from Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Sleep Mode* (SARs 24112, 24882, and 79503).	2-8
	The note stating what was included in I_{DD} was removed from Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Shutdown Mode. The note, "per VCCI or VJTAG bank" was removed from Table 2-12 • Quiescent Supply Current (IDD), No IGLOO nano Flash*Freeze Mode ¹ . The note giving I_{DD} was changed to " $I_{DD} = N_{BANKS} * I_{CCI} + I_{CCA}$."	2-8
	The values in Table 2-13 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings and Table 2-14 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings ¹ were updated. Wide range support information was added.	2-9



Revision	Changes	Page
Revision 10 (continued)	The following tables were updated with current available information. The equivalent software default drive strength option was added.	2-19 through
	Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels	2-40
	Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings	
	Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings	
	Table 2-28 • I/O Output Buffer Maximum Resistances ¹	
	Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances	
	Table 2-30 • I/O Short Currents IOSH/IOSL	
	Timing tables in the "Single-Ended I/O Characteristics" section, including new tables for 3.3 V and 1.2 V LVCMOS wide range.	
	Table 2-40 • Minimum and Maximum DC Input and Output Levels for LVCMOS 3.3 V Wide Range	
	Table 2-63 • Minimum and Maximum DC Input and Output Levels	
	Table 2-67 • Minimum and Maximum DC Input and Output Levels (new)	
	The formulas in the notes to Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances were revised (SAR 21348).	2-24
	The text introducing Table 2-31 • Duration of Short Circuit Event before Failure was revised to state six months at 100° instead of three months at 110° for reliability concerns. The row for 110° was removed from the table.	2-25
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 24916): "It uses a 5-V tolerant input buffer and push-pull output buffer."	2-32
	The $F_{DDRIMAX}$ and F_{DDOMAX} values were added to tables in the "DDR Module Specifications" section (SAR 23919). A note was added stating that DDR is not supported for AGLN010, AGLN015, and AGLN020.	2-51
	Tables in the "Global Tree Timing Characteristics" section were updated with new information available.	2-64
	Table 2-100 • IGLOO nano CCC/PLL Specification and Table 2-101 • IGLOO nano CCC/PLL Specification were revised (SAR 79390).	2-70, 2-71
	Tables in the SRAM "Timing Characteristics" section and FIFO "Timing Characteristics" section were updated with new information available.	2-77, 2-85
	Table 3-3 • TRST and TCK Pull-Down Recommendations is new.	3-4
	A note was added to the "CS81" pin tables for AGLN060, AGLN060Z, AGLN125, AGLN125Z, AGLN250, and AGLN250Z indicating that pins F1 and F2 must be grounded (SAR 25007).	4-9, through 4-14
	A note was added to the "CS81" and "VQ100" pin tables for AGLN060 and AGLN060Z stating that bus hold is not available for pin H7 or pin 45 (SAR 24079).	4-9, 4-24
	The AGLN250 function for pin C8 in the "CS81" table was revised (SAR 22134).	4-13

5-4 Revision 17



Revision / Version	Changes	Page
Revision 9 (Mar2010) Product Brief Advance v0.9 Packaging Advance	All product tables and pin tables were updated to show clearly that AGLN030 is available only in the Z feature grade at this time. The nano-Z feature grade devices are designated with a Z at the end of the part number.	N/A
v0.8		
Revision 8 (Jan 2009)	The "Reprogrammable Flash Technology" section was revised to add "250 MHz (1.5 V systems) and 160 MHz (1.2 V systems) System Performance."	I
Product Brief Advance v0.8	The note for AGLN030 in the "IGLOO nano Devices" table and "I/Os Per Package" table was revised to remove the statement regarding package compatibility with lower density nano devices.	
	The "I/Os with Advanced I/O Standards" section was revised to add definitions for hot-swap and cold-sparing.	1-8
Packaging Advance v0.7	The "UC81", "CS81", "QN48", and "QN68" pin tables for AGLN030 are new.	4-5, 4-8, 4-17,4-21
	The "CS81"pin table for AGLN060 is new.	4-9
	The "CS81" and "VQ100" pin tables for AGLN060Z are new.	4-10, 4-25
	The "CS8" and "VQ100" pin tables for AGLN125Z are new.	4-12, 4-27
	The "CS81" and "VQ100" pin tables for AGLN250Z is new.	4-14, 4-29
Product Brief Advance v0.7 DC and Switching Characteristics Advance v0.3	removed from the datasheet.	
Revision 6 (Mar 2009) Packaging Advance v0.6	The "VQ100" pin table for AGLN030 is new.	4-23
Revision 5 (Feb 2009) Packaging Advance v0.5	The "100-Pin QFN" section was removed.	N/A
Revision 4 (Feb 2009)	The QN100 package was removed for all devices.	N/A
Product Brief Advance v0.6	"IGLOO nano Devices" table was updated to change the maximum user I/Os for AGLN030 from 81 to 77.	Ш
	The "Device Marking" section is new.	III
Revision 3 (Feb 2009) Product Brief Advance v0.5	The following table note was removed from "IGLOO nano Devices" table: "Six chip (main) and three quadrant global networks are available for AGLN060 and above."	
	The CS81 package was added for AGLN250 in the "IGLOO nano Products Available in the Z Feature Grade" table.	IV
Packaging Advance v0.4	The "UC81" and "CS81" pin tables for AGLN020 are new.	4-4, 4-7
	The "CS81" pin table for AGLN250 is new.	4-13

Revision / Version	Changes	Page
Revision 2 (Dec 2008) Product Brief Advance v0.4	The second table note in "IGLOO nano Devices" table was revised to state, "AGLN060, AGLN125, and AGLN250 in the CS81 package do not support PLLs. AGLN030 and smaller devices do not support this feature."	II
	The I/Os per package for CS81 were revised to 60 for AGLN060, AGLN125, and AGLN250 in the "I/Os Per Package"table.	Ш
Packaging Advance v0.3	The "UC36" pin table is new.	4-2
Revision 1 (Nov 2008) Product Brief Advance v0.3	The "Advanced I/Os" section was updated to include wide power supply voltage support for 1.14 V to 1.575 V.	I
	The AGLN030 device was added to product tables and replaces AGL030 entries that were formerly in the tables.	IV
	The "I/Os Per Package"table was updated for the CS81 package to change the number of I/Os for AGLN060, AGLN125, and AGLN250 from 66 to 64.	Ш
	The "Wide Range I/O Support" section is new.	1-8
	The table notes and references were revised in Table 2-2 • Recommended Operating Conditions ¹ . VMV was included with VCCI and a table note was added stating, "VMV pins must be connected to the corresponding VCCI pins. See <i>Pin Descriptions</i> for further information." Please review carefully.	2-2
	VJTAG was added to the list in the table note for Table 2-9 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Flash*Freeze Mode*. Values were added for AGLN010, AGLN015, and AGLN030 for 1.5 V.	2-7
	VCCI was removed from the list in the table note for Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Sleep Mode*.	2-8
	Values for I _{CCA} current were updated for AGLN010, AGLN015, and AGLN030 in Table 2-12 • Quiescent Supply Current (IDD), No IGLOO nano Flash*Freeze Mode ¹ .	2-8
	Values for PAC1 and PAC2 were added to Table 2-15 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices and Table 2-17 • Different Components Contributing to Dynamic Power Consumption in IGLOO nano Devices.	2-10, 2-11
	Table notes regarding wide range support were added to Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels.	2-19
	1.2 V LVCMOS wide range values were added to Table 2-22 • Summary of Maximum and Minimum DC Input Levels and Table 2-23 • Summary of AC Measuring Points.	2-19, 2-20
	The following table note was added to Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings and Table 2-26 • Summary of I/O Timing Characteristics—Software Default Settings: "All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification."	2-21
	3.3 V LVCMOS Wide Range and 1.2 V Wide Range were added to Table 2-28 • I/O Output Buffer Maximum Resistances ¹ and Table 2-30 • I/O Short Currents IOSH/IOSL.	2-23, 2-24

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Revision / Version	Changes	Page
Revision 1 (cont'd)	The "QN48" pin diagram was revised.	4-16
Packaging Advance v0.2	Note 2 for the "QN48", "QN68", and "100-Pin QFN" pin diagrams was changed to "The die attach paddle of the package is tied to ground (GND)."	4-16, 4-19
	The "VQ100" pin diagram was revised to move the pin IDs to the upper left corner instead of the upper right corner.	4-23
Revision 0 (Oct 2008) Product Brief Advance v0.2	The following tables and sections were updated to add the UC81 and CS81 packages for AGL030: "IGLOO nano Devices" "I/Os Per Package" "IGLOO nano Products Available in the Z Feature Grade" "Temperature Grade Offerings"	N/A
	The "I/Os Per Package" table was updated to add the following information to table note 4: "For nano devices, the VQ100 package is offered in both leaded and RoHS-compliant versions. All other packages are RoHS-compliant only."	
	The "IGLOO nano Products Available in the Z Feature Grade" section was updated to remove QN100 for AGLN250.	IV
	The device architecture figures, Figure 1-3 • IGLOO Device Architecture Overview with Two I/O Banks (AGLN060, AGLN125) through Figure 1-4 • IGLOO Device Architecture Overview with Four I/O Banks (AGLN250), were revised. Figure 1-1 • IGLOO Device Architecture Overview with Two I/O Banks and No RAM (AGLN010 and AGLN030) is new.	through 1-5
	The "PLL and CCC" section was revised to include information about CCC-GLs in AGLN020 and smaller devices.	1-7
	The "I/Os with Advanced I/O Standards" section was revised to add information about IGLOO nano devices supporting double-data-rate applications.	1-8



Datasheet Categories

Categories

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "IGLOO nano Device Status" table on page II, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

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The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

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This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

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The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

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